

# TLC220x, TLC220xA, TLC220xB, TLC220xY Advanced LinCMOS™ LOW-NOISE PRECISION OPERATIONAL AMPLIFIERS

SLOS175B – FEBRUARY 1997 – REVISED JANUARY 2008

- B Grade Is 100% Tested for Noise  
30 nV/ $\sqrt{\text{Hz}}$  Max at f = 10 Hz  
12 nV/ $\sqrt{\text{Hz}}$  Max at f = 1 kHz
- Low Input Offset Voltage . . . 500  $\mu\text{V}$  Max
- Excellent Offset Voltage Stability  
With Temperature . . . 0.5  $\mu\text{V}/^\circ\text{C}$  Typ
- Rail-to-Rail Output Swing
- Low Input Bias Current  
1 pA Typ at  $T_A = 25^\circ\text{C}$
- Common-Mode Input Voltage Range  
Includes the Negative Rail
- Fully Specified For Both Single-Supply and  
Split-Supply Operation

## description

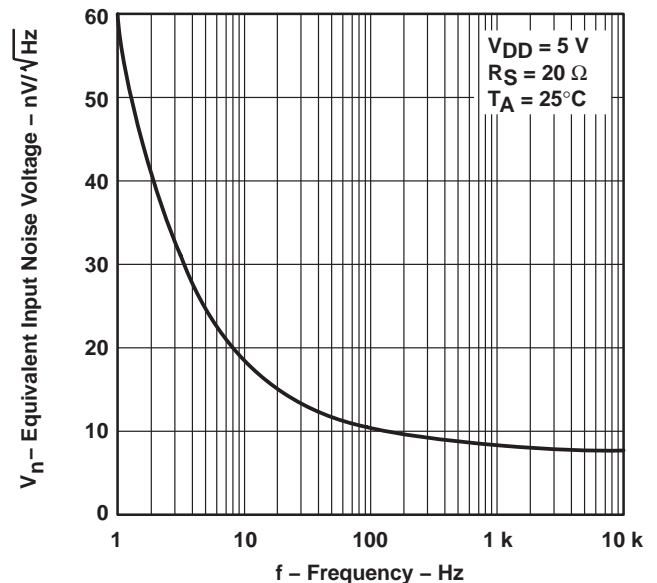
The TLC220x, TLC220xA, TLC220xB, and TLC220xY are precision, low-noise operational amplifiers using Texas Instruments Advanced LinCMOS™ process. These devices combine the noise performance of the lowest-noise JFET amplifiers with the dc precision available previously only in bipolar amplifiers. The Advanced LinCMOS™ process uses silicon-gate technology to obtain input offset voltage stability with temperature and time that far exceeds that obtainable using metal-gate technology. In addition, this technology makes possible input impedance levels that meet or exceed levels offered by top-gate JFET and expensive dielectric-isolated devices.

The combination of excellent DC and noise performance with a common-mode input voltage range that includes the negative rail makes these devices an ideal choice for high-impedance, low-level signal-conditioning applications in either single-supply or split-supply configurations.

The device inputs and outputs are designed to withstand –100-mA surge currents without sustaining latch-up. In addition, internal ESD-protection circuits prevent functional failures at voltages up to 2000 V as tested under MIL-PRF-38535, Method 3015.2; however, care should be exercised in handling these devices as exposure to ESD may result in degradation of the parametric performance.

The C-suffix devices are characterized for operation from 0°C to 70°C. The I-suffix devices are characterized for operation from –40°C to 85°C. The M-suffix devices are characterized for operation over the full military temperature range of –55°C to 125°C.

TYPICAL EQUIVALENT  
INPUT NOISE VOLTAGE  
VS  
FREQUENCY



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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



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On products compliant to MIL-PRF-38535, all parameters are tested unless otherwise noted. On all other products, production processing does not necessarily include testing of all parameters.

# TLC220x, TLC220xA, TLC220xB, TLC220xY

## Advanced LinCMOS™ LOW-NOISE PRECISION OPERATIONAL AMPLIFIERS

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### TLC2201 AVAILABLE OPTIONS

T <sub>A</sub>	V <sub>IO</sub> max AT 25°C	V <sub>n</sub> max f = 10 Hz AT 25°C	V <sub>n</sub> max f = 1 kHz AT 25°C	PACKAGED DEVICES				CHIP FORM‡ (Y)
				SMALL OUTLINE† (D)	CHIP CARRIER (FK)	CERAMIC DIP (JG)	PLASTIC DIP (P)	
0°C to 70°C	200 μV	35 nV/√Hz	15 nV/√Hz	TLC2201ACD	—	—	TLC2201ACP	TLC2201Y
	200 μV	30 nV/√Hz	12 nV/√Hz	TLC2201BCD			TLC2201BCP	
	500 μV	—	—	TLC2201CD			TLC2201CP	
–40°C to 85°C	200 μV	35 nV/√Hz	15 nV/√Hz	TLC2201AID	—	—	TLC2201AIP	—
	200 μV	30 nV/√Hz	12 nV/√Hz	TLC2201BID			TLC2201BIP	
	500 μV	—	—	TLC2201ID			TLC2201IP	
–55°C to 125°C	200 μV	35 nV/√Hz	15 nV/√Hz	TLC2201AMD	TLC2201AMFK	TLC2201AMJG	TLC2201AMP	—
	200 μV	30 nV/√Hz	12 nV/√Hz	TLC2201BMD	TLC2201BMFK	TLC2201BMJG	TLC2201BMP	
	500 μV	—	—	TLC2201MD	TLC2201MFK	TLC2201MJG	TLC2201MP	

† The D packages are available taped and reeled. Add R suffix to device type (e.g. TLC220xBCDR).

‡ Chip forms are tested at 25°C only.

### TLC2202 AVAILABLE OPTIONS

T <sub>A</sub>	V <sub>IO</sub> max AT 25°C	V <sub>n</sub> max f = 10 Hz AT 25°C	V <sub>n</sub> max f = 1 kHz AT 25°C	PACKAGED DEVICES					CHIP FORM‡ (Y)
				SMALL OUTLINE† (D)	PLASTIC SMALL OUTLINE (PS)	CHIP CARRIER (FK)	CERAMIC DIP (JG)	PLASTIC DIP (P)	
0°C to 70°C	500 μV	30 nV/√Hz	12 nV/√Hz	TLC2202BCD	—	—	—	TLC2202BCP	TLC2202Y
	500 μV	35 nV/√Hz	15 nV/√Hz	TLC2202ACD	—	—	—	TLC2202ACP	
	1 mV	—	—	TLC2202CD	TLC2202CPSR	—	—	TLC2202CP	
–40°C to 85°C	500 μV	30 nV/√Hz	12 nV/√Hz	TLC2202BID	—	—	—	TLC2202BIP	—
	500 μV	35 nV/√Hz	15 nV/√Hz	TLC2202AID	—	—	—	TLC2202AIP	
	1 mV	—	—	TLC2202ID	—	—	—	TLC2202IP	
–55°C to 125°C	500 μV	30 nV/√Hz	12 nV/√Hz	TLC2202BMD	—	TLC2202BMFK	TLC2202BMJG	TLC2202BMP	—
	500 μV	35 nV/√Hz	15 nV/√Hz	TLC2202AMD	—	TLC2202AMFK	TLC2202AMJG	TLC2202AMP	
	1 mV	—	—	TLC2202MD	—	TLC2202MFK	TLC2202MJG	TLC2202MP	

† The D packages are available taped and reeled. Add R suffix to device type (e.g. TLC220xBCDR).

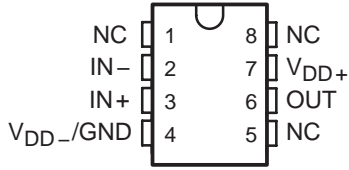
‡ Chip forms are tested at 25°C only.



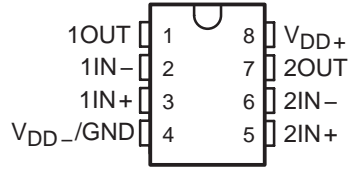
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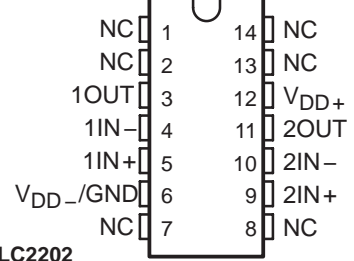
**TLC2201**  
D, JG, OR P PACKAGE  
(TOP VIEW)



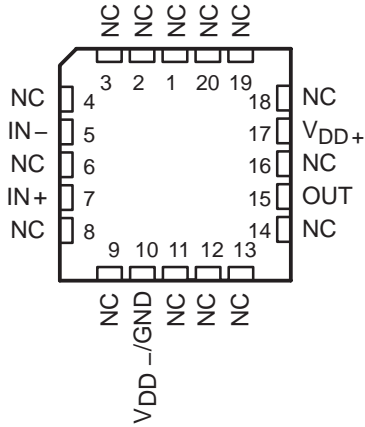
**TLC2202**  
PS, JG, OR P PACKAGE  
(TOP VIEW)



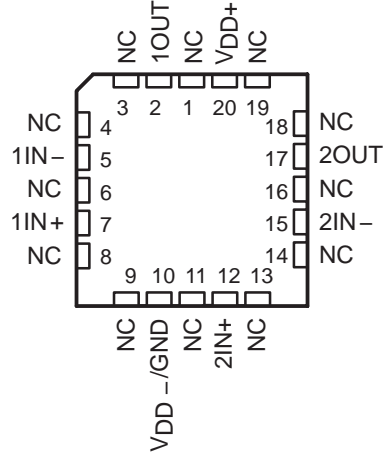
**TLC2202**  
D PACKAGE  
(TOP VIEW)



**TLC2201**  
FK PACKAGE  
(TOP VIEW)



**TLC2202**  
FK PACKAGE  
(TOP VIEW)

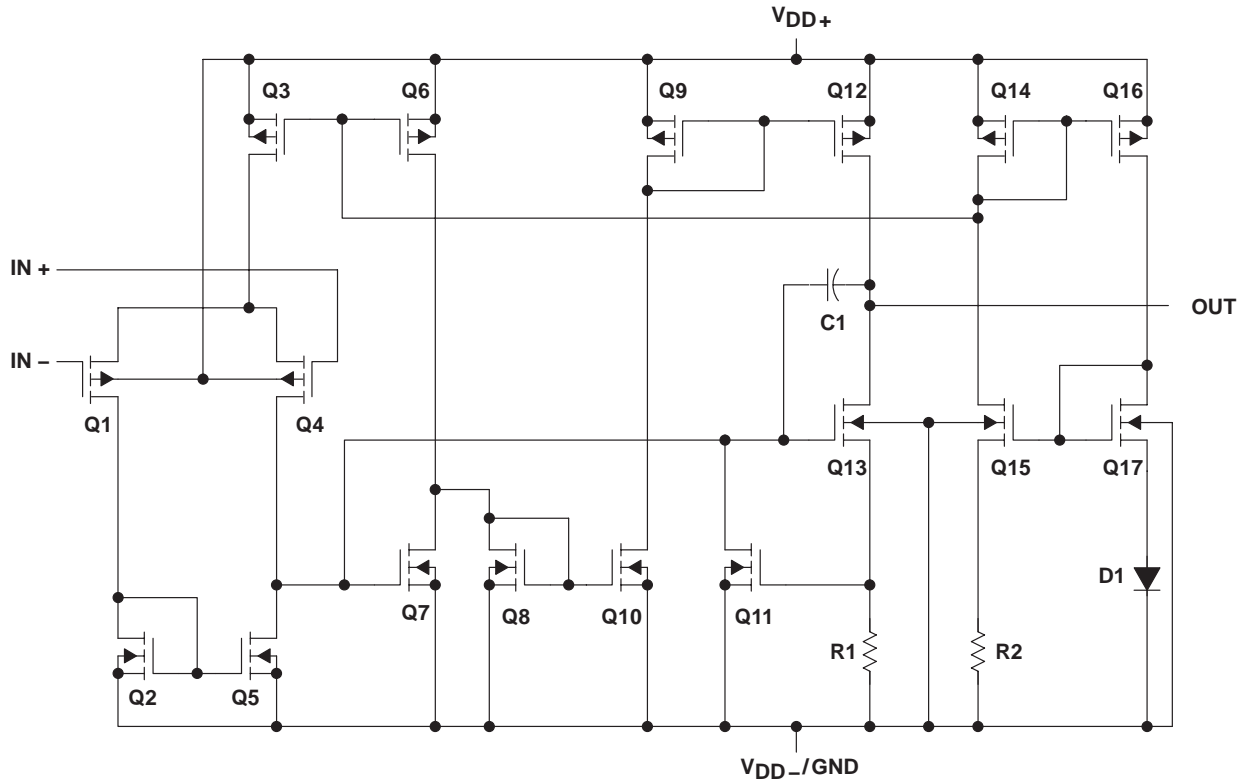


NC – No internal connection

**TLC220x, TLC220xA, TLC220xB, TLC220xY**  
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equivalent schematic (each amplifier)



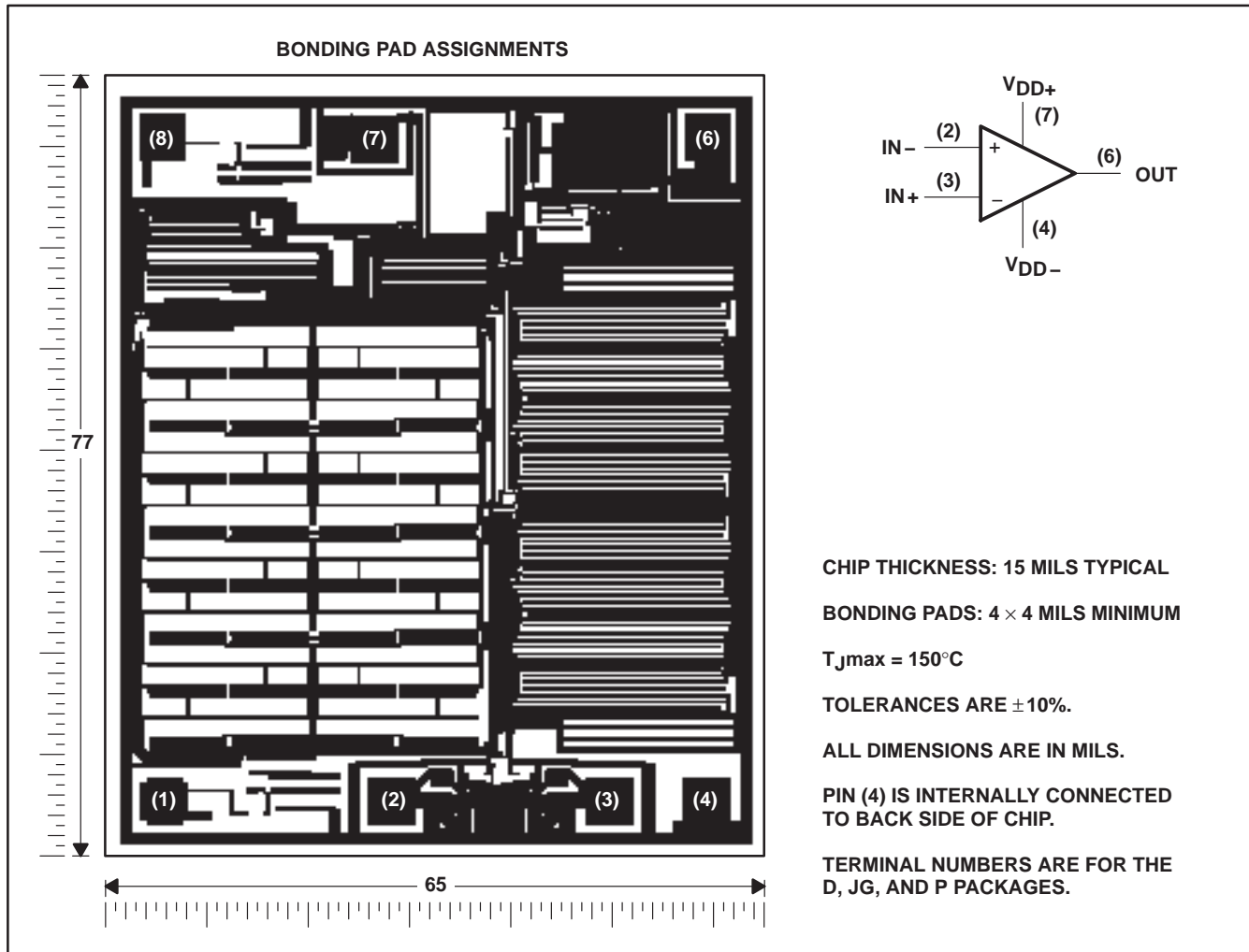
ACTUAL DEVICE COMPONENT COUNT		
COMPONENT	TLC2201	TLC2202
Transistors	17	34
Resistors	2	2
Diodes	1	4
Capacitors	1	2

# TLC220x, TLC220xA, TLC220xB, TLC220xY Advanced LinCMOS™ LOW-NOISE PRECISION OPERATIONAL AMPLIFIERS

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## TLC2201Y chip information

This chip, when properly assembled, displays characteristics similar to the TLC2201C. Thermal compression or ultrasonic bonding may be used on the doped-aluminum bonding path. Chips may be mounted with conductive epoxy or a gold-silicon preform.

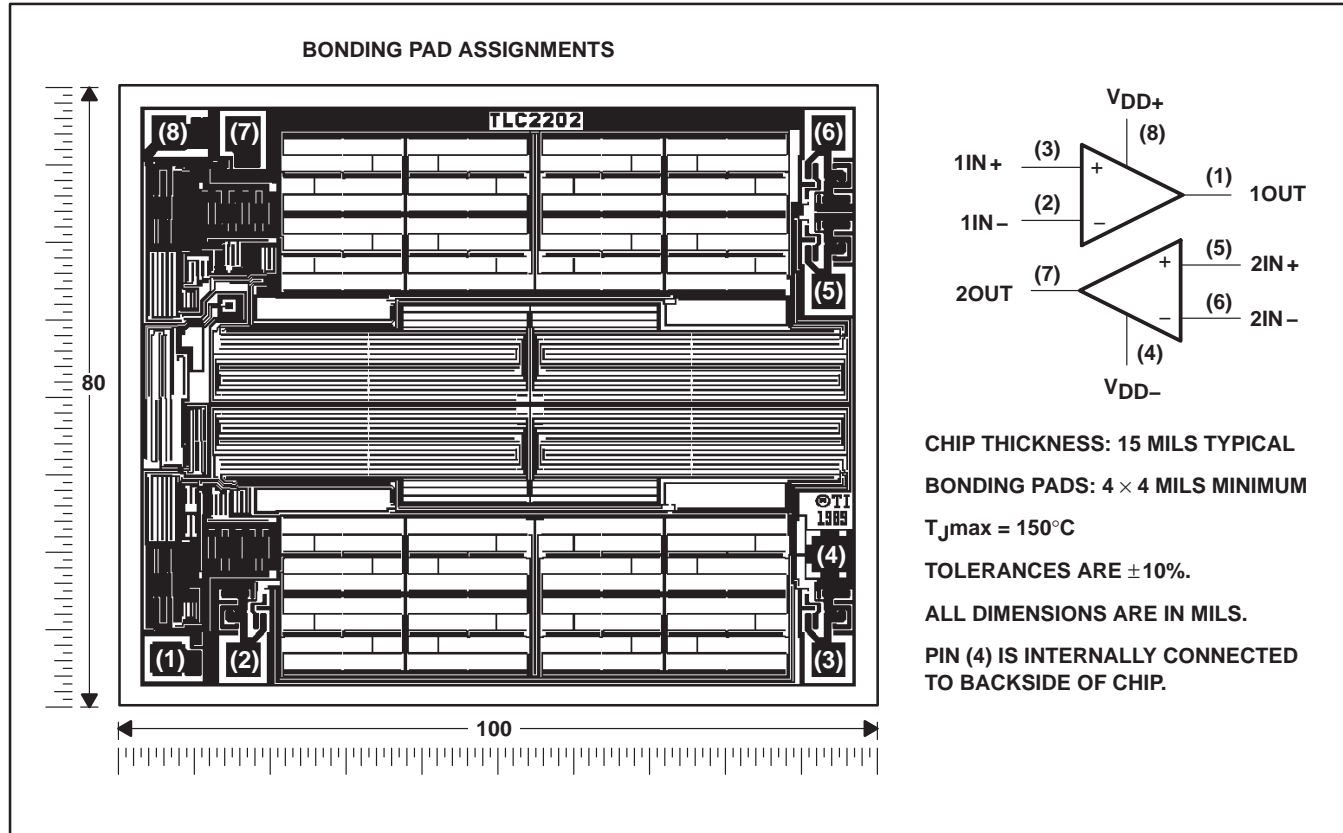


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**TLC2202Y chip formation**

This chip, when properly assembled, displays characteristics similar to the TLC2202C. Thermal compression or ultrasonic bonding may be used on the doped-aluminum bonding pads. Chips may be mounted with conductive epoxy or a gold-silicon preform.



# TLC220x, TLC220xA, TLC220xB, TLC220xY Advanced LinCMOS™ LOW-NOISE PRECISION OPERATIONAL AMPLIFIERS

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## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, $V_{DD+}$ (see Note 1)	8 V
Supply voltage, $V_{DD-}$	-8 V
Differential input voltage, $V_{ID}$ (see Note 2)	±16 V
Input voltage, $V_I$ (any input)	±8 V
Input current, $I_I$ (each input)	±5 mA
Output current, $I_O$ (each output)	±50 mA
Duration of short-circuit current at (or below) 25°C (see Note 3)	unlimited
Continuous total dissipation	See Dissipation Rating Table
Operating free-air temperature range, $T_A$ : C suffix	0°C to 70°C
I suffix	-40°C to 85°C
M suffix	-55°C to 125°C
Storage temperature range	-65°C to 150°C
Case temperature for 60 seconds: FK package	260°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds: D, PS, or P package	260°C
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds: JG package	300°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES:
1. All voltage values except differential voltages are with respect to the midpoint between  $V_{DD+}$  and  $V_{DD-}$ .
  2. Differential voltages are at  $IN+$  with respect to  $IN-$ .
  3. The output may be shorted to either supply. Temperature and/or supply voltages must be limited to ensure that the maximum dissipation rating is not exceeded.

**DISSIPATION RATING TABLE**

PACKAGE	$T_A \leq 25^\circ\text{C}$	DERATING FACTOR	$T_A = 70^\circ\text{C}$	$T_A = 85^\circ\text{C}$	$T_A = 125^\circ\text{C}$
	POWER RATING	ABOVE $T_A = 25^\circ\text{C}$	POWER RATING	POWER RATING	POWER RATING
D-8	725 mW	5.8 mW/°C	464 mW	377 mW	145 mW
D-14	950 mW	7.6 mW/°C	608 mW	494 mW	190 mW
PS	770 mW	6.2 mW/°C	496 mW	403 mW	155 mW
FK	1375 mW	11.0 mW/°C	880 mW	715 mW	275 mW
JG	1050 mW	8.4 mW/°C	672 mW	546 mW	210 mW
P	1000 mW	8.0 mW/°C	640 mW	520 mW	200 mW

## recommended operating conditions

	C SUFFIX		I SUFFIX		M SUFFIX		UNIT
	MIN	MAX	MIN	MAX	MIN	MAX	
Supply voltage, $V_{DD\pm}$	±2.3	±8	±2.3	±8	±2.3	±8	V
Common-mode input voltage, $V_{IC}$	$V_{DD-}$	$V_{DD+} - 2.3$	$V_{DD-}$	$V_{DD+} - 2.3$	$V_{DD-}$	$V_{DD+} - 2.3$	V
Operating free-air temperature, $T_A$	0	70	-40	85	-55	125	°C



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**TLC2201C electrical characteristics at specified free-air temperature,  $V_{DD\pm} = \pm 5\text{ V}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2201C			UNIT
			MIN	TYP	MAX	
$V_{IO}$ Input offset voltage	$V_{IC} = 0, R_S = 50\ \Omega$	25°C	100	500	$\mu\text{V}$	
		Full range	600			
$\alpha_{V_{IO}}$ Temperature coefficient of input offset voltage		Full range	0.5		$\mu\text{V}/^\circ\text{C}$	
Input offset voltage long-term drift (see Note 4)		25°C	0.001	0.005	$\mu\text{V}/\text{mo}$	
$I_{IO}$ Input offset current		25°C	0.5	60	$\text{pA}$	
		Full range	100			
$I_{IB}$ Input bias current		25°C	1	60	$\text{pA}$	
		Full range	100			
$V_{ICR}$ Common-mode input voltage range	$R_S = 50\ \Omega$	Full range	-5 to 2.7	$\text{V}$		
$V_{OM+}$ Maximum positive peak output voltage swing	$R_L = 10\ \text{k}\Omega$	25°C	4.7	4.8	$\text{V}$	
$V_{OM-}$ Maximum negative peak output voltage swing		Full range	4.7			
		25°C	-4.7	-4.9	$\text{V}$	
Full range		-4.7				
$A_{VD}$ Large-signal differential voltage amplification	$V_O = \pm 4\ \text{V}, R_L = 500\ \text{k}\Omega$	25°C	400	560	$\text{V}/\text{mV}$	
		Full range	300			
	$V_O = \pm 4\ \text{V}, R_L = 10\ \text{k}\Omega$	25°C	90	100		
		Full range	70			
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, V_O = 0, R_S = 50\ \Omega$	Full range	85		$\text{dB}$	
$k_{SVR}$ Supply voltage rejection ratio ( $\Delta V_{DD\pm} / \Delta V_{IO}$ )	$V_{DD\pm} = \pm 2.3\ \text{V}$ to $\pm 8\ \text{V}$	25°C	90	110	$\text{dB}$	
		Full range	85			
$I_{DD}$ Supply current	$V_O = 0, \text{ No load}$	25°C	1.1	1.5	$\text{mA}$	
		Full range	1.5			

† Full range is 0°C to +70°C.

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.

**TLC2201C operating characteristics at specified free-air temperature,  $V_{DD\pm} = \pm 5\ \text{V}$**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2201C			UNIT
			MIN	TYP	MAX	
SR Slew rate at unity gain	$V_O = \pm 2.3\ \text{V}, R_L = 10\ \text{k}\Omega, C_L = 100\ \text{pF}$	25°C	2	2.7	$\text{V}/\mu\text{s}$	
		Full range	1.5			
$V_n$ Equivalent input noise voltage	$f = 10\ \text{Hz}$	25°C	18		$\text{nV}/\sqrt{\text{Hz}}$	
	$f = 1\ \text{kHz}$	25°C	8			
$V_{N(PP)}$ Peak-to-peak equivalent input noise voltage	$f = 0.1$ to $1\ \text{Hz}$	25°C	0.5		$\mu\text{V}$	
	$f = 0.1$ to $10\ \text{Hz}$	25°C	0.7			
$I_n$ Equivalent input noise current		25°C	0.6		$\text{fA}/\sqrt{\text{Hz}}$	
Gain-bandwidth product	$f = 10\ \text{kHz}, R_L = 10\ \text{k}\Omega, C_L = 100\ \text{pF}$	25°C	1.9		$\text{MHz}$	
$\phi_m$ Phase margin at unity gain	$R_L = 10\ \text{k}\Omega, C_L = 100\ \text{pF}$	25°C	48°			

† Full range is 0°C to +70°C.



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**TLC2201C electrical characteristics at specified free-air temperature,  $V_{DD\pm} = \pm 5\text{ V}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2201AC			TLC2201BC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
$V_{IO}$ Input offset voltage	$V_{IC} = 0, R_S = 50\ \Omega$	25°C	80	200		80	200	$\mu\text{V}$	
		Full range			300		300		
$\alpha_{VIO}$ Temperature coefficient of input offset voltage		Full range		0.5			0.5	$\mu\text{V}/^\circ\text{C}$	
Input offset voltage long-term drift (see Note 4)		25°C	0.001	0.005		0.001	0.005	$\mu\text{V}/\text{mo}$	
$I_{IO}$ Input offset current		25°C	0.5	60		0.5	60	$\text{pA}$	
		Full range			100		100		
$I_{IB}$ Input bias current		25°C	1	60		1	60	$\text{pA}$	
		Full range			100		100		
$V_{ICR}$ Common-mode input voltage range		$R_S = 50\ \Omega$	Full range	-5 to 2.7			-5 to 2.7	V	
$V_{OM+}$ Maximum positive peak output voltage swing		$R_L = 10\ \text{k}\Omega$	25°C	4.7	4.8		4.7	4.8	V
$V_{OM-}$ Maximum negative peak output voltage swing	Full range			4.7			4.7		
	25°C		-4.7	-4.9		-4.7	-4.9	V	
Full range			-4.7			-4.7			
$A_{VD}$ Large-signal differential voltage amplification	$V_O = \pm 4\ \text{V}, R_L = 500\ \text{k}\Omega$	25°C	400	560		400	560	V/mV	
		Full range		300			300		
	$V_O = \pm 4\ \text{V}, R_L = 10\ \text{k}\Omega$	25°C	90	100		90	100		
		Full range		70			70		
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICR\text{min}}, V_O = 0, R_S = 50\ \Omega$	25°C	90	115		90	115	dB	
		Full range		85			85		
$k_{SVR}$ Supply voltage rejection ratio ( $\Delta V_{DD\pm} / \Delta V_{IO}$ )	$V_{DD\pm} = \pm 2.3\ \text{V to } \pm 8\ \text{V}$	25°C	90	110		90	110	dB	
		Full range		85			85		
$I_{DD}$ Supply current	$V_O = 0, \text{ No load}$	25°C		1.1	1.5		1.1	1.5	mA
		Full range			1.5			1.5	

† Full range is 0°C to +70°C.

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.

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**TLC2201C operating characteristics at specified free-air temperature,  $V_{DD\pm} = \pm 5\text{ V}$**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2201AC			TLC2201BC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR Slew rate at unity gain	$V_O = \pm 2.3\text{ V}$ , $R_L = 10\text{ k}\Omega$ , $C_L = 100\text{ pF}$	25°C	2	2.7		2	2.7		V/ $\mu$ s
		Full range	1.5			1.5			
$V_n$ Equivalent input noise voltage (see Note 5)	$f = 10\text{ Hz}$	25°C		18	35		18	30	nV/ $\sqrt{\text{Hz}}$
	$f = 1\text{ kHz}$	25°C		8	15		8	12	
$V_{N(PP)}$ Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ to }1\text{ Hz}$	25°C		0.5			0.5		$\mu$ V
	$f = 0.1\text{ to }10\text{ Hz}$	25°C		0.7			0.7		
$I_n$ Equivalent input noise current		25°C		0.6			0.6	fA/ $\sqrt{\text{Hz}}$	
Gain-bandwidth product	$f = 10\text{ kHz}$ , $R_L = 10\text{ k}\Omega$ , $C_L = 100\text{ pF}$	25°C		1.9			1.9	MHz	
$\phi_m$ Phase margin at unity gain	$R_L = 10\text{ k}\Omega$ , $C_L = 100\text{ pF}$	25°C		48°			48°		

† Full range is 0°C to +70°C.

NOTE 5: This parameter is tested on a sample basis for the TLC2201A and on all devices for the TLC2201B. For other test requirements, please contact the factory. This statement has no bearing on testing or nontesting of other parameters.



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**TLC2201C electrical characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2201C			UNIT
			MIN	TYP	MAX	
$V_{IO}$ Input offset voltage	$V_{IC} = 0, \quad R_S = 50\ \Omega$	25°C		100	500	$\mu\text{V}$
		Full range			600	
$\alpha_{V_{IO}}$ Temperature coefficient of input offset voltage		Full range		0.5		$\mu\text{V}/^\circ\text{C}$
Input offset voltage long-term drift (see Note 4)		25°C		0.001	0.005	$\mu\text{V}/\text{mo}$
$I_{IO}$ Input offset current		25°C		0.5	60	$\text{pA}$
		Full range			100	
$I_{IB}$ Input bias current		25°C		1	60	$\text{pA}$
		Full range			100	
$V_{ICR}$ Common-mode input voltage range	$R_S = 50\ \Omega$	Full range	0 to 2.7		V	
$V_{OH}$ Maximum high-level output voltage	$R_L = 10\ \text{k}\Omega$	25°C	4.7	4.8	V	
		Full range	4.7			
$V_{OL}$ Maximum low-level output voltage	$I_O = 0$	25°C		0 50	mV	
		Full range		50		
$A_{VD}$ Large-signal differential voltage amplification	$V_O = 1\text{ V to }4\text{ V}, \quad R_L = 500\ \text{k}\Omega$	25°C	150	315	V/mV	
		Full range	100			
	$V_O = 1\text{ V to }4\text{ V}, \quad R_L = 10\ \text{k}\Omega$	25°C	25	55		
		Full range	15			
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICR\text{min}}, \quad V_O = 0, \quad R_S = 50\ \Omega$	25°C	90	110	dB	
		Full range	85			
$k_{SVR}$ Supply voltage rejection ratio ( $\Delta V_{DD\pm}/\Delta V_{IO}$ )	$V_{DD} = 4.6\text{ V to }16\text{ V}$	25°C	90	110	dB	
		Full range	85			
$I_{DD}$ Supply current	$V_O = 2.5\text{ V}, \quad \text{No load}$	25°C		1 1.5	mA	
		Full range		1.5		

† Full range is 0°C to +70°C.

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.

**TLC2201C operating characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2201C			UNIT
			MIN	TYP	MAX	
SR Slew rate at unity gain	$V_O = 0.5\text{ V to }2.5\text{ V}, \quad R_L = 10\ \text{k}\Omega, \quad C_L = 100\ \text{pF}$	25°C	1.8	2.5	$\text{V}/\mu\text{s}$	
		Full range	1.3			
$V_n$ Equivalent input noise voltage	$f = 10\ \text{Hz}$	25°C		18	$\text{nV}/\sqrt{\text{Hz}}$	
	$f = 1\ \text{kHz}$	25°C		8		
$V_{N(PP)}$ Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ to }1\ \text{Hz}$	25°C		0.5	$\mu\text{V}$	
	$f = 0.1\text{ to }10\ \text{Hz}$	25°C		0.7		
$I_n$ Equivalent input noise current		25°C		0.6	$\text{fA}/\sqrt{\text{Hz}}$	
Gain-bandwidth product	$f = 10\ \text{kHz}, \quad R_L = 10\ \text{k}\Omega, \quad C_L = 100\ \text{pF}$	25°C		1.8	MHz	
$\phi_m$ Phase margin at unity gain	$R_L = 10\ \text{k}\Omega, \quad C_L = 100\ \text{pF}$	25°C		45°		

† Full range is 0°C to +70°C.



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**TLC2201C electrical characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2201AC			TLC2201BC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
$V_{IO}$ Input offset voltage	$V_{IC} = 0, R_S = 50\ \Omega$	25°C	80	200		80	200	$\mu\text{V}$	
		Full range		300		300			
$\alpha_{VIO}$ Temperature coefficient of input offset voltage		Full range	0.5			0.5		$\mu\text{V}/^\circ\text{C}$	
Input offset voltage long-term drift (see Note 4)		25°C	0.001	0.005		0.001	0.005	$\mu\text{V}/\text{mo}$	
$I_{IO}$ Input offset current		25°C	0.5	60		0.5	60	$\text{pA}$	
		Full range		100		100			
$I_{IB}$ Input bias current		25°C	1	60		1	60	$\text{pA}$	
	Full range		100		100				
$V_{ICR}$ Common-mode input voltage range	$R_S = 50\ \Omega$	Full range	0 to 2.7			0 to 2.7	$\text{V}$		
$V_{OH}$ Maximum high-level output voltage	$R_L = 10\ \text{k}\Omega$	25°C	4.7	4.8		4.7	4.8	$\text{V}$	
		Full range	4.7			4.7			
$V_{OL}$ Maximum low-level output voltage	$I_O = 0$	25°C		0	50		0	$\text{mV}$	
		Full range			50		50		
$AVD$ Large-signal differential voltage amplification	$V_O = 1\ \text{V to } 4\ \text{V}, R_L = 500\ \text{k}\Omega$	25°C	150	315		150	315	$\text{V}/\text{mV}$	
		Full range	100			100			
	$V_O = 1\ \text{V to } 4\ \text{V}, R_L = 10\ \text{k}\Omega$	25°C	25	55		25	55		
		Full range	15			15			
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, V_O = 0, R_S = 50\ \Omega$	25°C	90	110		90	110	$\text{dB}$	
		Full range	85			85			
$k_{SVR}$ Supply voltage rejection ratio ( $\Delta V_{DD} / \Delta V_{IO}$ )	$V_{DD} = 4.6\ \text{V to } 16\ \text{V}$	25°C	90	110		90	110	$\text{dB}$	
		Full range	85			85			
$I_{DD}$ Supply current	$V_O = 2.5\ \text{V}, \text{ No load}$	25°C		1	1.5		1	$\text{mA}$	
		Full range			1.5		1.5		

† Full range is 0°C to +70°C.

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.



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**TLC2201C operating characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2201AC			TLC2201BC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR Slew rate at unity gain	$V_O = 0.5\text{ V to }2.5\text{ V},$ $R_L = 10\text{ k}\Omega, C_L = 100\text{ pF}$	25°C	1.8	2.5		1.8	2.5		V/ $\mu$ s
		Full range	1.3			1.3			
$V_n$ Equivalent input noise voltage (see Note 5)	$f = 10\text{ Hz}$	25°C		18	35		18	30	nV/ $\sqrt{\text{Hz}}$
	$f = 1\text{ kHz}$	25°C		8	15		8	12	
$V_{N(PP)}$ Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ to }1\text{ Hz}$	25°C		0.5			0.5		$\mu$ V
	$f = 0.1\text{ to }10\text{ Hz}$	25°C		0.7			0.7		
$I_n$ Equivalent input noise current		25°C		0.6			0.6		fA/ $\sqrt{\text{Hz}}$
Gain-bandwidth product	$f = 10\text{ kHz}, R_L = 10\text{ k}\Omega,$ $C_L = 100\text{ pF}$	25°C		1.8			1.8		MHz
$\phi_m$ Phase margin at unity gain	$R_L = 10\text{ k}\Omega, C_L = 100\text{ pF}$	25°C		45°			45°		

† Full range is 0°C to +70°C.

NOTE 5: This parameter is tested on a sample basis for the TLC2201A and on all devices for the TLC2201B. For other test requirements, please contact the factory. This statement has no bearing on testing or nontesting of other parameters.

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**TLC2202C electrical characteristics at specified free-air temperature,  $V_{DD\pm} = \pm 5\text{ V}$  (unless otherwise specified)**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2202C			UNIT
			MIN	TYP	MAX	
$V_{IO}$ Input offset voltage	$V_{IC} = 0, R_S = 50\ \Omega$	25°C	100	1000	$\mu\text{V}$	
		Full range	1150			
$\alpha_{V_{IO}}$ Temperature coefficient of input offset voltage		Full range	0.5		$\mu\text{V}/^\circ\text{C}$	
Input offset voltage long-term drift (see Note 4)		25°C	0.001	0.005	$\mu\text{V}/\text{mo}$	
$I_{IO}$ Input offset current		25°C	0.5	60	pA	
		Full range	100			
$I_{IB}$ Input bias current		25°C	1	60		
		Full range	100			
$V_{ICR}$ Common-mode input voltage range	$R_S = 50\ \Omega$	Full range	-5 to 2.7	V		
$V_{OM+}$ Maximum positive peak output voltage swing	$R_L = 10\ \text{k}\Omega$	25°C	4.7	4.8	V	
		Full range	4.7			
$V_{OM-}$ Maximum negative peak output voltage swing		25°C	-4.7	-4.9	V	
		Full range	-4.7			
$A_{VD}$ Large-signal differential voltage amplification	$V_O = \pm 4\ \text{V}, R_L = 500\ \text{k}\Omega$	25°C	300	560	V/mV	
		Full range	200			
	$V_O = \pm 4\ \text{V}, R_L = 10\ \text{k}\Omega$	25°C	50	100		
		Full range	25			
CMRR Common-mode rejection ratio	$V_O = 0, R_S = 50\ \Omega, V_{IC} = V_{ICRmin}$	25°C	80	115	dB	
		Full range	80			
$k_{SVR}$ Supply-voltage rejection ratio ( $\Delta V_{DD\pm}/\Delta V_{IO}$ )	$V_{DD\pm} = \pm 2.3\ \text{V to } \pm 8\ \text{V}$	25°C	80	110	dB	
		Full range	80			
$I_{DD}$ Supply current	$V_O = 0, \text{ No load}$	25°C	1.8	2.7	mA	
		Full range	2.7			

† Full range is 0°C to +70°C.

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.

**TLC2202C operating characteristics at specified free-air temperature,  $V_{DD\pm} = \pm 5\ \text{V}$**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2202C			UNIT
			MIN	TYP	MAX	
SR Slew rate at unity gain	$V_O = \pm 2.3\ \text{V}, R_L = 10\ \text{k}\Omega, C_L = 100\ \text{pF}$	25°C	1.8	2.7	$\text{V}/\mu\text{s}$	
		Full range	1.3			
$V_n$ Equivalent input noise voltage	$f = 10\ \text{Hz}$	25°C	18		$\text{nV}/\sqrt{\text{Hz}}$	
	$f = 1\ \text{kHz}$	25°C	8			
$V_{N(PP)}$ Peak-to-peak equivalent input noise voltage	$f = 0.1\ \text{to } 1\ \text{Hz}$	25°C	0.5		$\mu\text{V}$	
	$f = 0.1\ \text{to } 10\ \text{Hz}$	25°C	0.7			
$I_n$ Equivalent input noise current		25°C	0.6		$\text{fA}/\sqrt{\text{Hz}}$	
Gain-bandwidth product	$f = 10\ \text{kHz}, R_L = 10\ \text{k}\Omega, C_L = 100\ \text{pF}$	25°C	1.9		MHz	
$\phi_m$ Phase margin at unity gain	$R_L = 10\ \text{k}\Omega, C_L = 100\ \text{pF}$	25°C	48°			

† Full range is 0°C to +70°C.



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**TLC2202C electrical characteristics at specified free-air temperature,  $V_{DD\pm} = \pm 5\text{ V}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2202AC			TLC2202BC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
$V_{IO}$ Input offset voltage		25°C	80	500		80	500	$\mu\text{V}$	
		Full range			650		650		
$\alpha_{VIO}$ Temperature coefficient of input offset voltage		Full range	0.5			0.5			$\mu\text{V}/^\circ\text{C}$
Input offset voltage long-term drift (see Note 4)	$V_{IC} = 0, R_S = 50\ \Omega$	25°C	0.001	0.005		0.001	0.005	$\mu\text{V}/\text{mo}$	
$I_{IO}$ Input offset current		25°C	0.5	60		0.5	60	$\text{pA}$	
		Full range			100		100		
$I_{IB}$ Input bias current		25°C	1	60		1	60	$\text{pA}$	
		Full range			100		100		
$V_{ICR}$ Common-mode input voltage range	$R_S = 50\ \Omega$	Full range	-5 to 2.7			-5 to 2.7			V
$V_{OM+}$ Maximum positive peak output voltage swing	$R_L = 10\ \text{k}\Omega$	25°C	4.7	4.8		4.7	4.8	V	
		Full range	4.7			4.7			
$V_{OM-}$ Maximum negative peak output voltage swing		25°C	-4.7	-4.9		-4.7	-4.9	V	
		Full range	-4.7			-4.7			
$A_{VD}$ Large-signal differential voltage amplification	$V_O = \pm 4\text{ V}, R_L = 500\ \text{k}\Omega$	25°C	300	560		300	560	V/mV	
		Full range	200			200			
	$V_O = \pm 4\text{ V}, R_L = 10\ \text{k}\Omega$	25°C	50	100		50	100		
		Full range	25			25			
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICR\text{min}}, V_O = 0, R_S = 50\ \Omega$	25°C	80	115		80	115	dB	
		Full range	80			80			
$k_{SVR}$ Supply-voltage rejection ratio ( $\Delta V_{DD\pm}/\Delta V_{IO}$ )	$V_{DD\pm} = \pm 2.3\text{ V to } \pm 8\text{ V}$	25°C	80	110		80	110	dB	
		Full range	80			80			
$I_{DD}$ Supply current	$V_O = 0, \text{ No load}$	25°C	1.8	2.7		1.8	2.7	mA	
		Full range			2.7		2.7		

† Full range is 0°C to +70°C.

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.

**TLC2202C operating characteristics at specified free-air temperature,  $V_{DD\pm} = \pm 5\text{ V}$**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2202AC			TLC2202BC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR Slew rate at unity gain	$V_O = \pm 2.3\text{ V}, R_L = 10\ \text{k}\Omega, C_L = 100\ \text{pF}$	25°C	1.8	2.7		1.8	2.7	$\text{V}/\mu\text{s}$	
		Full range	1.3			1.3			
$V_n$ Equivalent input noise voltage (see Note 5)	$f = 10\ \text{Hz}$	25°C	18	35		18	30	$\text{nV}/\sqrt{\text{Hz}}$	
	$f = 1\ \text{kHz}$	25°C	8	15		8	12		
$V_{N(PP)}$ Peak-to-peak equivalent input noise voltage	$f = 0.1\ \text{to } 1\ \text{Hz}$	25°C	0.5			0.5			$\mu\text{V}$
	$f = 0.1\ \text{to } 10\ \text{Hz}$	25°C	0.7			0.7			
$I_n$ Equivalent input noise current		25°C	0.6			0.6			$\text{fA}/\sqrt{\text{Hz}}$
Gain-bandwidth product	$f = 10\ \text{kHz}, R_L = 10\ \text{k}\Omega, C_L = 100\ \text{pF}$	25°C	1.9			1.9			MHz
$\phi_m$ Phase margin at unity gain	$R_I = 10\ \text{k}\Omega, C_I = 100\ \text{pF}$	25°C	48°			48°			

† Full range is 0°C to +70°C.

NOTE 5: This parameter is tested on a sample basis for the TLC2202A and on all devices for the TLC2202B. For other test requirements, please contact the factory. This statement has no bearing on testing or nontesting of other parameters.



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**TLC2202C electrical characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLC2202C			UNIT
			MIN	TYP	MAX	
$V_{IO}$ Input offset voltage	$V_{IC} = 0, \quad R_S = 50\ \Omega$	25°C	100	1000		$\mu\text{V}$
		Full range		1150		
$\alpha_{V_{IO}}$ Temperature coefficient of input offset voltage		Full range	0.5			$\mu\text{V}/^\circ\text{C}$
Input offset voltage long-term drift (see Note 4)		25°C	0.001	0.005		$\mu\text{V}/\text{mo}$
$I_{IO}$ Input offset current		25°C	0.5	60		$\text{pA}$
		Full range		100		
$I_{IB}$ Input bias current	25°C	1	60		$\text{pA}$	
	Full range		100			
$V_{ICR}$ Common-mode input voltage range	$R_S = 50\ \Omega$	Full range	0 to 2.7		V	
$V_{OH}$ Maximum high-level output voltage	$R_L = 10\ \text{k}\Omega$	25°C	4.7	4.8		V
		Full range	4.7			
$V_{OL}$ Maximum low-level output voltage	$I_O = 0$	25°C	0	50		mV
		Full range		50		
$A_{VD}$ Large-signal differential voltage amplification	$V_O = 1\ \text{V to } 4\ \text{V},$ $R_L = 500\ \text{k}\Omega$	25°C	150	315		V/mV
		Full range	100			
	$V_O = 1\ \text{V to } 4\ \text{V},$ $R_L = 10\ \text{k}\Omega$	25°C	25	55		
		Full range	15			
CMRR Common-mode rejection ratio	$V_O = 0, \quad V_{IC} = V_{ICR\text{min}},$ $R_S = 50\ \Omega$	25°C	75	110		dB
		Full range	75			
$k_{SVR}$ Supply-voltage rejection ratio ( $\Delta V_{DD\pm}/\Delta V_{IO}$ )	$V_{DD} = 4.6\ \text{V to } 16\ \text{V}$	25°C	80	110		dB
		Full range	80			
$I_{DD}$ Supply current	$V_O = 0, \quad \text{No load}$	25°C	1.7	2.6		mA
		Full range		2.6		

$^\dagger$  Full range is 0°C to +70°C.

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using Arrhenius equation and assuming an activation energy of 0.96 eV.

**TLC2202C operating characteristics at specified free-air temperature,  $V_{DD} = 5\ \text{V}$**

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLC2202C			UNIT
			MIN	TYP	MAX	
SR Slew rate at unity gain	$V_O = 0.5\ \text{V to } 2.5\ \text{V},$ $R_L = 10\ \text{k}\Omega, \quad C_L = 100\ \text{pF}$	25°C	1.6	2.5		$\text{V}/\mu\text{s}$
		Full range	1.1			
$V_n$ Equivalent input noise voltage	$f = 10\ \text{Hz}$	25°C		18		$\text{nV}/\sqrt{\text{Hz}}$
	$f = 1\ \text{kHz}$	25°C		8		
$V_{N(\text{PP})}$ Peak-to-peak equivalent input noise voltage	$f = 0.1\ \text{to } 1\ \text{Hz}$	25°C		0.5		$\mu\text{V}$
	$f = 0.1\ \text{to } 10\ \text{Hz}$	25°C		0.7		
$I_n$ Equivalent input noise current		25°C		0.6		$\text{fA}/\sqrt{\text{Hz}}$
Gain-bandwidth product	$f = 10\ \text{kHz}, \quad R_L = 10\ \text{k}\Omega,$ $C_L = 100\ \text{pF}$	25°C		1.9		MHz
$\phi_m$ Phase margin at unity gain	$R_L = 10\ \text{k}\Omega, \quad C_L = 100\ \text{pF}$	25°C		47°		

$^\dagger$  Full range is 0°C to +70°C.



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**TLC2202C electrical characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2202AC			TLC2202BC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
$V_{IO}$ Input offset voltage	$V_{IC} = 0, R_S = 50\ \Omega$	25°C	80	500	80	500	$\mu\text{V}$		
		Full range	650		650				
$\alpha_{VIO}$ Temperature coefficient of input offset voltage		Full range	0.5		0.5		$\mu\text{V}/^\circ\text{C}$		
Input offset voltage long-term drift (see Note 4)		25°C	0.001	0.005	0.001	0.005	$\mu\text{V}/\text{mo}$		
$I_{IO}$ Input offset current		25°C	0.5	60	0.5	60	$\text{pA}$		
		Full range	100		100				
$I_{IB}$ Input bias current		25°C	1	60	1	60	$\text{pA}$		
		Full range	100		100				
$V_{ICR}$ Common-mode input voltage range	$R_S = 50\ \Omega$	Full range	0 to 2.7		0 to 2.7		V		
$V_{OH}$ Maximum high-level output voltage	$R_L = 10\ \text{k}\Omega$	25°C	4.7	4.8	4.7	4.8	V		
		Full range	4.7		4.7				
$V_{OL}$ Maximum low-level output voltage	$I_O = 0$	25°C	0	50	0	50	mV		
		Full range	50		50				
$A_{VD}$ Large-signal differential voltage amplification	$V_O = 1\text{ V to }4\text{ V}, R_L = 500\ \text{k}\Omega$	25°C	150	315	150	315	V/mV		
		Full range	100		100				
	$V_O = 1\text{ V to }4\text{ V}, R_L = 10\ \text{k}\Omega$	25°C	25	55	25	55			
		Full range	15		15				
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICR\text{min}}, V_O = 0, R_S = 50\ \Omega$	25°C	75	110	75	110	dB		
		Full range	75		75				
$k_{SVR}$ Supply-voltage rejection ratio ( $\Delta V_{DD\pm}/\Delta V_{IO}$ )	$V_{DD} = 4.6\text{ V to }16\text{ V}$	25°C	80	110	80	110	dB		
		Full range	80		80				
$I_{DD}$ Supply current	$V_O = 2.5\text{ V}, \text{ No load}$	25°C	1.7	2.6	1.7	2.6	mA		
		Full range	2.6		2.6				

† Full range is 0°C to +70°C.

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.

**TLC2202C operating characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2202AC			TLC2202BC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR Slew rate at unity gain	$V_O = 0.5\text{ V to }2.5\text{ V}, R_L = 10\ \text{k}\Omega, C_L = 100\ \text{pF}$	25°C	1.6	2.5	1.6	2.5	$\text{V}/\mu\text{s}$		
		Full range	1.1		1.1				
$V_n$ Equivalent input noise voltage (see Note 5)	$f = 10\ \text{Hz}$	25°C	18	35	18	30	$\text{nV}/\sqrt{\text{Hz}}$		
	$f = 1\ \text{kHz}$	25°C	8	15	8	12			
$V_{N(PP)}$ Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ to }1\ \text{Hz}$	25°C	0.5		0.5		$\mu\text{V}$		
	$f = 0.1\text{ to }10\ \text{Hz}$	25°C	0.7		0.7				
$I_n$ Equivalent input noise current		25°C	0.6		0.6		$\text{fA}/\sqrt{\text{Hz}}$		
Gain-bandwidth product	$f = 10\ \text{kHz}, R_L = 10\ \text{k}\Omega, C_L = 100\ \text{pF}$	25°C	1.9		1.9		MHz		
$\phi_m$ Phase margin at unity gain	$R_I = 10\ \text{k}\Omega, C_I = 100\ \text{pF}$	25°C	47°		47°				

† Full range is 0°C to +70°C.

NOTE 5: This parameter is tested on a sample basis for the TLC2202A and on all devices for the TLC2202B. For other test requirements, please contact the factory. This statement has no bearing on testing or nontesting of other parameters.



**TLC220x, TLC220xA, TLC220xB, TLC220xY**  
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**TLC2201I electrical characteristics at specified free-air temperature,  $V_{DD\pm} = \pm 5\text{ V}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2201I			UNIT
			MIN	TYP	MAX	
$V_{IO}$ Input offset voltage	$V_{IC} = 0, R_S = 50\ \Omega$	25°C	100	500	$\mu\text{V}$	
		Full range	650			
$\alpha_{V_{IO}}$ Temperature coefficient of input offset voltage		Full range	0.5		$\mu\text{V}/^\circ\text{C}$	
Input offset voltage long-term drift (see Note 4)		25°C	0.001	0.005	$\mu\text{V}/\text{mo}$	
$I_{IO}$ Input offset current		25°C	0.5	60	$\text{pA}$	
		Full range	150			
$I_{IB}$ Input bias current		25°C	1	60	$\text{pA}$	
		Full range	150			
$V_{ICR}$ Common-mode input voltage range	$R_S = 50\ \Omega$	Full range	–5 to 2.7		V	
$V_{OM+}$ Maximum positive peak output voltage swing	$R_L = 10\ \text{k}\Omega$	25°C	4.7	4.8	V	
		Full range	4.7			
$V_{OM-}$ Maximum negative peak output voltage swing		25°C	–4.7	–4.9	V	
		Full range	–4.7			
$A_{VD}$ Large-signal differential voltage amplification	$V_O = \pm 4\ \text{V}, R_L = 500\ \text{k}\Omega$	25°C	400	560	V/mV	
		Full range	250			
	$V_O = \pm 4\ \text{V}, R_L = 10\ \text{k}\Omega$	25°C	90	100		
		Full range	65			
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, V_O = 0, R_S = 50\ \Omega$	25°C	90	115	dB	
		Full range	85			
$k_{SVR}$ Supply voltage rejection ratio ( $\Delta V_{DD\pm}/\Delta V_{IO}$ )	$V_{DD\pm} = \pm 2.3\ \text{V to } \pm 8\ \text{V}$	25°C	90	110	dB	
		Full range	85			
$I_{DD}$ Supply current	$V_O = 0, \text{ No load}$	25°C	1.1	1.5	mA	
		Full range	1.5			

† Full range is –40°C to +85°C.

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.

**TLC2201I operating characteristics at specified free-air temperature,  $V_{DD\pm} = \pm 5\ \text{V}$**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2201I			UNIT
			MIN	TYP	MAX	
SR Slew rate at unity gain	$V_O = \pm 2.3\ \text{V}, R_L = 10\ \text{k}\Omega, C_L = 100\ \text{pF}$	25°C	2	2.7	$\text{V}/\mu\text{s}$	
		Full range	1.4			
$V_n$ Equivalent input noise voltage	f = 10 Hz	25°C	18		$\text{nV}/\sqrt{\text{Hz}}$	
	f = 1 kHz	25°C	8			
$V_{N(PP)}$ Peak-to-peak equivalent input noise voltage	f = 0.1 to 1 Hz	25°C	0.5		$\mu\text{V}$	
	f = 0.1 to 10 Hz	25°C	0.7			
$I_n$ Equivalent input noise current		25°C	0.6		$\text{fA}/\sqrt{\text{Hz}}$	
Gain-bandwidth product	f = 10 kHz, $R_L = 10\ \text{k}\Omega, C_L = 100\ \text{pF}$	25°C	1.9		MHz	
$\phi_m$ Phase margin at unity gain	$R_L = 10\ \text{k}\Omega, C_L = 100\ \text{pF}$	25°C	48°			

† Full range is –40°C to +85°C.



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**TLC2201I electrical characteristics at specified free-air temperature,  $V_{DD\pm} = \pm 5\text{ V}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2201AI			TLC2201BI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
$V_{IO}$ Input offset voltage	$V_{IC} = 0, R_S = 50\ \Omega$	25°C	80	200		80	200	$\mu\text{V}$	
		Full range			350		350		
$\alpha_{VIO}$ Temperature coefficient of input offset voltage		Full range	0.5			0.5		$\mu\text{V}/^\circ\text{C}$	
Input offset voltage long-term drift (see Note 4)		25°C	0.001	0.005		0.001	0.005	$\mu\text{V}/\text{mo}$	
$I_{IO}$ Input offset current		25°C	0.5	60		0.5	60	$\text{pA}$	
		Full range			150		150		
$I_{IB}$ Input bias current		25°C	1	60		1	60	$\text{pA}$	
		Full range			150		150		
$V_{ICR}$ Common-mode input voltage range	$R_S = 50\ \Omega$	Full range	–5 to 2.7		–5 to 2.7		$\text{V}$		
$V_{OM+}$ Maximum positive peak output voltage swing	$R_L = 10\ \text{k}\Omega$	25°C	4.7	4.8		4.7	4.8	$\text{V}$	
		Full range	4.7			4.7			
$V_{OM-}$ Maximum negative peak output voltage swing		25°C	–4.7	–4.9		–4.7	–4.9	$\text{V}$	
		Full range	–4.7			–4.7			
$A_{VD}$ Large-signal differential voltage amplification	$V_O = \pm 4\ \text{V}, R_L = 500\ \text{k}\Omega$	25°C	400	560		400	560	$\text{V}/\text{mV}$	
		Full range	250			250			
	$V_O = \pm 4\ \text{V}, R_L = 10\ \text{k}\Omega$	25°C	90	100		90	100		
		Full range	65			65			
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, V_O = 0, R_S = 50\ \Omega$	25°C	90	115		90	115	dB	
		Full range	85			85			
$k_{SVR}$ Supply voltage rejection ratio ( $\Delta V_{DD\pm}/\Delta V_{IO}$ )	$V_{DD\pm} = \pm 2.3\ \text{V}$ to $\pm 8\ \text{V}$	25°C	90	110		90	110	dB	
		Full range	85			85			
$I_{DD}$ Supply current	$V_O = 0, \text{ No load}$	25°C	1.1	1.5		1.1	1.5	mA	
		Full range			1.5		1.5		

† Full range is  $-40^\circ\text{C}$  to  $+85^\circ\text{C}$ .

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation assuming an activation energy of 0.96 eV.

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**TLC2201I operating characteristics at specified free-air temperature,  $V_{DD\pm} = \pm 5\text{ V}$**

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLC2201AI			TLC2201BI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR Slew rate at unity gain	$V_O = \pm 2.3\text{ V}$ , $R_L = 10\text{ k}\Omega$ , $C_L = 100\text{ pF}$	25°C	2	2.7		2	2.7		V/ $\mu\text{s}$
		Full range	1.4			1.4			
$V_n$ Equivalent input noise voltage (see Note 5)	$f = 10\text{ Hz}$	25°C		18	35		18	30	nV/ $\sqrt{\text{Hz}}$
	$f = 1\text{ kHz}$	25°C		8	15		8	12	
$V_{N(PP)}$ Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ to }1\text{ Hz}$	25°C		0.5			0.5		$\mu\text{V}$
	$f = 0.1\text{ to }10\text{ Hz}$	25°C		0.7			0.7		
$I_n$ Equivalent input noise current		25°C		0.6			0.6		fA/ $\sqrt{\text{Hz}}$
Gain-bandwidth product	$f = 10\text{ kHz}$ , $R_L = 10\text{ k}\Omega$ , $C_L = 100\text{ pF}$	25°C		1.9			1.9		MHz
$\phi_m$ Phase margin at unity gain	$R_L = 10\text{ k}\Omega$ , $C_L = 100\text{ pF}$	25°C		48°			48°		

$^\dagger$  Full range is  $-40^\circ\text{C}$  to  $+85^\circ\text{C}$ .

NOTE 5: This parameter is tested on a sample basis for the TLC2201A and on all devices for the TLC2201B. For other test requirements, please contact the factory. This statement has no bearing on testing or nontesting of other parameters.



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**TLC22011 electrical characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLC22011			UNIT
			MIN	TYP	MAX	
$V_{IO}$ Input offset voltage	$V_{IC} = 0, \quad R_S = 50\ \Omega$	25°C		100	500	$\mu\text{V}$
		Full range			650	
$\alpha_{VIO}$ Temperature coefficient of input offset voltage		Full range		0.5		$\mu\text{V}/^\circ\text{C}$
Input offset voltage long-term drift (see Note 4)		25°C		0.001	0.005	$\mu\text{V}/\text{mo}$
$I_{IO}$ Input offset current		25°C		0.5	60	$\text{pA}$
		Full range			150	
$I_{IB}$ Input bias current		25°C		1	60	$\text{pA}$
		Full range			150	
$V_{ICR}$ Common-mode input voltage range	$R_S = 50\ \Omega$	Full range	0 to 2.7		V	
$V_{OH}$ Maximum high-level output voltage	$R_L = 10\ \text{k}\Omega$	25°C	4.7	4.8	V	
		Full range	4.7			
$V_{OL}$ Maximum low-level output voltage	$I_O = 0$	25°C		0 50	mV	
		Full range		50		
$A_{VD}$ Large-signal differential voltage amplification	$V_O = 1\ \text{V to } 4\ \text{V},$ $R_L = 500\ \text{k}\Omega$	25°C	150	315	V/mV	
		Full range	100			
	$V_O = 1\ \text{V to } 4\ \text{V},$ $R_L = 10\ \text{k}\Omega$	25°C	25	55		
		Full range	15			
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICR\text{min}},$ $V_O = 0, \quad R_S = 50\ \Omega$	25°C	90	110	dB	
		Full range	85			
$k_{SVR}$ Supply voltage rejection ratio ( $\Delta V_{DD\pm} / \Delta V_{IO}$ )	$V_{DD} = 4.6\ \text{V to } 16\ \text{V}$	25°C	90	110	dB	
		Full range	85			
$I_{DD}$ Supply current	$V_O = 2.5\ \text{V}, \quad \text{No load}$	25°C		1 1.5	mA	
		Full range		1.5		

$^\dagger$  Full range is  $-40^\circ\text{C}$  to  $+85^\circ\text{C}$ .

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.

**TLC22011 operating characteristics at specified free-air temperature,  $V_{DD} = 5\ \text{V}$**

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLC22011			UNIT
			MIN	TYP	MAX	
SR Slew rate at unity gain	$V_O = 0.5\ \text{V to } 2.5\ \text{V},$ $R_L = 10\ \text{k}\Omega, \quad C_L = 100\ \text{pF}$	25°C	1.8	2.5	$\text{V}/\mu\text{s}$	
		Full range	1.2			
$V_n$ Equivalent input noise voltage	$f = 10\ \text{Hz}$	25°C		18	$\text{nV}/\sqrt{\text{Hz}}$	
	$f = 1\ \text{kHz}$	25°C		8		
$V_{N(PP)}$ Peak-to-peak equivalent input noise voltage	$f = 0.1\ \text{to } 1\ \text{Hz}$	25°C		0.5	$\mu\text{V}$	
	$f = 0.1\ \text{to } 10\ \text{Hz}$	25°C		0.7		
$I_n$ Equivalent input noise current		25°C		0.6	$\text{fA}/\sqrt{\text{Hz}}$	
Gain-bandwidth product	$f = 10\ \text{kHz}, \quad R_L = 10\ \text{k}\Omega,$ $C_L = 100\ \text{pF}$	25°C		1.8	MHz	
$\phi_m$ Phase margin at unity gain	$R_L = 10\ \text{k}\Omega, \quad C_L = 100\ \text{pF}$	25°C		45°		

$^\dagger$  Full range is  $-40^\circ\text{C}$  to  $+85^\circ\text{C}$ .



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**TLC2201I electrical characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2201AI			TLC2201BI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
$V_{IO}$ Input offset voltage	$V_{IC} = 0, R_S = 50\ \Omega$	25°C	80	200		80	200	$\mu\text{A}$	
		Full range		350		350			
$\alpha_{VIO}$ Temperature coefficient of input offset voltage		Full range	0.5			0.5		$\mu\text{V}/^\circ\text{C}$	
Input offset voltage long-term drift (see Note 4)		25°C	0.001	0.005		0.001	0.005	$\mu\text{V}/\text{mo}$	
$I_{IO}$ Input offset current		25°C	0.5	60		0.5	60	$\text{pA}$	
		Full range		150		150			
$I_{IB}$ Input bias current	25°C	1	60		1	60	$\text{pA}$		
	Full range		150		150				
$V_{ICR}$ Common-mode input voltage range	$R_S = 50\ \Omega$	Full range	0 to 2.7			0 to 2.7	V		
$V_{OH}$ Maximum high-level output voltage	$R_L = 10\ \text{k}\Omega$	25°C	4.7	4.8		4.7	4.8	V	
		Full range	4.7			4.7			
$V_{OL}$ Maximum low-level output voltage	$I_O = 0$	25°C		0	50		0	mV	
		Full range		50		50			
$A_{VD}$ Large-signal differential voltage amplification	$V_O = 1\text{ V to }4\text{ V}, R_L = 500\ \text{k}\Omega$	25°C	150	315		150	315	V/mV	
		Full range	100			100			
	$V_O = 1\text{ V to }4\text{ V}, R_L = 10\ \text{k}\Omega$	25°C	25	55		25	55		
		Full range	15			15			
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICR\text{min}}, V_O = 0, R_S = 50\ \Omega$	25°C	90	110		90	110	dB	
		Full range	85			85			
$k_{SVR}$ Supply voltage rejection ratio ( $\Delta V_{DD\pm} / \Delta V_{IO}$ )	$V_{DD} = 4.6\text{ V to }16\text{ V}$	25°C	90	110		90	110	dB	
		Full range	85			85			
$I_{DD}$ Supply current	$V_O = 2.5\text{ V}, \text{ No load}$	25°C		1	1.5		1	mA	
		Full range			1.5		1.5		

† Full range is  $-40^\circ\text{C}$  to  $+85^\circ\text{C}$ .

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.



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**TLC2201I operating characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2201AI			TLC2201BI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR Slew rate at unity gain	$V_O = 0.5\text{ V to }2.5\text{ V}$ , $R_L = 10\text{ k}\Omega$ , $C_L = 100\text{ pF}$	25°C	1.8	2.5		1.8	2.5		V/ $\mu$ s
		Full range	1.2			1.2			
$V_n$ Equivalent input noise voltage (see Note 5)	$f = 10\text{ Hz}$	25°C		18	35		18	30	nV/ $\sqrt{\text{Hz}}$
	$f = 1\text{ kHz}$	25°C		8	15		8	12	
$V_{N(PP)}$ Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ to }1\text{ Hz}$	25°C		0.5			0.5		$\mu$ V
	$f = 0.1\text{ to }10\text{ Hz}$	25°C		0.7			0.7		
$I_n$ Equivalent input noise current		25°C		0.6			0.6		fA/ $\sqrt{\text{Hz}}$
Gain-bandwidth product	$f = 10\text{ kHz}$ , $R_L = 10\text{ k}\Omega$ , $C_L = 100\text{ pF}$	25°C		1.8			1.8		MHz
$\phi_m$ Phase margin at unity gain	$R_L = 10\text{ k}\Omega$ , $C_L = 100\text{ pF}$	25°C		45°			45°		

† Full range is  $-40^\circ\text{C}$  to  $+85^\circ\text{C}$ .

NOTE 5: This parameter is tested on a sample basis for the TLC2201A and on all devices for the TLC2201B. For other test requirements, please contact the factory. This statement has no bearing on testing or nontesting of other parameters.

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**TLC2202I electrical characteristics at specified free-air temperature,  $V_{DD\pm} = \pm 5\text{ V}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2202I			UNIT
			MIN	TYP	MAX	
$V_{IO}$ Input offset voltage	$V_{IC} = 0, R_S = 50\ \Omega$	25°C	100	1000	$\mu\text{V}$	
		Full range	1200			
$\alpha_{VIO}$ Temperature coefficient of input offset voltage		Full range	0.5	$\mu\text{V}/^\circ\text{C}$		
Input offset voltage long-term drift (see Note 4)		25°C	0.001	0.005	$\mu\text{V}/\text{mo}$	
$I_{IO}$ Input offset current		25°C	0.5	60	$\text{pA}$	
		Full range	150			
$I_{IB}$ Input bias current		25°C	1	60	$\text{pA}$	
		Full range	150			
$V_{ICR}$ Common-mode input voltage range		$R_S = 50\ \Omega$	Full range	-5 to 2.7	V	
$V_{OM+}$ Maximum positive peak output voltage swing		$R_L = 10\ \text{k}\Omega$	25°C	4.7	4.8	V
$V_{OM-}$ Maximum negative peak output voltage swing	Full range		4.7			
	25°C		-4.7	-4.9	V	
Full range	-4.7					
$A_{VD}$ Large-signal differential voltage amplification	$V_O = \pm 4\ \text{V}, R_L = 500\ \text{k}\Omega$	25°C	300	560	V/mV	
		Full range	150			
	$V_O = \pm 4\ \text{V}, R_L = 10\ \text{k}\Omega$	25°C	50	100		
		Full range	25			
CMRR Common-mode rejection ratio	$V_O = 0, V_{IC} = V_{ICR\text{min}}, R_S = 50\ \Omega$	25°C	80	115	dB	
		Full range	80			
$k_{SVR}$ Supply-voltage rejection ratio ( $\Delta V_{DD\pm}/\Delta V_{IO}$ )	$V_{DD} = \pm 2.3\ \text{V}$ to $\pm 8\ \text{V}$	25°C	80	110	dB	
		Full range	80			
$I_{DD}$ Supply current	$V_O = 0, \text{No load}$	25°C	1.8	2.7	mA	
		Full range	2.7			

† Full range is  $-40^\circ\text{C}$  to  $+85^\circ\text{C}$ .

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.

**TLC2202I operating characteristics at specified free-air temperature,  $V_{DD\pm} = \pm 5\ \text{V}$**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2202I			UNIT
			MIN	TYP	MAX	
SR Slew rate at unity gain	$V_O = \pm 2.3\ \text{V}, R_L = 10\ \text{k}\Omega, C_L = 100\ \text{pF}$	25°C	1.8	2.7	$\text{V}/\mu\text{s}$	
		Full range	1.2			
$V_n$ Equivalent input noise voltage	$f = 10\ \text{Hz}$	25°C	18		$\text{nV}/\sqrt{\text{Hz}}$	
	$f = 1\ \text{kHz}$	25°C	8			
$V_{N(PP)}$ Peak-to-peak equivalent input noise voltage	$f = 0.1$ to $1\ \text{Hz}$	25°C	0.5		$\mu\text{V}$	
	$f = 0.1$ to $10\ \text{Hz}$	25°C	0.7			
$I_n$ Equivalent input noise current		25°C	0.6		$\text{fA}/\sqrt{\text{Hz}}$	
Gain-bandwidth product	$f = 10\ \text{kHz}, R_L = 10\ \text{k}\Omega, C_L = 100\ \text{pF}$	25°C	1.9		MHz	
$\phi_m$ Phase margin at unity gain	$R_L = 10\ \text{k}\Omega, C_L = 100\ \text{pF}$	25°C	48°			

† Full range is  $-40^\circ\text{C}$  to  $+85^\circ\text{C}$ .



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**TLC2202I electrical characteristics at specified free-air temperature,  $V_{DD\pm} = \pm 5\text{ V}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2202AI			TLC2202BI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
$V_{IO}$ Input offset voltage		25°C	80	500		80	500	$\mu\text{V}$	
		Full range			700		700		
$\alpha_{VIO}$ Temperature coefficient of input offset voltage		Full range	0.5			0.5			$\mu\text{V}/^\circ\text{C}$
Input offset voltage long-term drift (see Note 4)	$V_{IC} = 0, R_S = 50\ \Omega$	25°C	0.001	0.005		0.001	0.005	$\mu\text{V}/\text{mo}$	
$I_{IO}$ Input offset current		25°C	0.5	60		0.5	60	$\text{pA}$	
		Full range			150		150		
$I_{IB}$ Input bias current		25°C	1	60		1	60	$\text{pA}$	
	Full range			150		150			
$V_{ICR}$ Common-mode input voltage range	$R_S = 50\ \Omega$	Full range	–5 to 2.7			–5 to 2.7			V
$V_{OM+}$ Maximum positive peak output voltage swing	$R_L = 10\ \text{k}\Omega$	25°C	4.7	4.8		4.7	4.8	V	
		Full range	4.7			4.7			
$V_{OM-}$ Maximum negative peak output voltage swing		25°C	–4.7	–4.9		–4.7	–4.9	V	
		Full range	–4.7			–4.7			
$A_{VD}$ Large-signal differential voltage amplification	$V_O = \pm 4\ \text{V}, R_L = 500\ \text{k}\Omega$	25°C	300	560		300	560	V/mV	
		Full range	150			150			
	$V_O = \pm 4\ \text{V}, R_L = 10\ \text{k}\Omega$	25°C	50	100		50	100		
		Full range	25			25			
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, V_O = 0, R_S = 50\ \Omega$	25°C	80	115		80	115	dB	
		Full range	80			80			
$k_{SVR}$ Supply-voltage rejection ratio ( $\Delta V_{DD\pm}/\Delta V_{IO}$ )	$V_{DD\pm} \pm 2.3\ \text{V}$ to $\pm 8\ \text{V}$	25°C	80	110		80	110	dB	
		Full range	80			80			
$I_{DD}$ Supply current	$V_O = 0, \text{ No load}$	25°C	1.8	2.7		1.8	2.7	mA	
		Full range	2.7			2.7			

† Full range is  $-40^\circ\text{C}$  to  $+85^\circ\text{C}$ .

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.

**TLC2202I operating characteristics at specified free-air temperature,  $V_{DD\pm} = \pm 5\ \text{V}$**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2202AI			TLC2202BI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR Slew rate at unity gain	$V_O = \pm 2.3\ \text{V}, R_L = 10\ \text{k}\Omega, C_L = 100\ \text{pF}$	25°C	1.8	2.7		1.8	2.7	V/ $\mu\text{s}$	
		Full range	1.2			1.2			
$V_n$ Equivalent input noise voltage (see Note 5)	$f = 10\ \text{Hz}$	25°C	18	35		18	30	$\text{nV}/\sqrt{\text{Hz}}$	
	$f = 1\ \text{kHz}$	25°C	8	15		8	12		
$V_{N(PP)}$ Peak-to-peak equivalent input noise voltage	$f = 0.1$ to $1\ \text{Hz}$	25°C	0.5			0.5			$\mu\text{V}$
	$f = 0.1$ to $10\ \text{Hz}$	25°C	0.7			0.7			
$I_n$ Equivalent input noise current		25°C	0.6			0.6			$\text{fA}/\sqrt{\text{Hz}}$
Gain-bandwidth product	$f = 10\ \text{kHz}, R_L = 10\ \text{k}\Omega, C_L = 100\ \text{pF}$	25°C	1.9			1.9			MHz
$\phi_m$ Phase margin at unity gain	$R_I = 10\ \text{k}\Omega, C_I = 100\ \text{pF}$	25°C	48°			48°			

† Full range is  $-40^\circ\text{C}$  to  $+85^\circ\text{C}$ .

NOTE 5: This parameter is tested on a sample basis for the TLC2202A and on all devices for the TLC2202B. For other test requirements, please contact the factory. This statement has no bearing on testing or nontesting of other parameters.



**TLC220x, TLC220xA, TLC220xB, TLC220xY**  
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**TLC2202I electrical characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2202I			UNIT
			MIN	TYP	MAX	
$V_{IO}$ Input offset voltage	$V_{IC} = 0, R_S = 50\ \Omega$	25°C	100	1000	$\mu\text{V}$	
		Full range	1200			
$\alpha_{V_{IO}}$ Temperature coefficient of input offset voltage		Full range	0.5		$\mu\text{V}/^\circ\text{C}$	
Input offset voltage long-term drift (see Note 4)		25°C	0.001	0.005	$\mu\text{V}/\text{mo}$	
$I_{IO}$ Input offset current		25°C	0.5	60	$\text{pA}$	
		Full range	150			
$I_{IB}$ Input bias current		25°C	1	60	$\text{pA}$	
		Full range	150			
$V_{ICR}$ Common-mode input voltage range	$R_S = 50\ \Omega$	Full range	0 to 2.7	$\text{V}$		
$V_{OH}$ Maximum high-level output voltage	$R_L = 10\ \text{k}\Omega$	25°C	4.7	4.8	$\text{V}$	
		Full range	4.7			
$V_{OL}$ Maximum low-level output voltage	$I_O = 0$	25°C	0	50	$\text{mV}$	
		Full range	50			
$A_{VD}$ Large-signal differential voltage amplification	$V_O = 1\ \text{V to } 4\ \text{V}, R_L = 500\ \text{k}\Omega$	25°C	150	315	$\text{V}/\text{mV}$	
		Full range	100			
	$V_O = 1\ \text{V to } 4\ \text{V}, R_L = 10\ \text{k}\Omega$	25°C	25	55		
		Full range	15			
CMRR Common-mode rejection ratio	$V_O = 0, V_{IC} = V_{ICR\text{min}}, R_S = 50\ \Omega$	25°C	75	110	$\text{dB}$	
		Full range	75			
$k_{SVR}$ Supply-voltage rejection ratio ( $\Delta V_{DD\pm}/\Delta V_{IO}$ )	$V_{DD} = 4.6\ \text{V to } 16\ \text{V}$	25°C	80	110	$\text{dB}$	
		Full range	80			
$I_{DD}$ Supply current	$V_O = 2.5\ \text{V}, \text{ No load}$	25°C	1.7	2.6	$\text{mA}$	
		Full range	2.6			

† Full range is  $-40^\circ\text{C}$  to  $+85^\circ\text{C}$ .

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.

**TLC2202I operating characteristics at specified free-air temperature,  $V_{DD} = 5\ \text{V}$**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2202I			UNIT
			MIN	TYP	MAX	
SR Slew rate at unity gain	$V_O = 0.5\ \text{V to } 2.5\ \text{V}, R_L = 10\ \text{k}\Omega, C_L = 100\ \text{pF}$	25°C	1.6	2.5	$\text{V}/\mu\text{s}$	
		Full range	1			
$V_n$ Equivalent input noise voltage	$f = 10\ \text{Hz}$	25°C	18		$\text{nV}/\sqrt{\text{Hz}}$	
	$f = 1\ \text{kHz}$	25°C	8			
$V_{N(PP)}$ Peak-to-peak equivalent input noise voltage	$f = 0.1\ \text{to } 1\ \text{Hz}$	25°C	0.5		$\mu\text{V}$	
	$f = 0.1\ \text{to } 10\ \text{Hz}$	25°C	0.7			
$I_n$ Equivalent input noise current		25°C	0.6		$\text{fA}/\sqrt{\text{Hz}}$	
Gain-bandwidth product	$f = 10\ \text{kHz}, R_L = 10\ \text{k}\Omega, C_L = 100\ \text{pF}$	25°C	1.9		$\text{MHz}$	
$\phi_m$ Phase margin at unity gain	$R_L = 10\ \text{k}\Omega, C_L = 100\ \text{pF}$	25°C	47°			

† Full range is  $-40^\circ\text{C}$  to  $+85^\circ\text{C}$ .



# TLC220x, TLC220xA, TLC220xB, TLC220xY Advanced LinCMOS™ LOW-NOISE PRECISION OPERATIONAL AMPLIFIERS

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**TLC2202I electrical characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2202AI			TLC2202BI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
$V_{IO}$ Input offset voltage		25°C	80	500		80	500	$\mu\text{V}$	
		Full range			700		700		
$\alpha_{VIO}$ Temperature coefficient of input offset voltage		Full range	0.5			0.5			$\mu\text{V}/^\circ\text{C}$
Input offset voltage long-term drift (see Note 4)	$V_{IC} = 0, R_S = 50\ \Omega$	25°C	0.001	0.005		0.001	0.005	$\mu\text{V}/\text{mo}$	
$I_{IO}$ Input offset current		25°C	0.5			0.5			$\text{pA}$
		Full range	150			150			
$I_{IB}$ Input bias current		25°C	1			1			$\text{pA}$
		Full range	150			150			
$V_{ICR}$ Common-mode input voltage range		$R_S = 50\ \Omega$	Full range	0 to 2.7		0 to 2.7		V	
$V_{OH}$ Maximum high-level output voltage	$R_L = 10\ \text{k}\Omega$	25°C	4.7	4.8		4.7	4.8	V	
		Full range	4.7			4.7			
$V_{OL}$ Maximum low-level output voltage	$I_O = 0$	25°C	0			0			mV
		Full range	50			50			
$A_{VD}$ Large-signal differential voltage amplification	$V_O = 1\ \text{V to } 4\ \text{V}, R_L = 500\ \text{k}\Omega$	25°C	150	315		150	315	V/mV	
		Full range	100			100			
	$V_O = 1\ \text{V to } 4\ \text{V}, R_L = 10\ \text{k}\Omega$	25°C	25	55		25	55		
		Full range	15			15			
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICR\text{min}}, V_O = 0, R_S = 50\ \Omega$	25°C	75	110		75	110	dB	
		Full range	75			75			
$k_{SVR}$ Supply-voltage rejection ratio ( $\Delta V_{DD\pm}/\Delta V_{IO}$ )	$V_{DD} = 4.6\ \text{V to } 16\ \text{V}$	25°C	80	110		80	110	dB	
		Full range	80			80			
$I_{DD}$ Supply current	$V_O = 2.5\ \text{V}, \text{ No load}$	25°C	1.7			1.7			mA
		Full range	2.6			2.6			

† Full range is  $-40^\circ\text{C}$  to  $+85^\circ\text{C}$

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.

**TLC2202I operating characteristics at specified free-air temperature,  $V_{DD} = 5\ \text{V}$**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2202AI			TLC2202BI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR Slew rate at unity gain	$V_O = 0.5\ \text{V to } 2.5\ \text{V}, R_L = 10\ \text{k}\Omega, C_L = 100\ \text{pF}$	25°C	1.6	2.5		1.6	2.5	V/ $\mu\text{s}$	
		Full range	1			1			
$V_n$ Equivalent input noise voltage (see Note 5)	$f = 10\ \text{Hz}$	25°C	18			18			nV/ $\sqrt{\text{Hz}}$
	$f = 1\ \text{kHz}$	25°C	8			8			
$V_{N(PP)}$ Peak-to-peak equivalent input noise voltage	$f = 0.1\ \text{to } 1\ \text{Hz}$	25°C	0.5			0.5			$\mu\text{V}$
	$f = 0.1\ \text{to } 10\ \text{Hz}$	25°C	0.7			0.7			
$I_n$ Equivalent input noise current		25°C	0.6			0.6			fA/ $\sqrt{\text{Hz}}$
Gain-bandwidth product	$f = 10\ \text{kHz}, R_L = 10\ \text{k}\Omega, C_L = 100\ \text{pF}$	25°C	1.9			1.9			MHz
$\phi_m$ Phase margin at unity gain	$R_I = 10\ \text{k}\Omega, C_I = 100\ \text{pF}$	25°C	47°			47°			

† Full range is  $-40^\circ\text{C}$  to  $+85^\circ\text{C}$

NOTE 5: This parameter is tested on a sample basis for the TLC2202A and on all devices for the TLC2202B. For other test requirements, please contact the factory. This statement has no bearing on testing or nontesting of other parameters.



**TLC220x, TLC220xA, TLC220xB, TLC220xY**  
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**TLC2201M electrical characteristics at specified free-air temperature,  $V_{DD\pm} = \pm 5\text{ V}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2201M			UNIT
			MIN	TYP	MAX	
$V_{IO}$ Input offset voltage	$V_{IC} = 0, R_S = 50\ \Omega$	25°C	100	500	$\mu\text{V}$	
		Full range	700			
$\alpha_{V_{IO}}$ Temperature coefficient of input offset voltage		Full range	0.5		$\mu\text{V}/^\circ\text{C}$	
Input offset voltage long-term drift (see Note 4)		25°C	0.001	0.005	$\mu\text{V}/\text{mo}$	
		25°C	0.5	60	$\text{pA}$	
$I_{IO}$ Input offset current		Full range	500			
$I_{IB}$ Input bias current	25°C	1	60	$\text{pA}$		
	Full range	500				
$V_{ICR}$ Common-mode input voltage range	$R_S = 50\ \Omega$	Full range	-5 to 2.7	V		
$V_{OM+}$ Maximum positive peak output voltage swing	$R_L = 10\ \text{k}\Omega$	25°C	4.7	4.8	V	
		Full range	4.7			
$V_{OM-}$ Maximum negative peak output voltage swing		25°C	-4.7	-4.9	V	
		Full range	-4.7			
$A_{VD}$ Large-signal differential voltage amplification	$V_O = \pm 4\ \text{V}, R_L = 500\ \text{k}\Omega$	25°C	400	560	V/mV	
		Full range	200			
	$V_O = \pm 4\ \text{V}, R_L = 10\ \text{k}\Omega$	25°C	90	100		
		Full range	45			
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, V_O = 0, R_S = 50\ \Omega$	25°C	90	115	dB	
		Full range	85			
$k_{SVR}$ Supply voltage rejection ratio ( $\Delta V_{DD\pm}/\Delta V_{IO}$ )	$V_{DD\pm} = \pm 2.3\ \text{V to } \pm 8\ \text{V}$	25°C	90	110	dB	
		Full range	85			
$I_{DD}$ Supply current	$V_O = 0, \text{ No load}$	25°C	1.1	1.5	mA	
		Full range	1.5			

† Full range is -55°C to 125°C.

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.

**TLC2201M operating characteristics at specified free-air temperature,  $V_{DD\pm} = \pm 5\ \text{V}$**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2201M			UNIT
			MIN	TYP	MAX	
SR Slew rate at unity gain	$V_O = \pm 2.3\ \text{V}, R_L = 10\ \text{k}\Omega, C_L = 100\ \text{pF}$	25°C	2	2.7	$\text{V}/\mu\text{s}$	
		Full range	1.3			
$V_n$ Equivalent input noise voltage	$f = 10\ \text{Hz}$	25°C	18		$\text{nV}/\sqrt{\text{Hz}}$	
	$f = 1\ \text{kHz}$	25°C	8			
$V_{N(PP)}$ Peak-to-peak equivalent input noise voltage	$f = 0.1\ \text{to } 1\ \text{Hz}$	25°C	0.5		$\mu\text{V}$	
	$f = 0.1\ \text{to } 10\ \text{Hz}$	25°C	0.7			
$I_n$ Equivalent input noise current		25°C	0.6		$\text{fA}/\sqrt{\text{Hz}}$	
Gain-bandwidth product	$f = 10\ \text{kHz}, R_L = 10\ \text{k}\Omega, C_L = 100\ \text{pF}$	25°C	1.9		MHz	
$\phi_m$ Phase margin	$R_L = 10\ \text{k}\Omega, C_L = 100\ \text{pF}$	25°C	48°			

† Full range is -55°C to 125°C.



# TLC220x, TLC220xA, TLC220xB, TLC220xY Advanced LinCMOS™ LOW-NOISE PRECISION OPERATIONAL AMPLIFIERS

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**TLC2201M electrical characteristics at specified free-air temperature,  $V_{DD\pm} = \pm 5\text{ V}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2201AM			TLC2201BM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
$V_{IO}$ Input offset voltage	$V_{IC} = 0, R_S = 50\ \Omega$	25°C	80	200		80	200	$\mu\text{V}$	
		Full range		400		400			
$\alpha_{VIO}$ Temperature coefficient of input offset voltage		Full range	0.5			0.5		$\mu\text{V}/^\circ\text{C}$	
Input offset voltage long-term drift (see Note 4)		25°C	0.001	0.005		0.001	0.005	$\mu\text{V}/\text{mo}$	
$I_{IO}$ Input offset current		25°C	0.5	60		0.5	60	$\text{pA}$	
		Full range		500		500			
$I_{IB}$ Input bias current		25°C	1	60		1	60	$\text{pA}$	
	Full range		500		500				
$V_{ICR}$ Common-mode input voltage range	$R_S = 50\ \Omega$	Full range	-5 to 2.7			-5 to 2.7	$\text{V}$		
$V_{OM+}$ Maximum positive peak output voltage swing	$R_L = 10\ \text{k}\Omega$	25°C	4.7	4.8		4.7	4.8	$\text{V}$	
		Full range	4.7			4.7			
$V_{OM-}$ Maximum negative peak output voltage swing		25°C	-4.7	-4.9		-4.7	-4.9	$\text{V}$	
		Full range	-4.7			-4.7			
$A_{VD}$ Large-signal differential voltage amplification	$V_O = \pm 4\ \text{V}, R_L = 500\ \text{k}\Omega$	25°C	400	560		400	560	$\text{V}/\text{mV}$	
		Full range	200			200			
	$V_O = \pm 4\ \text{V}, R_L = 10\ \text{k}\Omega$	25°C	90	100		90	100		
		Full range	45			45			
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, V_O = 0, R_S = 50\ \Omega$	25°C	90	115		90	115	dB	
		Full range	85			85			
$k_{SVR}$ Supply voltage rejection ratio ( $\Delta V_{DD\pm}/\Delta V_{IO}$ )	$V_{DD\pm} = \pm 2.3\ \text{V to } \pm 8\ \text{V}$	25°C	90	110		90	110	dB	
		Full range	85			85			
$I_{DD}$ Supply current	$V_O = 0, \text{ No load}$	25°C	1.1	1.5		1.1	1.5	mA	
		Full range		1.5			1.5		

† Full range is  $-55^\circ\text{C}$  to  $125^\circ\text{C}$ .

NOTE 4: Typical values are based on the input offset voltage shift observable through 168 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.

**TLC220x, TLC220xA, TLC220xB, TLC220xY**  
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**TLC2201M operating characteristics at specified free-air temperature,  $V_{DD\pm} = \pm 5\text{ V}$**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2201AM			TLC2201BM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR Slew rate at unity gain	$V_O = \pm 2.3\text{ V}$ , $R_L = 10\text{ k}\Omega$ , $C_L = 100\text{ pF}$	25°C	2	2.7		2	2.7		V/ $\mu\text{s}$
		Full range	1.3			1.3			
$V_n$ Equivalent input noise voltage (see Note 5)	f = 10 Hz	25°C		18	35		18	30	nV/ $\sqrt{\text{Hz}}$
	f = 1 kHz	25°C		8	15		8	12	
$V_{N(PP)}$ Peak-to-peak equivalent input noise voltage	f = 0.1 to 1 Hz	25°C		0.5			0.5		$\mu\text{V}$
	f = 0.1 to 10 Hz	25°C		0.7			0.7		
$I_n$ Equivalent input noise current		25°C		0.6			0.6		fA/ $\sqrt{\text{Hz}}$
Gain-bandwidth product	f = 10 kHz, $R_L = 10\text{ k}\Omega$ , $C_L = 100\text{ pF}$	25°C		1.9			1.9		MHz
$\phi_m$ Phase margin at unity gain	$R_L = 10\text{ k}\Omega$ , $C_L = 100\text{ pF}$	25°C		48°			48°		

† Full range is  $-55^\circ\text{C}$  to  $125^\circ\text{C}$ .

NOTE 5: This parameter is tested on a sample basis for the TLC2201A and on all devices for the TLC2201B. For other test requirements, please contact the factory. This statement has no bearing on testing or nontesting of other parameters.



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**TLC2201M electrical characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2201M			UNIT
			MIN	TYP	MAX	
$V_{IO}$ Input offset voltage	$V_{IC} = 0, R_S = 50\ \Omega$	25°C		100	500	$\mu\text{V}$
		Full range			700	
$\alpha_{VIO}$ Temperature coefficient of input offset voltage		Full range		0.5		$\mu\text{V}/^\circ\text{C}$
Input offset voltage long-term drift (see Note 4)		25°C		0.001	0.005*	$\mu\text{V}/\text{mo}$
$I_{IO}$ Input offset current		25°C		0.5	60	$\text{pA}$
		Full range			500	
$I_{IB}$ Input bias current		25°C		1	60	$\text{pA}$
		Full range			500	
$V_{ICR}$ Common-mode input voltage range	$R_S = 50\ \Omega$	Full range	0 to 2.7		V	
$V_{OH}$ Maximum high-level output voltage	$R_L = 10\ \text{k}\Omega$	25°C	4.7	4.8	V	
		Full range	4.7			
$V_{OL}$ Maximum low-level output voltage	$I_O = 0$	25°C		0 50	mV	
		Full range		50		
$A_{VD}$ Large-signal differential voltage amplification	$V_O = 1\text{ V to }4\text{ V}, R_L = 500\ \text{k}\Omega$	25°C	150	315	V/mV	
		Full range	75			
	$V_O = 1\text{ V to }4\text{ V}, R_L = 10\ \text{k}\Omega$	25°C	25	55		
		Full range	10			
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, V_O = 0, R_S = 50\ \Omega$	25°C	90	110	dB	
		Full range	85			
$k_{SVR}$ Supply voltage rejection ratio ( $\Delta V_{DD\pm} / \Delta V_{IO}$ )	$V_{DD} = 4.6\text{ V to }16\text{ V}$	25°C	90	110	dB	
		Full range	85			
$I_{DD}$ Supply current	$V_O = 2.5\text{ V}, \text{ No load}$	25°C		1 1.5	mA	
		Full range		1.5		

\*On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.

† Full range is  $-55^\circ\text{C}$  to  $125^\circ\text{C}$ .

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.

**TLC2201M operating characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2201M			UNIT
			MIN	TYP	MAX	
SR Slew rate at unity gain	$V_O = 0.5\text{ V to }2.5\text{ V}, R_L = 10\ \text{k}\Omega, C_L = 100\ \text{pF}$	25°C	1.8	2.5	$\text{V}/\mu\text{s}$	
		Full range	1.1			
$V_n$ Equivalent input noise voltage	$f = 10\ \text{Hz}$	25°C		18	$\text{nV}/\sqrt{\text{Hz}}$	
	$f = 1\ \text{kHz}$	25°C		8		
$V_{N(PP)}$ Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ to }1\ \text{Hz}$	25°C		0.5	$\mu\text{V}$	
	$f = 0.1\text{ to }10\ \text{Hz}$	25°C		0.7		
$I_n$ Equivalent input noise current		25°C		0.6	$\text{fA}/\sqrt{\text{Hz}}$	
Gain-bandwidth product	$f = 10\ \text{kHz}, R_L = 10\ \text{k}\Omega, C_L = 100\ \text{pF}$	25°C		1.8	MHz	
$\phi_m$ Phase margin at unity gain	$R_L = 10\ \text{k}\Omega, C_L = 100\ \text{pF}$	25°C		45°		

† Full range is  $-55^\circ\text{C}$  to  $125^\circ\text{C}$ .



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**TLC2201M electrical characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2201AM			TLC2201BM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
$V_{IO}$ Input offset voltage		25°C	80	200		80	200	$\mu\text{V}$	
		Full range			400		400		
$\alpha_{VIO}$ Temperature coefficient of input offset voltage		Full range	0.5			0.5			$\mu\text{V}/^\circ\text{C}$
Input offset voltage long-term drift (see Note 4)	$V_{IC} = 0, R_S = 50\ \Omega$	25°C	0.001	0.005		0.001	0.005	$\mu\text{V}/\text{mo}$	
$I_{IO}$ Input offset current		25°C	0.5	60		0.5	60	$\text{pA}$	
		Full range			500		500		
$I_{IB}$ Input bias current		25°C	1	60		1	60	$\text{pA}$	
	Full range			500		500			
$V_{ICR}$ Common-mode input voltage range	$R_S = 50\ \Omega$	Full range	0 to 2.7			0 to 2.7	$\text{V}$		
$V_{OH}$ Maximum high-level output voltage	$R_L = 10\ \text{k}\Omega$	25°C	4.7	4.8		4.7	4.8	$\text{V}$	
		Full range	4.7			4.7			
$V_{OL}$ Maximum low-level output voltage	$I_O = 0$	25°C		0	50		0	$\text{V}$	
		Full range			50		50		
$A_{VD}$ Large-signal differential voltage amplification	$V_O = 1\ \text{V to } 4\ \text{V}, R_L = 500\ \text{k}\Omega$	25°C	150	315		150	315	$\text{V}/\text{mV}$	
		Full range	75			75			
	$V_O = 1\ \text{V to } 4\ \text{V}, R_L = 10\ \text{k}\Omega$	25°C	25	55		25	55		
		Full range	10			10			
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, V_O = 0, R_S = 50\ \Omega$	25°C	90	110		90	110	dB	
		Full range	85			85			
$k_{SVR}$ Supply voltage rejection ratio ( $\Delta V_{DD} \pm / \Delta V_{IO}$ )	$V_{DD} = 4.6\ \text{V to } 16\ \text{V}$	25°C	90	110		90	110	dB	
		Full range	85			85			
$I_{DD}$ Supply current	$V_O = 2.5\ \text{V}, \text{ No load}$	25°C	1.1	1.5		1.1	1.5	mA	
		Full range			1.5		1.5		

† Full range is  $-55^\circ\text{C}$  to  $125^\circ\text{C}$ .

NOTE 4: Typical values are based on the input offset voltage shift observable through 168 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.



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**TLC2201M operating characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2201AM			TLC2201BM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR Slew rate at unity gain	$V_O = 0.5\text{ V to }2.5\text{ V}$ , $R_L = 10\text{ k}\Omega$ , $C_L = 100\text{ pF}$	25°C	1.8	2.5		1.8	2.5		V/ $\mu\text{s}$
		Full range	1.1			1.1			
$V_n$ Equivalent input noise voltage (see Note 5)	$f = 10\text{ Hz}$ $f = 1\text{ kHz}$	25°C		18	35		18	30	nV/ $\sqrt{\text{Hz}}$
		25°C		8	15		8	12	
$V_{N(PP)}$ Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ to }1\text{ Hz}$ $f = 0.1\text{ to }10\text{ Hz}$	25°C		0.5			0.5		$\mu\text{V}$
		25°C		0.7			0.7		
$I_n$ Equivalent input noise current		25°C		0.6			0.6		fA/ $\sqrt{\text{Hz}}$
Gain-bandwidth product	$f = 10\text{ kHz}$ , $R_L = 10\text{ k}\Omega$ , $C_L = 100\text{ pF}$	25°C		1.8			1.8		MHz
$\phi_m$ Phase margin at unity gain	$R_L = 10\text{ k}\Omega$ , $C_L = 100\text{ pF}$	25°C		45°			45°		

† Full range is  $-55^\circ\text{C}$  to  $125^\circ\text{C}$ .

NOTE 5: This parameter is tested on a sample basis for the TLC2201A and on all devices for the TLC2201B. For other test requirements, please contact the factory. This statement has no bearing on testing or nontesting of other parameters.

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**TLC2202M electrical characteristics at specified free-air temperature,  $V_{DD\pm} = \pm 5\text{ V}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2202M			UNIT
			MIN	TYP	MAX	
$V_{IO}$ Input offset voltage	$V_{IC} = 0, R_S = 50\ \Omega$	25°C	100	1000	$\mu\text{V}$	
		Full range	1250			
$\alpha_{V_{IO}}$ Temperature coefficient of input offset voltage		Full range	0.5		$\mu\text{V}/^\circ\text{C}$	
Input offset voltage long-term drift (see Note 4)		25°C	0.001	0.005	$\mu\text{V}/\text{mo}$	
$I_{IO}$ Input offset current		25°C	0.5	60	$\text{pA}$	
		Full range	500			
$I_{IB}$ Input bias current		25°C	1	60	$\text{pA}$	
		Full range	500			
$V_{ICR}$ Common-mode input voltage range	$R_S = 50\ \Omega$	Full range	-5 to 2.7	$\text{V}$		
$V_{OM+}$ Maximum positive peak output voltage swing	$R_L = 10\ \text{k}\Omega$	25°C	4.7	4.8	$\text{V}$	
$V_{OM-}$ Maximum negative peak output voltage swing		Full range	4.7			
		25°C	-4.7	-4.9	$\text{V}$	
Full range		-4.7				
$A_{VD}$ Large-signal differential voltage amplification	$V_O = 1\ \text{V to } 4\ \text{V}, R_L = 500\ \text{k}\Omega$	25°C	300	560	$\text{V}/\text{mV}$	
		Full range	100			
	$V_O = 1\ \text{V to } 4\ \text{V}, R_L = 10\ \text{k}\Omega$	25°C	50	100		
		Full range	25			
CMRR Common-mode rejection ratio	$V_O = 0, V_{IC} = V_{ICR\text{min}}, R_S = 50\ \Omega$	25°C	80	115	$\text{dB}$	
		Full range	80			
$k_{SVR}$ Supply-voltage rejection ratio ( $\Delta V_{DD\pm}/\Delta V_{IO}$ )	$V_{DD} = \pm 2.3\ \text{V to } \pm 8\ \text{V}$	25°C	80	110	$\text{dB}$	
		Full range	80			
$I_{DD}$ Supply current	$V_O = 0, \text{ No load}$	25°C	1.8	2.7	$\text{mA}$	
		Full range	2.7			

\*On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.

† Full range is  $-55^\circ\text{C}$  to  $125^\circ\text{C}$ .

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using Arrhenius equation and assuming an activation energy of 0.96 eV.

**TLC2202M operating characteristics at specified free-air temperature,  $V_{DD\pm} = \pm 5\ \text{V}$**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2202M			UNIT
			MIN	TYP	MAX	
SR Slew rate at unity gain	$V_O = \pm 2.3\ \text{V}, R_L = 10\ \text{k}\Omega, C_L = 100\ \text{pF}$	25°C	1.8	2.7	$\text{V}/\mu\text{s}$	
		Full range	1.1			
$V_n$ Equivalent input noise voltage	$f = 10\ \text{Hz}$	25°C	18		$\text{nV}/\sqrt{\text{Hz}}$	
	$f = 1\ \text{kHz}$	25°C	8			
$V_{N(PP)}$ Peak-to-peak equivalent input noise voltage	$f = 0.1\ \text{to } 1\ \text{Hz}$	25°C	0.5		$\mu\text{V}$	
	$f = 0.1\ \text{to } 10\ \text{Hz}$	25°C	0.7			
$I_n$ Equivalent input noise current		25°C	0.6		$\text{fA}/\sqrt{\text{Hz}}$	
Gain-bandwidth product	$f = 10\ \text{kHz}, R_L = 10\ \text{k}\Omega, C_L = 100\ \text{pF}$	25°C	1.9		$\text{MHz}$	
$\phi_m$ Phase margin at unity gain	$R_L = 10\ \text{k}\Omega, C_L = 100\ \text{pF}$	25°C	48°			

† Full range is  $-55^\circ\text{C}$  to  $125^\circ\text{C}$ .



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**TLC2202M electrical characteristics at specified free-air temperature,  $V_{DD\pm} = \pm 5\text{ V}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2202AM			TLC2202BM			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
$V_{IO}$ Input offset voltage		25°C		80	500		80	500	$\mu\text{V}$	
		Full range			750			750		
$\alpha_{VIO}$ Temperature coefficient of input offset voltage		Full range		0.5			0.5	$\mu\text{V}/^\circ\text{C}$		
Input offset voltage long-term drift (see Note 4)	$V_{IC} = 0, R_S = 50\ \Omega$	25°C		0.001	0.005*		0.001	0.005*	$\mu\text{V}/\text{mo}$	
$I_{IO}$ Input offset current		25°C		0.5	60		0.5	60	$\text{pA}$	
		Full range			500			500		
$I_{IB}$ Input bias current		25°C			1	60		1	60	$\text{pA}$
		Full range				500			500	
$V_{ICR}$ Common-mode input voltage range		$R_S = 50\ \Omega$	Full range		-5 to 2.7			-5 to 2.7	V	
$V_{OM+}$ Maximum positive peak output voltage swing	$R_L = 10\ \text{k}\Omega$	25°C		4.7	4.8		4.7	4.8	V	
		Full range			4.7			4.7		
$V_{OM-}$ Maximum negative peak output voltage swing		25°C		-4.7	-4.9		-4.7	-4.9	V	
		Full range			-4.7			-4.7		
$A_{VD}$ Large-signal differential voltage amplification	$V_O = \pm 4\text{ V}, R_L = 500\ \text{k}\Omega$	25°C		300	560		300	560	V/mV	
		Full range			100			100		
	$V_O = \pm 4\text{ V}, R_L = 10\ \text{k}\Omega$	25°C		50	100		50	100		
		Full range			25			25		
CMRR Common-mode rejection ratio	$V_O = 0, V_{IC} = V_{ICRmin}, R_S = 50\ \Omega$	25°C		80	115		80	115	dB	
		Full range			80			80		
$k_{SVR}$ Supply-voltage rejection ratio ( $\Delta V_{DD\pm} / \Delta V_{IO}$ )	$V_{DD\pm} = \pm 2.3\text{ V to } \pm 8\text{ V}$	25°C		80	110		80	110	dB	
		Full range			80			80		
$I_{DD}$ Supply current	$V_O = 0, \text{ No load}$	25°C		1.8	2.7		1.8	2.7	mA	
		Full range			2.7			2.7		

\*On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.

† Full range is  $-55^\circ\text{C}$  to  $125^\circ\text{C}$ .

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.

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**TLC2202M operating characteristics at specified free-air temperature,  $V_{DD\pm} = \pm 5\text{ V}$**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2202AM			TLC2202BM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR Slew rate at unity gain	$V_O = \pm 2.3\text{ V}$ , $R_L = 10\text{ k}\Omega$ , $C_L = 100\text{ pF}$	25°C	1.8	2.7		1.8	2.7		V/ $\mu\text{s}$
		Full range	1.1			1.1			
$V_n$ Equivalent input noise voltage (see Note 5)	f = 10 Hz	25°C		18	35*		18	30*	nV/ $\sqrt{\text{Hz}}$
	f = 1 kHz	25°C		8	15*		8	12*	
$V_{N(PP)}$ Peak-to-peak equivalent input noise voltage	f = 0.1 to 1 Hz	25°C		0.5			0.5		$\mu\text{V}$
	f = 0.1 to 10 Hz	25°C		0.7			0.7		
$I_n$ Equivalent input noise current		25°C		0.6			0.6		fA/ $\sqrt{\text{Hz}}$
Gain-bandwidth product	f = 10 kHz, $R_L = 10\text{ k}\Omega$ , $C_L = 100\text{ pF}$	25°C		1.9			1.9		MHz
$\phi_m$ Phase margin at unity gain	$R_L = 10\text{ k}\Omega$ , $C_L = 100\text{ pF}$	25°C		48°			48°		

\*On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.

† Full range is -55°C to 125°C.

NOTE 5: This parameter is tested on a sample basis for the TLC2202A and on all devices for the TLC2202B. For other test requirements, please contact the factory. This statement has no bearing on testing or nontesting of other parameters.



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**TLC2202M electrical characteristics at specified free-air temperatures,  $V_{DD} = 5\text{ V}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2202M			UNIT
			MIN	TYP	MAX	
$V_{IO}$ Input offset voltage	$V_{IC} = 0, \quad R_S = 50\ \Omega$	25°C		100	1000	$\mu\text{V}$
		Full range			1250	
$\alpha_{V_{IO}}$ Temperature coefficient of input offset voltage		Full range		0.5		$\mu\text{V}/^\circ\text{C}$
Input offset voltage long-term drift (see Note 4)		25°C		0.001	0.005*	$\mu\text{V}/\text{mo}$
$I_{IO}$ Input offset current		25°C		0.5	60	$\text{pA}$
		Full range			500	
$I_{IB}$ Input bias current		25°C		1	60	$\text{pA}$
		Full range			500	
$V_{ICR}$ Common-mode input voltage range		$R_S = 50\ \Omega$	Full range	0 to 2.7		V
$V_{OH}$ Maximum high-level output voltage		$R_L = 10\ \text{k}\Omega$	25°C	4.7	4.8	V
	Full range		4.7			
$V_{OL}$ Maximum low-level output voltage	$I_O = 0$	25°C		0 50	mV	
		Full range		50		
$A_{VD}$ Large-signal differential voltage amplification	$V_O = 1\text{ V to }4\text{ V},$ $R_L = 500\ \text{k}\Omega$	25°C	150	315	V/mV	
		Full range	75			
	$V_O = 1\text{ V to }4\text{ V},$ $R_L = 10\ \text{k}\Omega$	25°C	25	55		
		Full range	10			
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICR\text{min}}, \quad R_S = 50\ \Omega$	25°C	75	110	dB	
		Full range	75			
$k_{SVR}$ Supply-voltage rejection ratio ( $\Delta V_{DD\pm} / \Delta V_{IO}$ )	$V_{DD} = 4.6\text{ V to }16\text{ V}$	25°C	80	110	dB	
		Full range	80			
$I_{DD}$ Supply current	$V_O = 2.5\text{ V}, \quad \text{No load}$	25°C		1.7 2.6	mA	
		Full range		2.6		

\* On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.

† Full range is  $-55^\circ\text{C}$  to  $125^\circ\text{C}$ .

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.

**TLC2202M operating characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2202M			UNIT
			MIN	TYP	MAX	
SR Slew rate at unity gain	$V_O = 0.5\text{ V to }2.5\text{ V},$ $R_L = 10\ \text{k}\Omega, \quad C_L = 100\ \text{pF}$	25°C	1.6	2.5	$\text{V}/\mu\text{s}$	
		Full range	0.9			
$V_n$ Equivalent input noise voltage	$f = 10\ \text{Hz}$	25°C		18	$\text{nV}/\sqrt{\text{Hz}}$	
	$f = 1\ \text{kHz}$	25°C		8		
$V_{N(\text{PP})}$ Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ to }1\ \text{Hz}$	25°C		0.5	$\mu\text{V}$	
	$f = 0.1\text{ to }10\ \text{Hz}$	25°C		0.7		
$I_n$ Equivalent input noise current		25°C		0.6	$\text{fA}/\sqrt{\text{Hz}}$	
Gain-bandwidth product	$f = 10\ \text{kHz}, \quad R_L = 10\ \text{k}\Omega,$ $C_L = 100\ \text{pF}$	25°C		1.9	MHz	
$\phi_m$ Phase margin at unity gain	$R_L = 10\ \text{k}\Omega, \quad C_L = 100\ \text{pF}$	25°C		47°		

† Full range is  $-55^\circ\text{C}$  to  $125^\circ\text{C}$ .



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**TLC2202M electrical characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2202AM			TLC2202BM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
$V_{IO}$ Input offset voltage	$V_{IC} = 0, R_S = 50\ \Omega$	25°C	80	500		80	500	$\mu\text{V}$	
		Full range		750		750			
$\alpha_{VIO}$ Temperature coefficient of input offset voltage		Full range	0.5			0.5		$\mu\text{V}/^\circ\text{C}$	
Input offset voltage long-term drift (see Note 4)		25°C	0.001	0.005*		0.001	0.005*	$\mu\text{V}/\text{mo}$	
$I_{IO}$ Input offset current		25°C	0.5	60		0.5	60	$\text{pA}$	
		Full range		500		500			
$I_{IB}$ Input bias current		25°C	1	60		1	60	$\text{pA}$	
		Full range		500		500			
$V_{ICR}$ Common-mode input voltage range	$R_S = 50\ \Omega$	Full range	0 to 2.7		0 to 2.7		V		
$V_{OH}$ Maximum high-level output voltage	$R_L = 10\ \text{k}\Omega$	25°C	4.7	4.8		4.7	4.8	V	
		Full range	4.7			4.7			
$V_{OL}$ Maximum low-level output voltage	$I_O = 0$	25°C		0	50		0	mV	
		Full range		50		50			
$A_{VD}$ Large-signal differential voltage amplification	$V_O = 1\text{ V to }4\text{ V}, R_L = 500\ \text{k}\Omega$	25°C	150	315		150	315	V/mV	
		Full range	75			75			
	$V_O = 1\text{ V to }4\text{ V}, R_L = 10\ \text{k}\Omega$	25°C	25	55		25	55		
		Full range	10			10			
CMRR Common-mode rejection ratio	$V_O = 0, V_{IC} = V_{ICRmin}, R_S = 50\ \Omega$	25°C	75	110		75	110	dB	
		Full range	75			75			
$k_{SVR}$ Supply-voltage rejection ratio ( $\Delta V_{DD\pm} / \Delta V_{IO}$ )	$V_{DD} = 4.6\text{ V to }16\text{ V}$	25°C	80	110		80	110	dB	
		Full range	80			80			
$I_{DD}$ Supply current	$V_O = 2.5\text{ V}, \text{ No load}$	25°C		1.7	2.6		1.7	mA	
		Full range		2.6		2.6			

\*On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.

† Full range is  $-55^\circ\text{C}$  to  $125^\circ\text{C}$

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.



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**TLC2202M operating characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2202AM			TLC2202BM			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
SR	Slew rate at unity gain	$V_O = 0.5\text{ V to }2.5\text{ V},$ $R_L = 10\text{ k}\Omega,$ $C_L = 100\text{ pF}$	25°C	1.6	2.5		1.6	2.5	$\text{V}/\mu\text{s}$	
			Full range	0.9			1.1			
$V_n$	Equivalent input noise voltage (see Note 5)	$f = 10\text{ Hz}$	25°C		18	35*		18	30*	$\text{nV}/\sqrt{\text{Hz}}$
			25°C		8	15*		8	12*	
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ to }1\text{ Hz}$	25°C		0.5			0.5		$\mu\text{V}$
			25°C		0.7			0.7		
$I_n$	Equivalent input noise current		25°C		0.6			0.6		$\text{fA}/\sqrt{\text{Hz}}$
	Gain-bandwidth product	$f = 10\text{ kHz},$ $R_L = 10\text{ k}\Omega,$ $C_L = 100\text{ pF}$	25°C		1.9			1.9		MHz
$\phi_m$	Phase margin at unity gain	$R_L = 10\text{ k}\Omega,$ $C_L = 100\text{ pF}$	25°C		47°			47°		

\* On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.

† Full range is  $-55^\circ\text{C}$  to  $125^\circ\text{C}$

NOTE 5: This parameter is tested on a sample basis for the TLC2202A and on all devices for the TLC2202B. For other test requirements, please contact the factory. This statement has no bearing on testing or nontesting of other parameters.

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**TLC2201Y electrical characteristics at  $V_{DD\pm} = \pm 5\text{ V}$ ,  $T_A = 25^\circ\text{C}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	TLC2201Y			UNIT
		MIN	TYP	MAX	
$V_{IO}$ Input offset voltage	$V_{IC} = 0$ , $R_S = 50\ \Omega$	100			$\mu\text{V}$
Input offset voltage long-term drift (see Note 4)		0.001			$\mu\text{V}/\text{mo}$
$I_{IO}$ Input offset current		0.5			$\text{pA}$
$I_{IB}$ Input bias current		1			$\text{pA}$
$V_{OH}$ Maximum high-level output voltage	$R_L = 10\ \text{k}\Omega$	4.8			$\text{V}$
$V_{OL}$ Maximum low-level output voltage	$I_O = 0$	0			$\text{mV}$
$A_{VD}$ Large-signal differential voltage amplification	$V_O = 1\ \text{V to } 4\ \text{V}$ , $R_L = 500\ \Omega$	55			$\text{V}/\text{mV}$
	$V_O = 1\ \text{V to } 4\ \text{V}$ , $R_L = 10\ \Omega$	55			
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}$ , $V_O = 0$ , $R_S = 50\ \Omega$	110			$\text{dB}$
$k_{SVR}$ Supply voltage rejection ratio ( $\Delta V_{DD\pm} / \Delta V_{IO}$ )	$V_{DD} = 4.6\ \text{to } 16\ \text{V}$	110			$\text{dB}$
$I_{DD}$ Supply current per amplifier	$V_O = 2.5\ \text{V}$ , No load	1			$\text{mA}$

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.

**TLC2201Y operating characteristics at  $V_{DD\pm} = \pm 5\ \text{V}$ ,  $T_A = 25^\circ\text{C}$**

PARAMETER	TEST CONDITIONS	TLC2201Y			UNIT
		MIN	TYP	MAX	
SR Positive slew rate at unity gain	$V_O = \pm 0.5\ \text{to } 2.5\ \text{V}$ , $R_L = 10\ \text{k}\Omega$ , $C_L = 100\ \text{pF}$	2.5			$\text{V}/\mu\text{s}$
$V_n$ Equivalent input noise voltage	$f = 10\ \text{Hz}$	18			$\text{nV}/\sqrt{\text{Hz}}$
	$f = 1\ \text{kHz}$	8			
$V_{N(PP)}$ Peak-to-peak equivalent input noise voltage	$f = 0.1\ \text{to } 1\ \text{Hz}$	0.5			$\mu\text{V}$
	$f = 0.1\ \text{to } 10\ \text{Hz}$	0.7			
$I_n$ Equivalent input noise current		0.6			$\text{pA}/\sqrt{\text{Hz}}$
Gain-bandwidth product	$f = 10\ \text{kHz}$ , $R_L = 10\ \text{k}\Omega$ , $C_L = 100\ \text{pF}$	1.8			$\text{MHz}$
$\phi_m$ Phase margin at unity gain	$R_L = 10\ \text{k}\Omega$ , $C_L = 100\ \text{pF}$	48°			



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**TLC2202Y electrical characteristics,  $V_{DD} = 5\text{ V}$ ,  $T_A = 25^\circ\text{C}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	TLC2202Y			UNIT
		MIN	TYP	MAX	
$V_{IO}$ Input offset voltage	$V_{IC} = 0$ , $R_S = 50\ \Omega$		100		$\mu\text{V}$
Input offset voltage long-term drift (see Note 4)			0.001		$\mu\text{V}/\text{mo}$
$I_{IO}$ Input offset current			0.5		$\text{pA}$
$I_{IB}$ Input bias current			1		$\text{pA}$
$V_{OH}$ Maximum high-level output voltage	$R_L = 10\ \text{k}\Omega$		4.8		$\text{V}$
$V_{OL}$ Maximum low-level output voltage	$I_O = 0$		0		$\text{mV}$
$A_{VD}$ Large-signal differential voltage amplification	$V_O = 1\ \text{V to } 4\ \text{V}$ , $R_L = 500\ \Omega$		315		$\text{V}/\text{mV}$
	$V_O = 1\ \text{V to } 4\ \text{V}$ , $R_L = 10\ \Omega$		55		
CMRR Common-mode rejection ratio	$V_O = 0$ , $V_{ICRmin}$ , $R_S = 50\ \Omega$		110		$\text{dB}$
$k_{SVR}$ Supply-voltage rejection ratio ( $\Delta V_{DCC}/\Delta V_{IO}$ )	$V_{DD} = 4.6\ \text{ to } 16\ \text{V}$		110		$\text{dB}$
$I_{DD}$ Supply current	$V_O = 2.5\ \text{V}$ , No load		1.7		$\text{mA}$

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.

**TLC2202Y operating characteristics at  $V_{DD} = 5\ \text{V}$ ,  $T_A = 25^\circ\text{C}$**

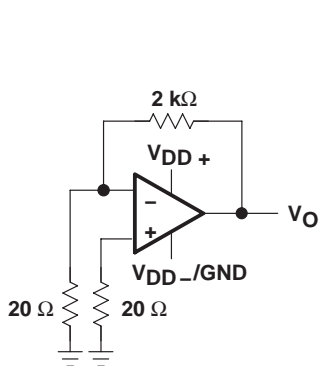
PARAMETER	TEST CONDITIONS	TLC2202Y			UNIT
		MIN	TYP	MAX	
SR Positive slew rate at unity gain	$V_O = 0.5\ \text{V to } 2.5\ \text{V}$ , $R_L = 10\ \text{k}\Omega$ , $C_L = 100\ \text{pF}$		2.5		$\text{V}/\mu\text{s}$
$V_n$ Equivalent input noise voltage	$f = 10\ \text{Hz}$		18		$\text{nV}/\sqrt{\text{Hz}}$
	$f = 10\ \text{kHz}$		8		
$V_{N(PP)}$ Peak-to-peak equivalent input noise voltage	$f = 0.1\ \text{ to } 1\ \text{Hz}$		0.5		$\mu\text{V}$
	$f = 0.1\ \text{ to } 10\ \text{Hz}$		0.7		
$I_n$ Equivalent input noise current			0.6		$\text{pA}/\sqrt{\text{Hz}}$
$B_1$ Gain-bandwidth product	$f = 10\ \text{kHz}$ , $R_L = 10\ \text{k}\Omega$ , $C_L = 100\ \text{pF}$		1.9		$\text{MHz}$
$\phi_m$ Phase margin at unity gain	$R_L = 10\ \text{k}\Omega$ , $C_L = 100\ \text{pF}$		$47^\circ$		



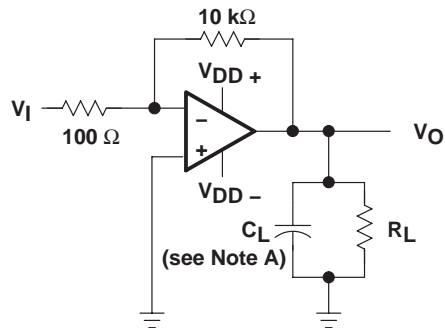
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**PARAMETER MEASUREMENT INFORMATION**

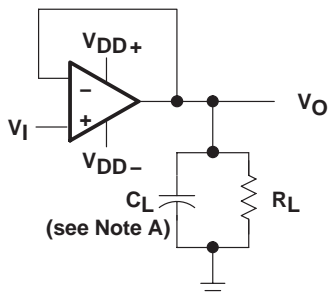


**Figure 1. Noise-Voltage Test Circuit**



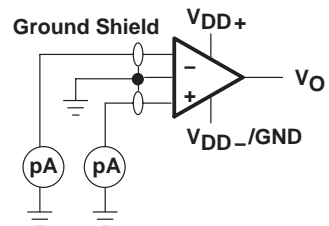
NOTE A:  $C_L$  includes fixture capacitance.

**Figure 2. Phase-Margin Test Circuit**



NOTE A:  $C_L$  includes fixture capacitance.

**Figure 3. Slew-Rate Test Circuit**



**Figure 4. Input-Bias and Offset-Current Test Circuit**

**typical values**

Typical values presented in this data sheet represent the median (50% point) of device parametric performance.

**input bias and offset current**

At the picoamp bias current level of the TLC220x, TLC220xA, and TLC220xB, accurate measurement of the bias current becomes difficult. Not only does this measurement require a picoammeter, but test socket leakages can easily exceed the actual device bias currents. To measure these small currents, Texas Instruments uses a two-step process. The socket leakage is measured using picoammeters with bias voltages applied but with no device in the socket. The device is then inserted in the socket, and a second test measuring both the socket leakage and the device input bias current is performed. The two measurements are then subtracted algebraically to determine the bias current of the device.

**noise**

Texas Instruments offers automated production noise testing to meet individual application requirements. Noise voltage at  $f = 10 \text{ Hz}$  and  $f = 1 \text{ kHz}$  is 100% tested on every TLC2201B device, while lot sample testing is performed on the TLC220xA. For other noise requirements, please contact the factory.



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**TYPICAL CHARACTERISTICS**

**Table of Graphs**

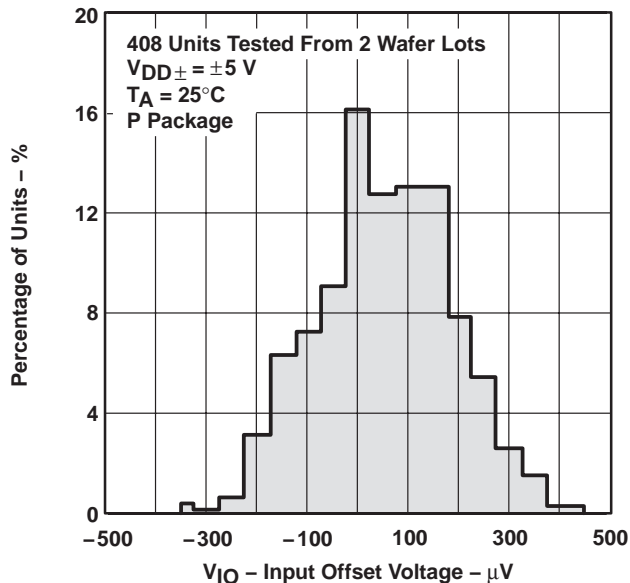
		<b>FIGURE</b>	
$V_{IO}$	Input offset voltage	Distribution	5, 6
$I_{IB}$	Input bias current	vs Common-mode input voltage	7
		vs Free-air temperature	8
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		vs Free-air temperature	10
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$V_{OH}$	High-level output voltage	vs Frequency	12
		vs High-level output current	13
		vs Free-air temperature	14
$V_{OL}$	Low-level output voltage	vs Low-level output current	15
		vs Free-air temperature	16
$A_{VD}$	Large-signal differential voltage amplification	vs Frequency	17
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		vs Free-air temperature	38, 39
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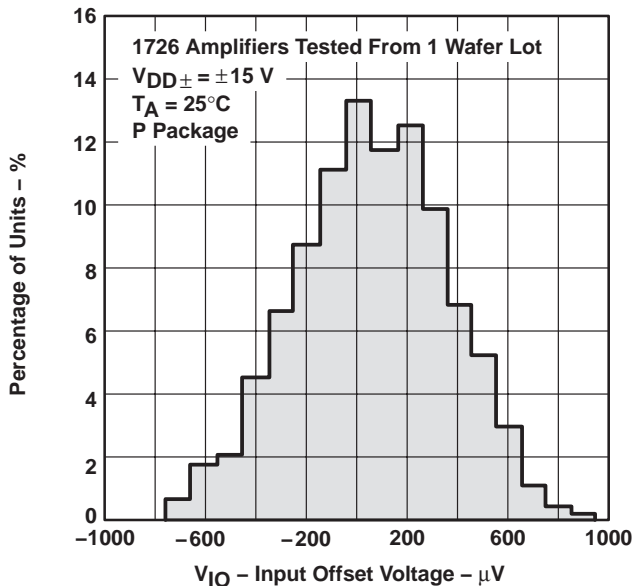
**TYPICAL CHARACTERISTICS**

**DISTRIBUTION OF TLC2201  
 INPUT OFFSET VOLTAGE**



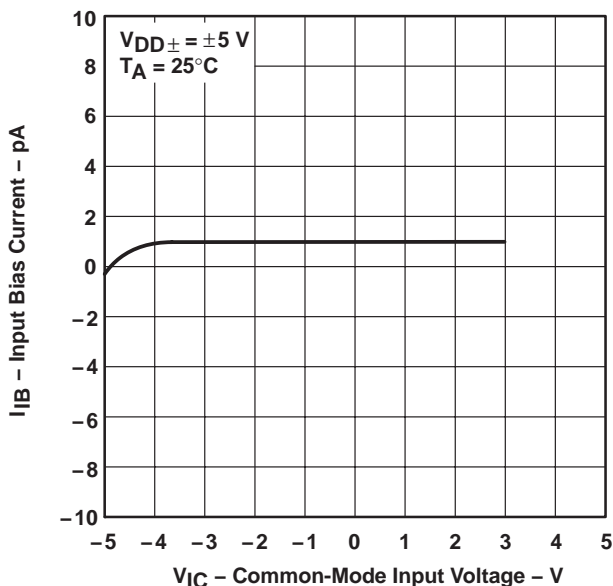
**Figure 5**

**TLC2202  
 DISTRIBUTION OF  
 INPUT OFFSET VOLTAGE**



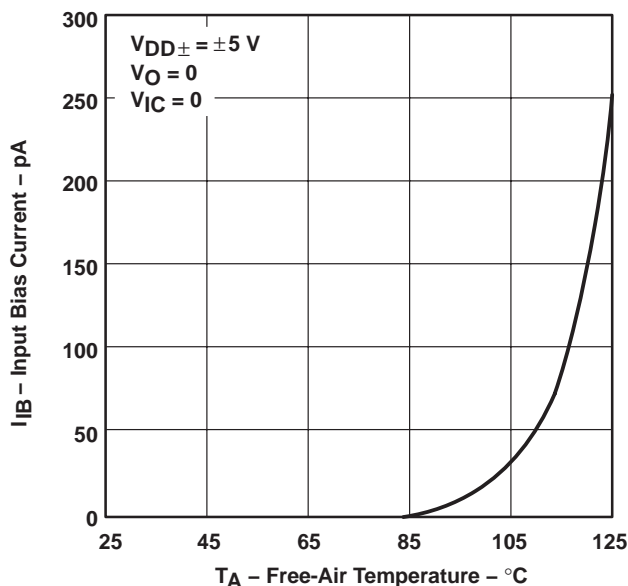
**Figure 6**

**INPUT BIAS CURRENT  
 VS  
 COMMON-MODE INPUT VOLTAGE**



**Figure 7**

**INPUT BIAS CURRENT†  
 VS  
 FREE-AIR TEMPERATURE**



**Figure 8**

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

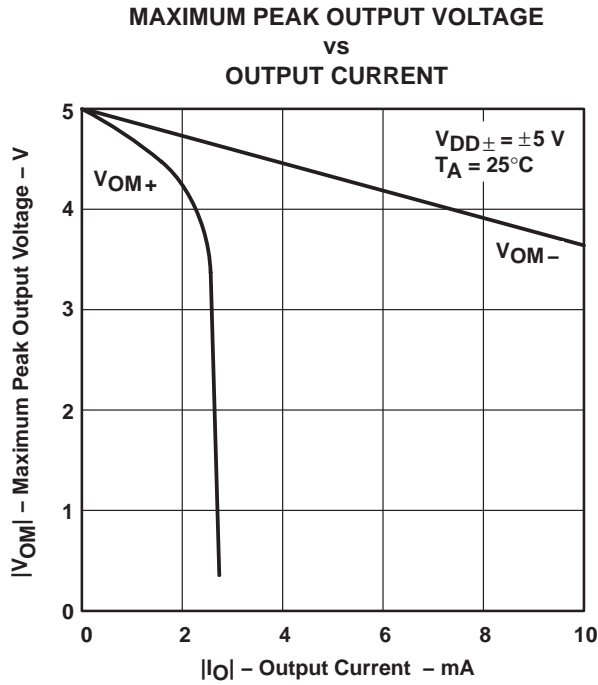


Figure 9

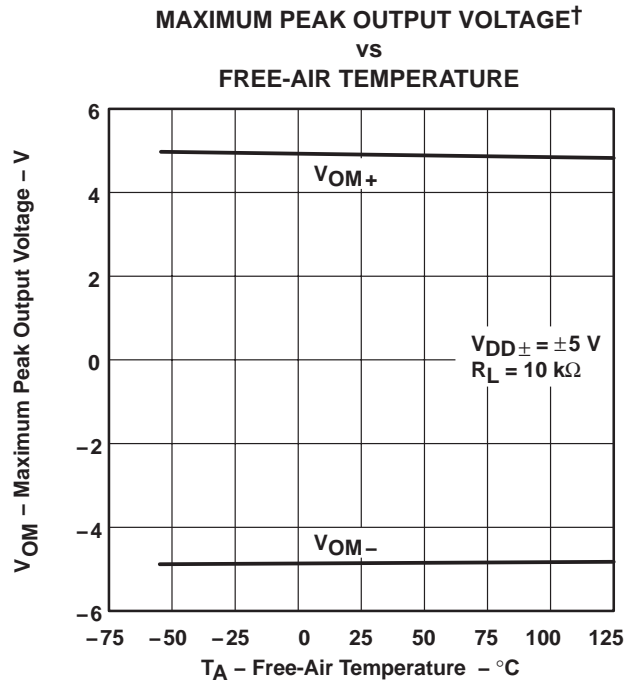


Figure 10

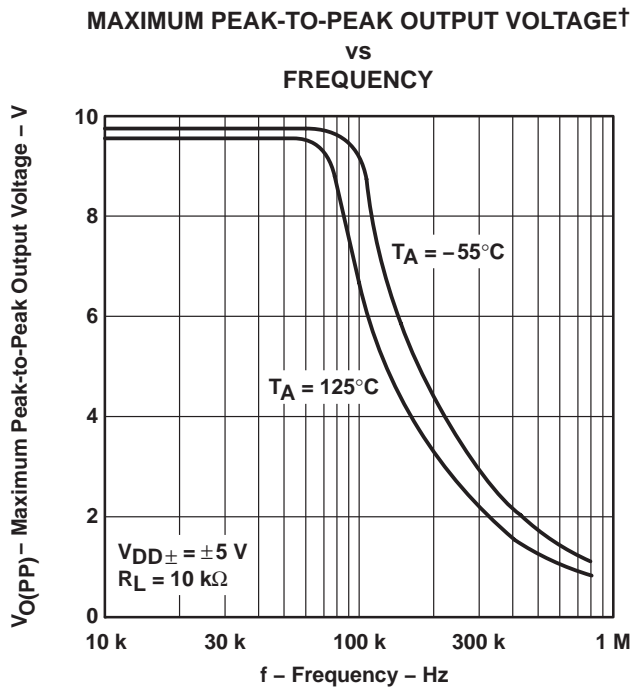


Figure 11

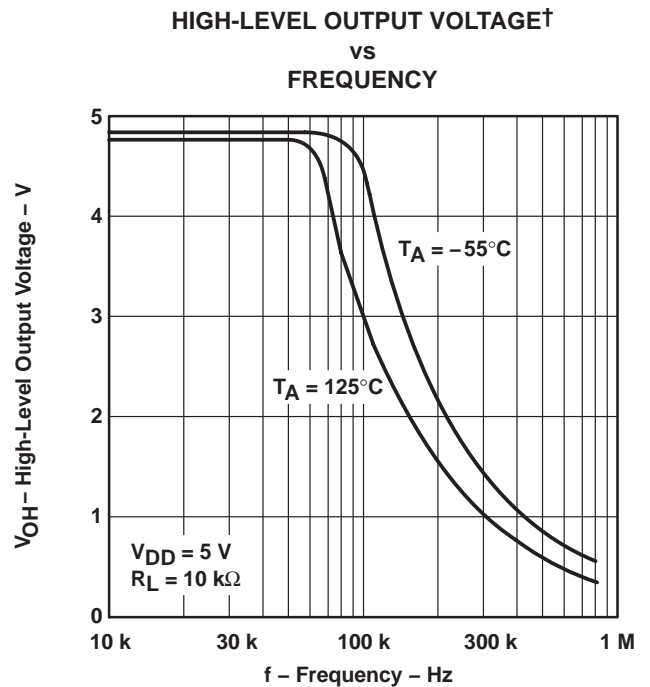


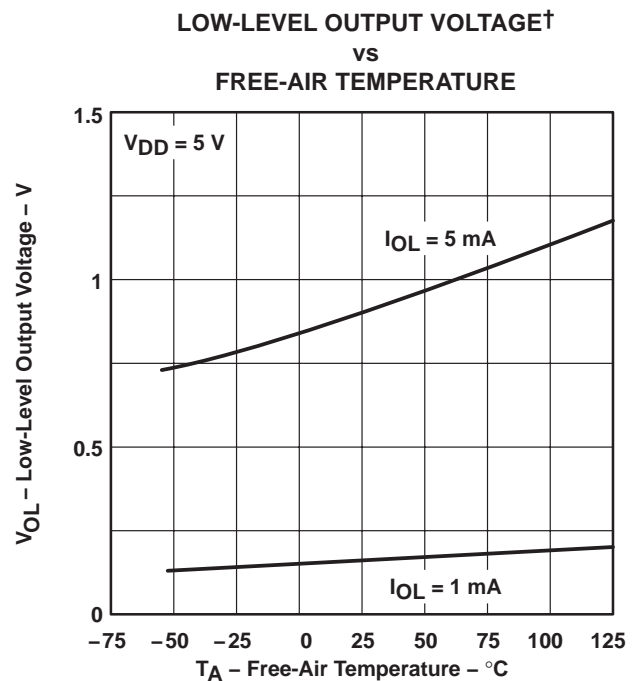
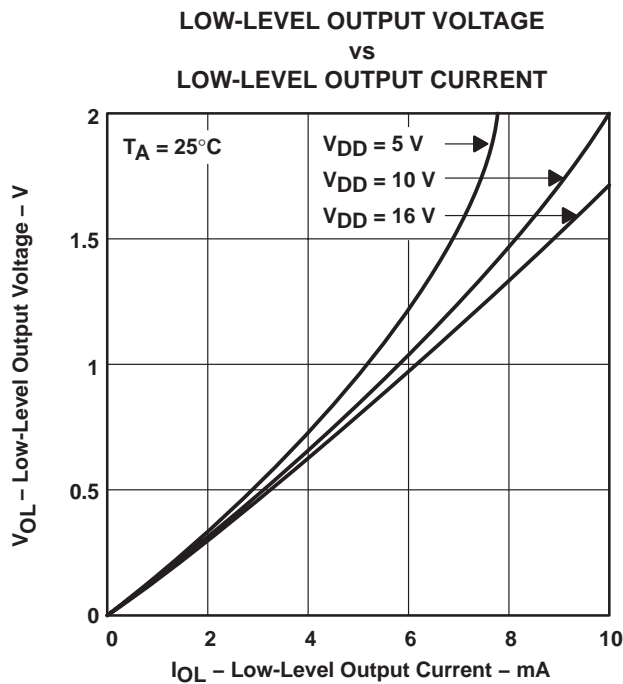
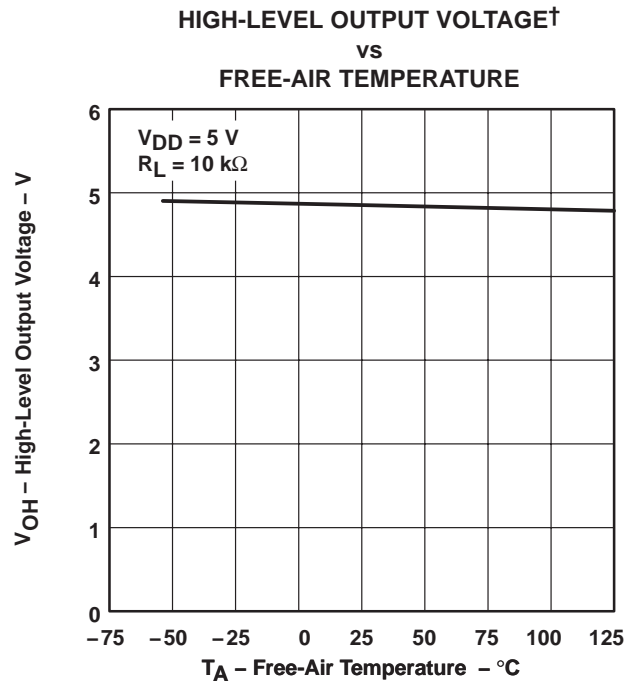
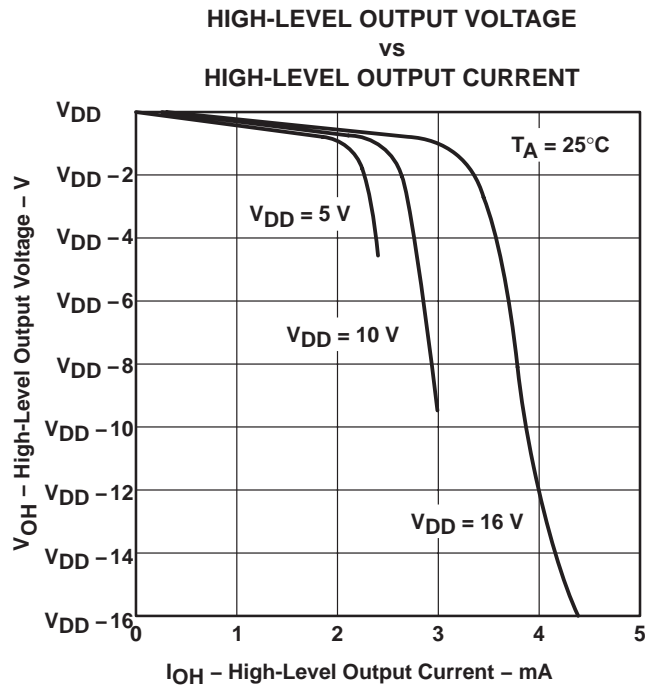
Figure 12

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

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† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE SHIFT

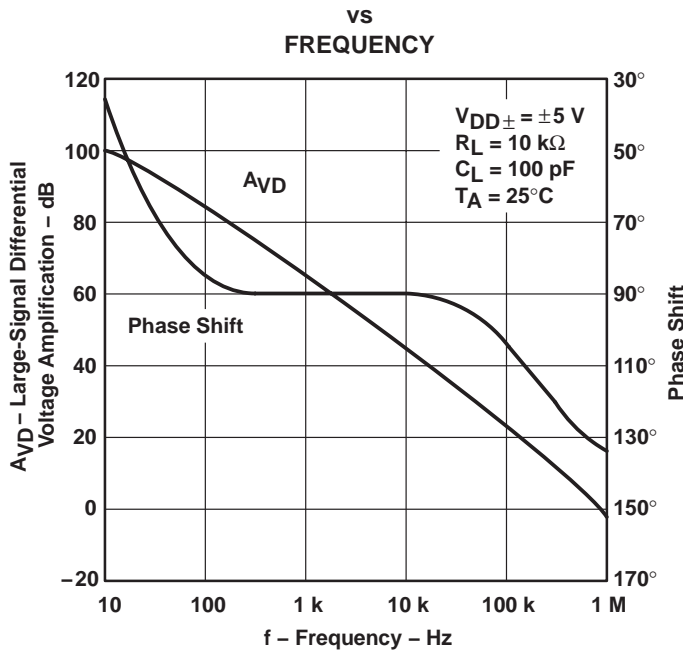


Figure 17

LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION†

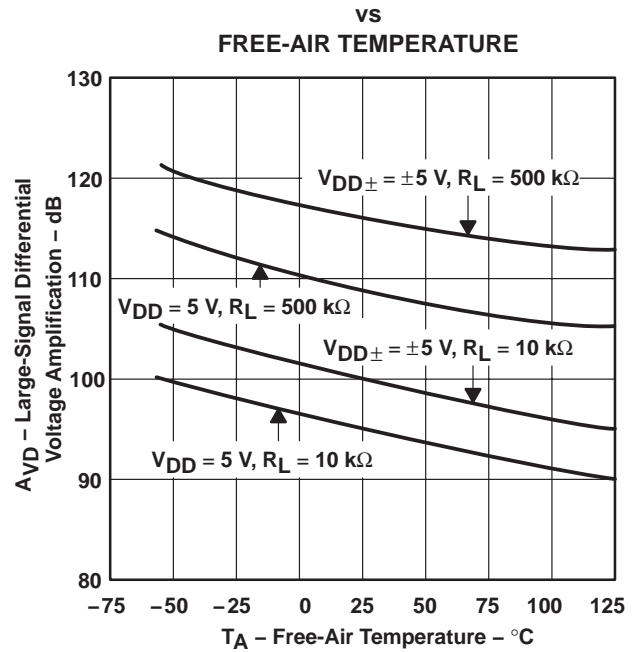


Figure 18

SHORT-CIRCUIT OUTPUT CURRENT vs SUPPLY VOLTAGE

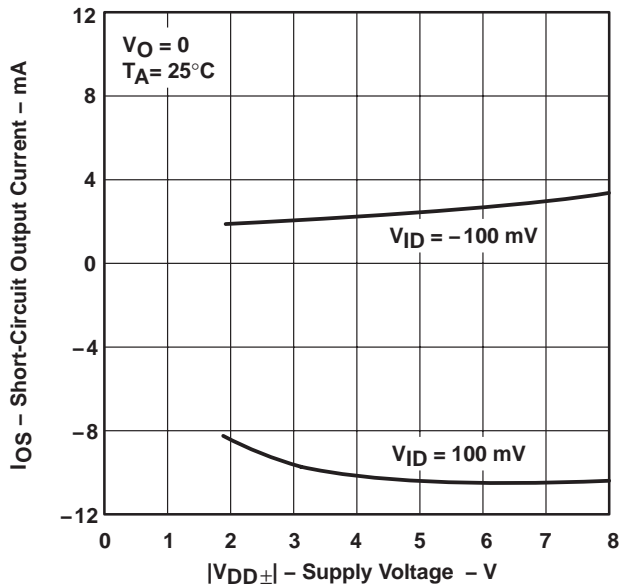


Figure 19

SHORT-CIRCUIT OUTPUT CURRENT† vs FREE-AIR TEMPERATURE

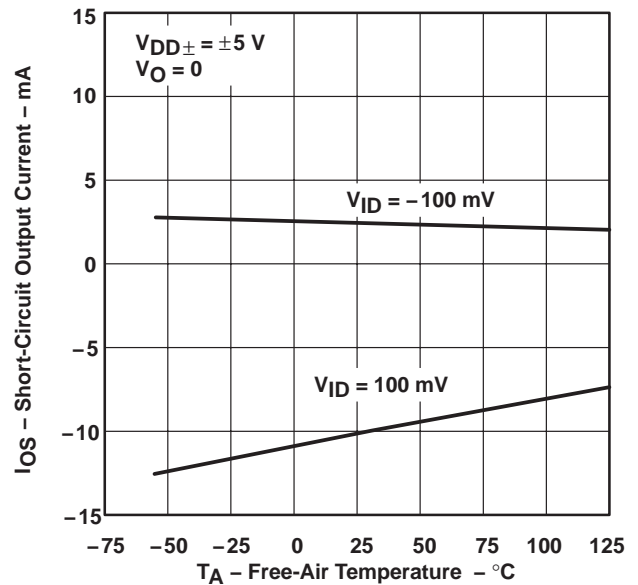


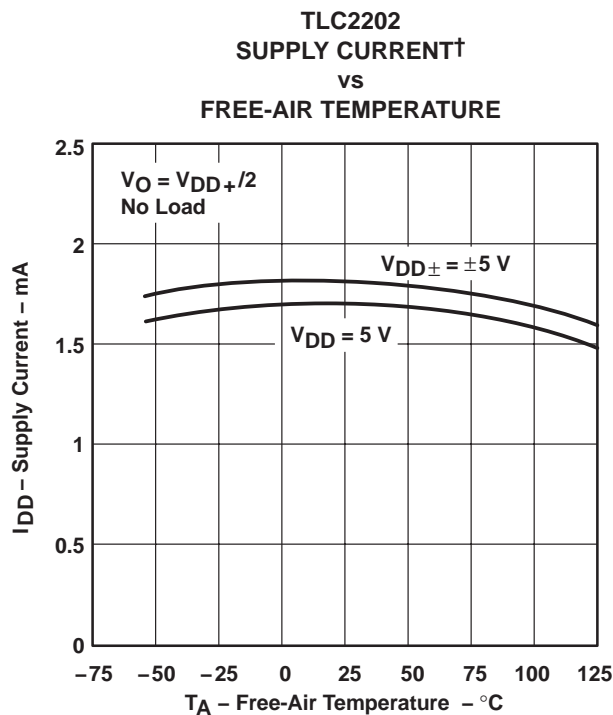
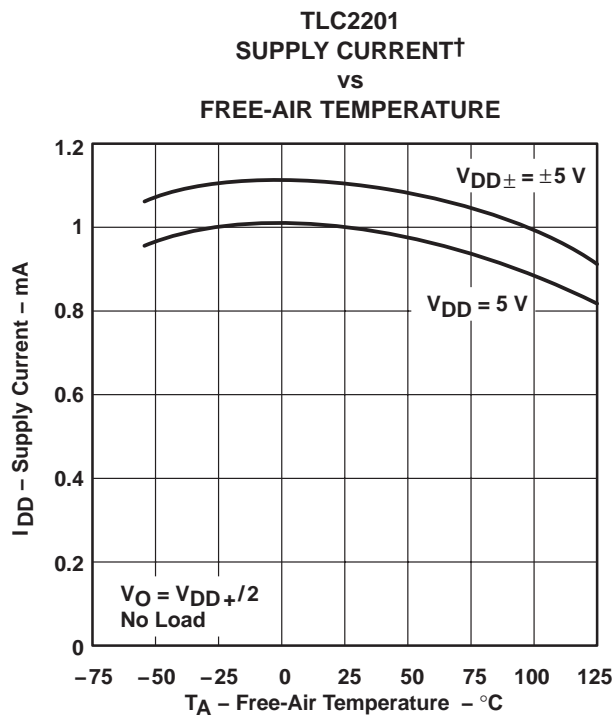
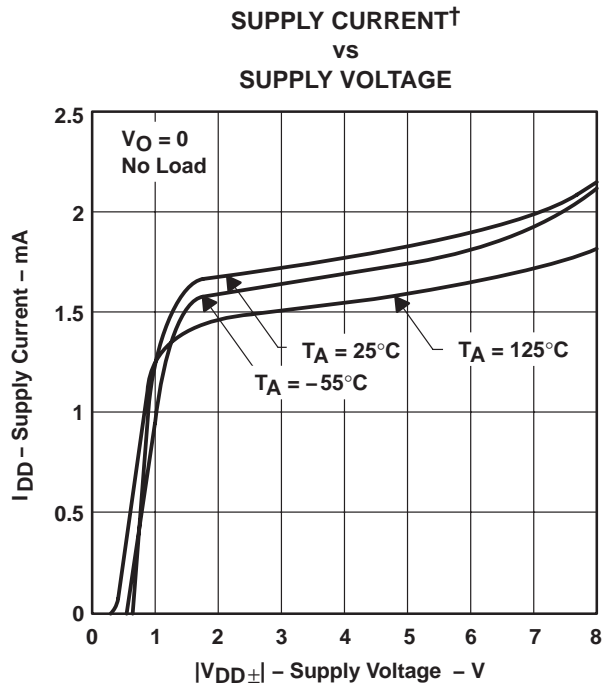
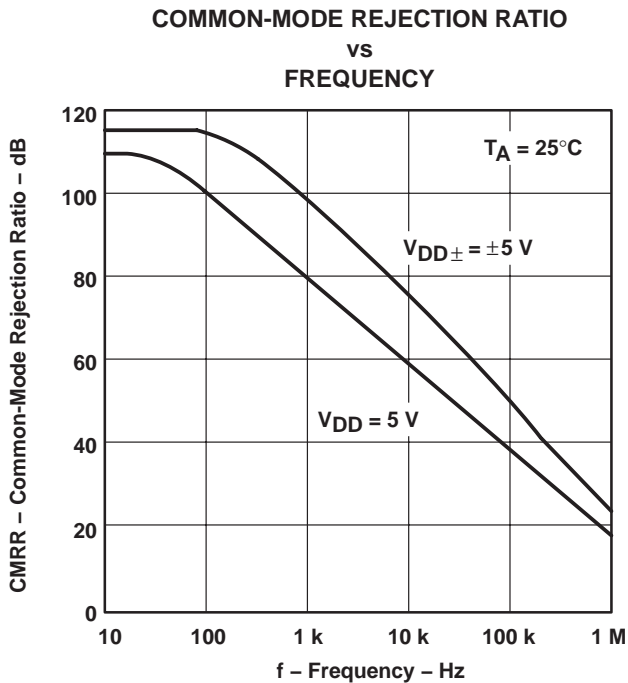
Figure 20

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

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† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.



TYPICAL CHARACTERISTICS

VOLTAGE-FOLLOWER  
 SMALL-SIGNAL  
 PULSE RESPONSE

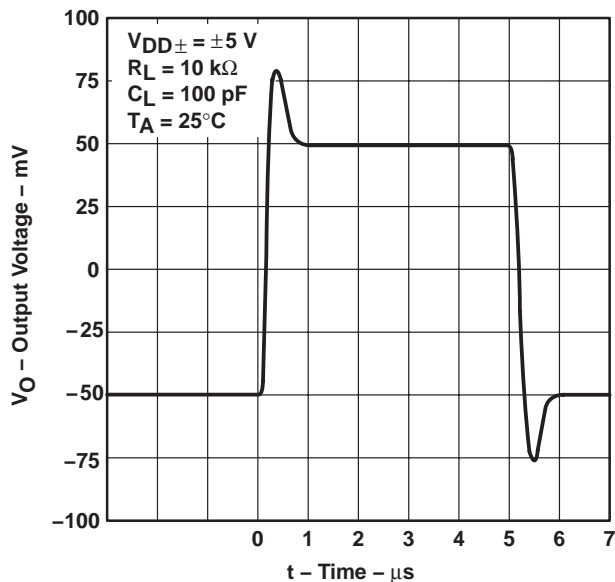


Figure 25

VOLTAGE-FOLLOWER  
 SMALL-SIGNAL  
 PULSE RESPONSE

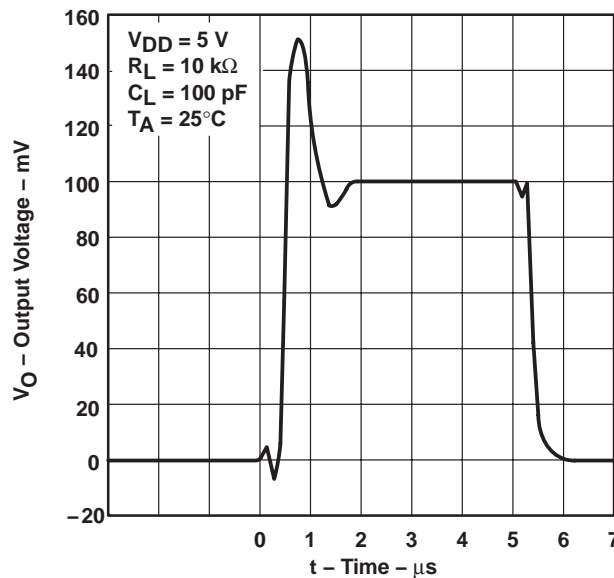


Figure 26

VOLTAGE-FOLLOWER  
 LARGE-SIGNAL  
 PULSE RESPONSE

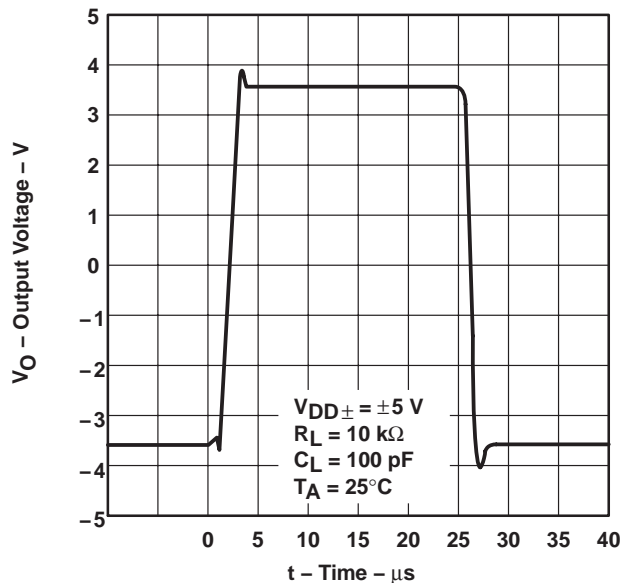


Figure 27

VOLTAGE-FOLLOWER  
 LARGE-SIGNAL  
 PULSE RESPONSE

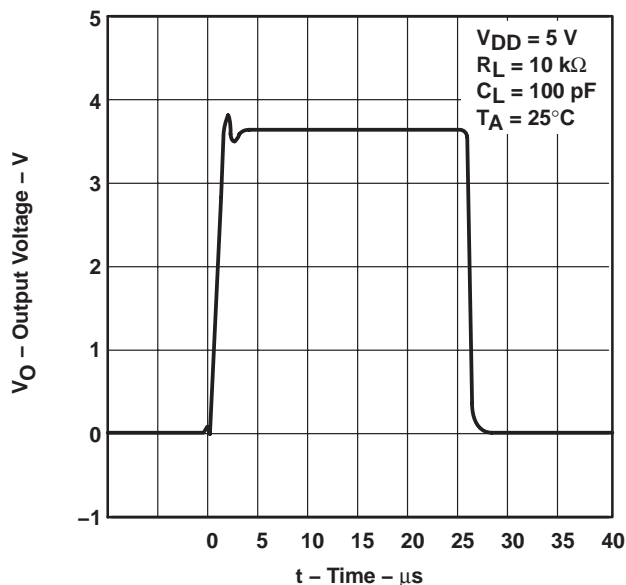
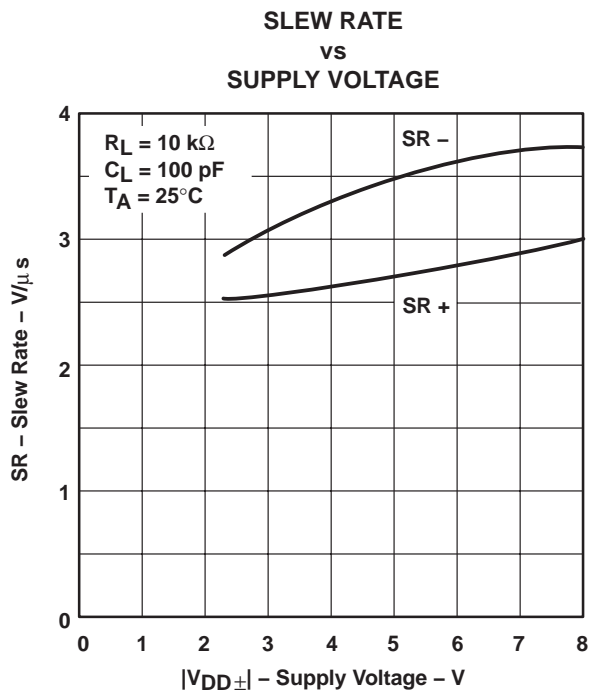


Figure 28

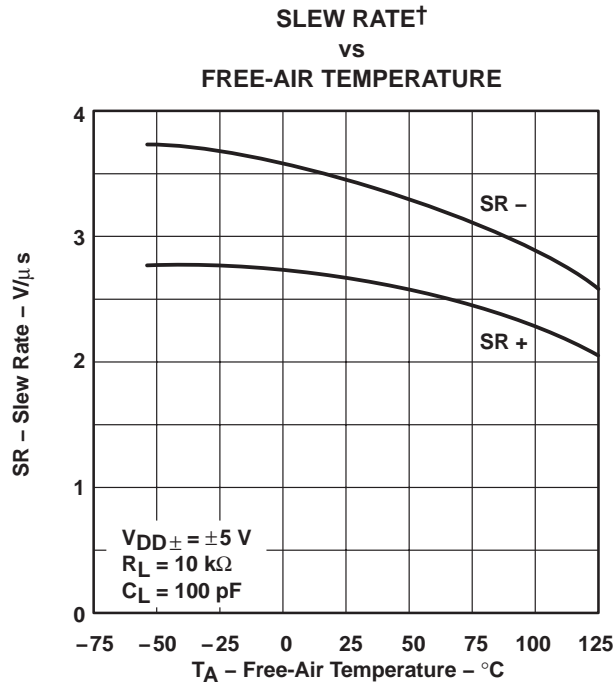
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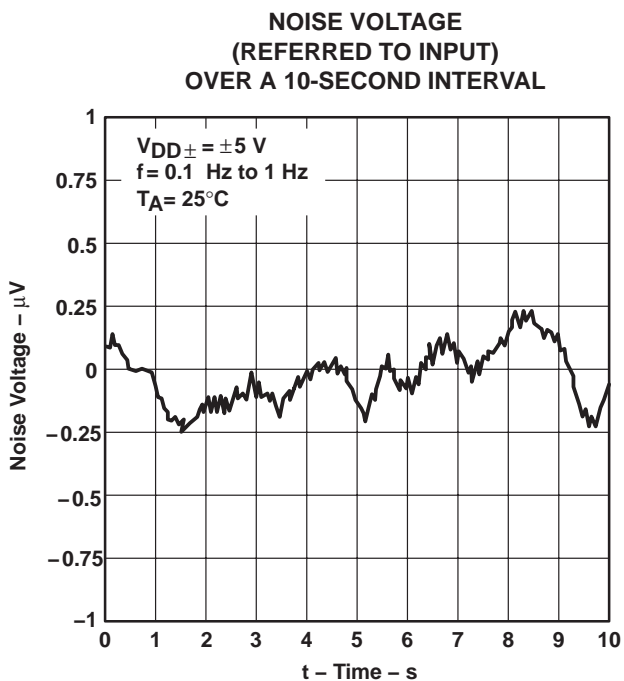
**TYPICAL CHARACTERISTICS**



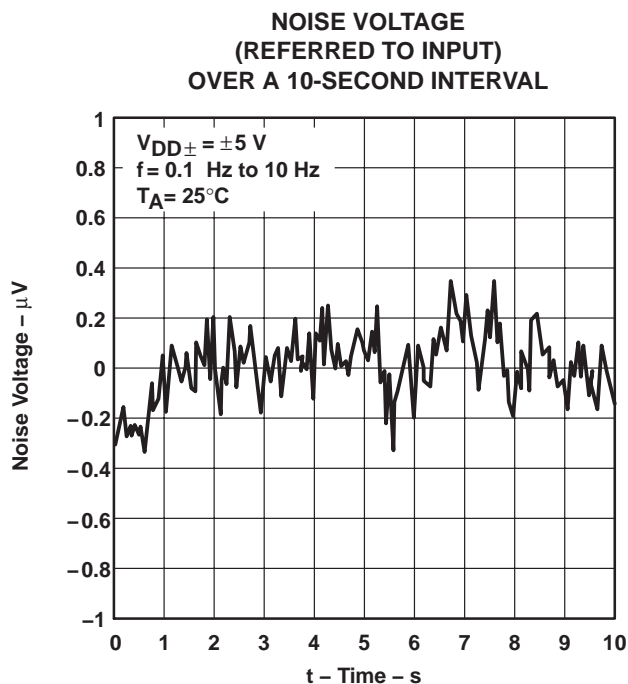
**Figure 29**



**Figure 30**



**Figure 31**



**Figure 32**

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

TLC2201  
 GAIN-BANDWIDTH PRODUCT  
 vs  
 SUPPLY VOLTAGE

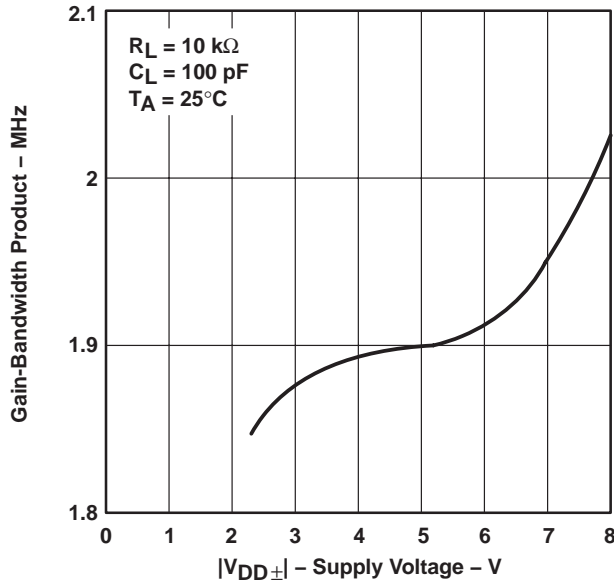


Figure 33

TLC2202  
 GAIN-BANDWIDTH PRODUCT  
 vs  
 SUPPLY VOLTAGE

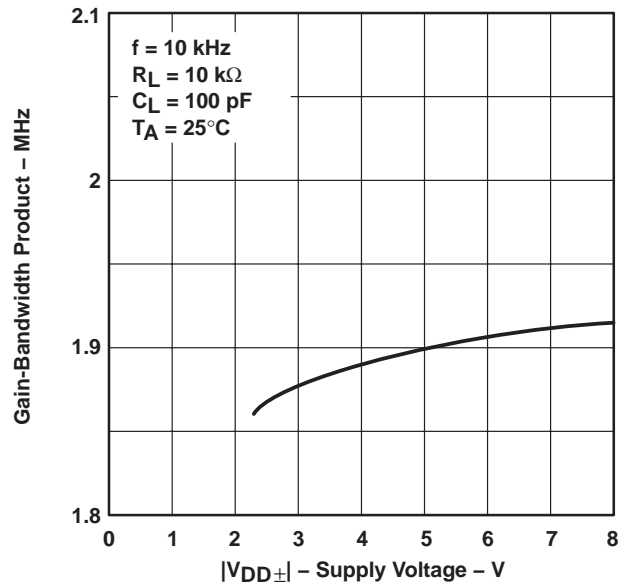


Figure 34

GAIN-BANDWIDTH PRODUCT†  
 vs  
 FREE-AIR TEMPERATURE

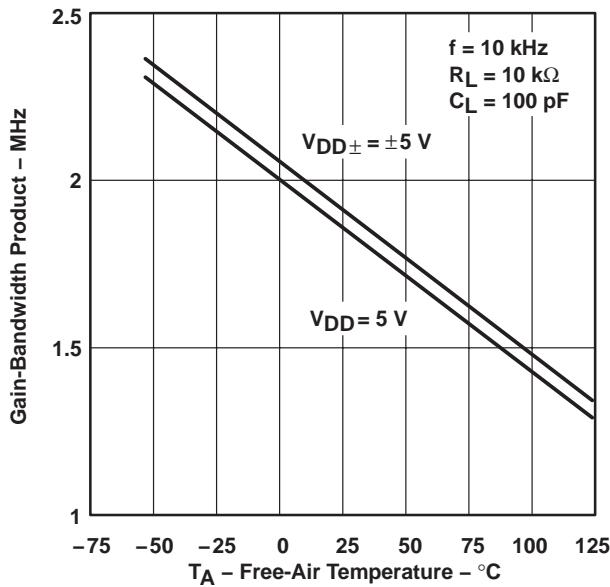


Figure 35

TLC2201  
 PHASE MARGIN  
 vs  
 SUPPLY VOLTAGE

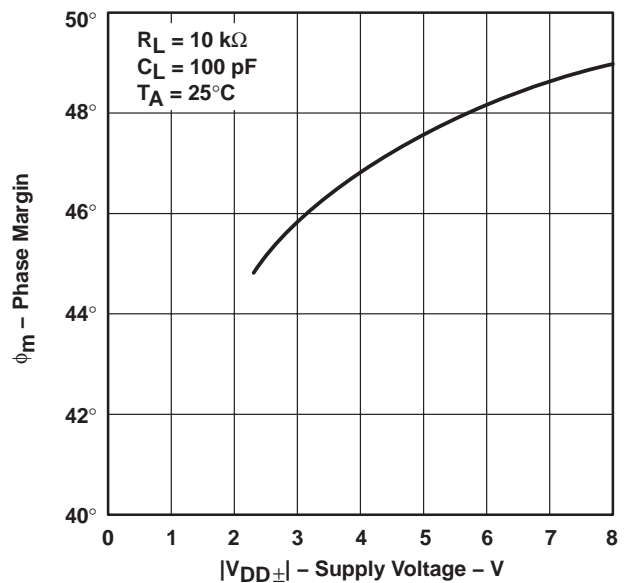


Figure 36

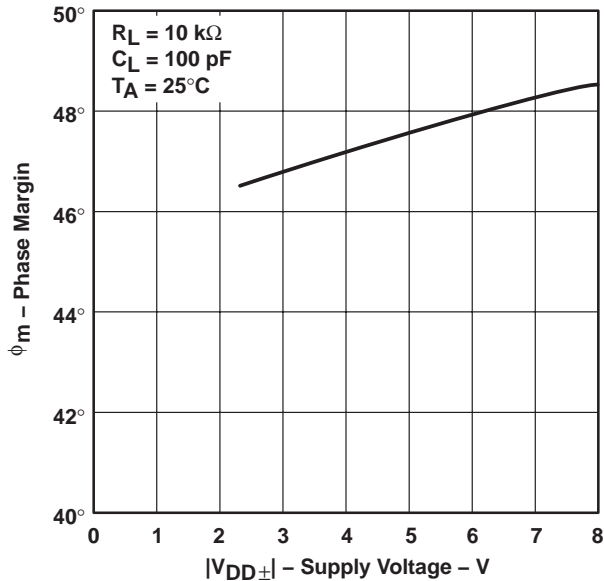
† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

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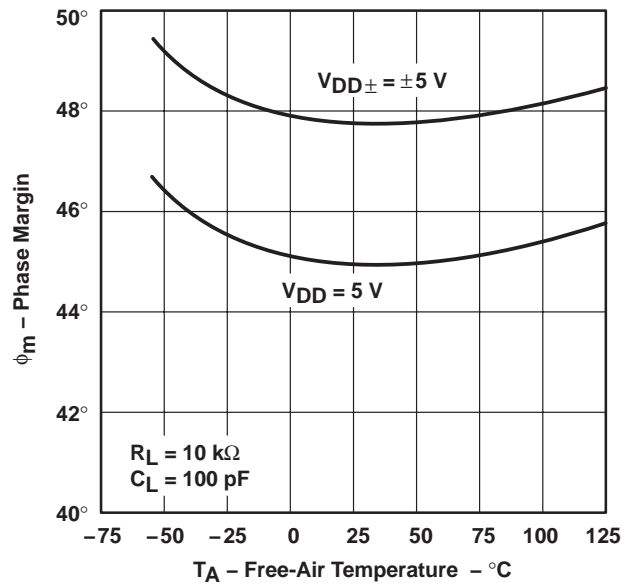
**TYPICAL CHARACTERISTICS**

**TLC2202**  
**PHASE MARGIN**  
**vs**  
**SUPPLY VOLTAGE**



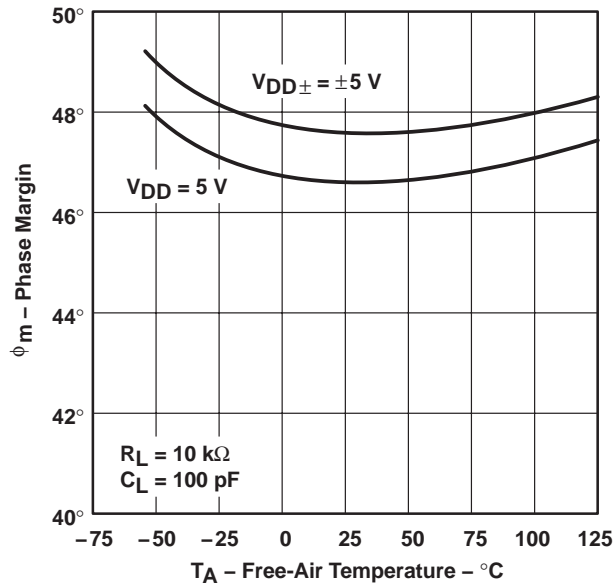
**Figure 37**

**TLC2201**  
**PHASE MARGIN†**  
**vs**  
**FREE-AIR TEMPERATURE**



**Figure 38**

**TLC2202**  
**PHASE MARGIN†**  
**vs**  
**FREE-AIR TEMPERATURE**



**Figure 39**

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

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## APPLICATION INFORMATION

### latch-up avoidance

Because CMOS devices are susceptible to latch-up due to their inherent parasitic thyristors, the TLC220x, TLC220xA, and TLC220xB inputs and outputs are designed to withstand –100-mA surge currents without sustaining latch-up; however, techniques reducing the chance of latch-up should be used whenever possible. Internal protection diodes should not be forward biased in normal operation. Applied input and output voltages should not exceed the supply voltage by more than 300 mV. Care should be exercised when using capacitive coupling on pulse generators. Supply transients should be shunted by the use of decoupling capacitors (0.1  $\mu$ F typical) located across the supply rails as close to the device as possible.

### electrostatic discharge protection

These devices use internal ESD-protection circuits that prevent functional failures at voltages at or below 2000 V. Care should be exercised in handling these devices as exposure to ESD may result in degradation of the device parametric performance.

### macromodel information

Macromodel information provided was derived using Microsim *Parts*™, the model generation software used with Microsim *PSpice*™. The Boyle macromodel (see Note 5) and subcircuit in Figure 40 were generated using the TLC220x typical electrical and operating characteristics at 25°C. Using this information, output simulations of the following key parameters can be generated to a tolerance of 20% (in most cases):

- Maximum positive output voltage swing
- Maximum negative output voltage swing
- Slew rate
- Quiescent power dissipation
- Input bias current
- Open-loop voltage amplification
- Unity-gain frequency
- Common-mode rejection ratio
- Phase margin
- DC output resistance
- AC output resistance
- Short-circuit output current limit

NOTE 5: G. R. Boyle, B. M. Cohn, D. O. Pederson, and J. E. Solomon, "Macromodeling of Integrated Circuit Operational Amplifiers", *IEEE Journal of Solid-State Circuits*, SC-9, 353 (1974).

*PSpice* and *Parts* are trademarks of MicroSim Corporation.

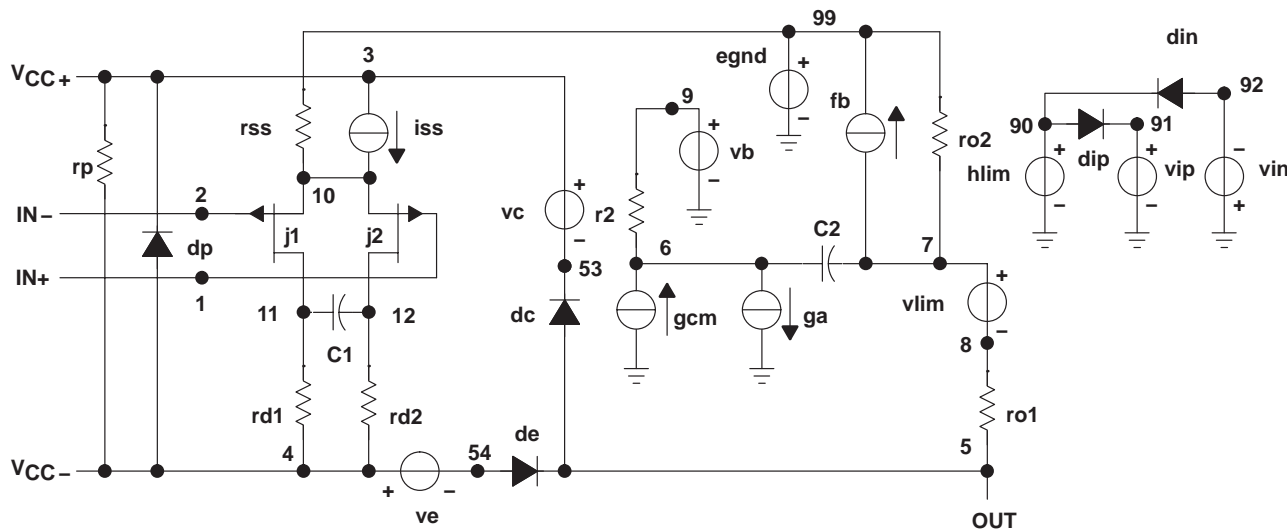


**TLC220x, TLC220xA, TLC220xB, TLC220xY**  
**Advanced LinCMOS™ LOW-NOISE PRECISION**  
**OPERATIONAL AMPLIFIERS**

SLOS175B – FEBRUARY 1997 – REVISED JANUARY 2008

**APPLICATION INFORMATION**

**macromodel information (continued)**



```
.subckt TLC220x 1 2 3 4 5
*
c1 11 12 8.51E-12
c2 6 7 50.00E-12
cpsr 85 86 79.6E-9
dcm+ 81 82 dx
dcm- 83 81 dx
dc 5 53 dx
de 54 5 dx
dlp 90 91 dx
dln 92 90 dx
dp 4 3 dx
ecmr 84 99 (2,99) 1
egnd 99 0 poly(2) (3,0) (4,0) 0 .5 .5
epsr 85 0 poly(1) (3,4) -200E-6 20E-6
ense 89 2 poly(1) (88,0) 100E-6 1
fb 7 99 poly(6) vb vc ve vlp vln
+ vpsr 0 + 895.9E3 -90E3 90E3 90E3 -90E3 895E3
ga 6 0 11 12 314.2E-6
gcm 0 6 10 99 1.295E-9
gpsr 85 86 (85,86) 100E-6
grd1 60 11 (60,11) 3.141E-4
grd2 60 12 (60,12) 3.141E-4
hlim 90 0 vlim 1k
hcmr 80 1 poly(2) vcm+ vcm- 0 1E2 1E2
irp 3 4 965E-6
iss 3 10 dc 135.0E-6
iio 2 0 .5E-12
i1 88 0 1E-21
j1 11 89 10 jx
j2 12 80 10 jx
r2 6 9 100.0E3
rcm 84 81 1k
rn1 88 0 1500
ro1 8 5 188
ro2 7 99 187
rss 10 99 1.481E6
vad 60 4 -.3v
vcm+ 82 99 2.2
vcm- 83 99 -4.5
vb 9 0 dc 0
vc 3 53 dc .9
ve 54 4 dc .8
vlim 7 8 dc 0
vlp 91 0 dc 2.8
vln 0 92 dc 2.8
vpsr 0 86 dc 0
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.model jx pjf(is=500.0E-15 beta=1.462E-3
+ vto=-.155 kf=1E-17)
.endsx
```

**Figure 40. Boyle Macromodel and Subcircuit**

**PACKAGING INFORMATION**

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
<a href="#">5962-9088201M2A</a>	Active	Production	LCCC (FK)   20	55   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 9088201M2A TLC2201MFKB
<a href="#">5962-9088201MPA</a>	Active	Production	CDIP (JG)   8	50   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9088201MPA TLC2201M
<a href="#">5962-9088202M2A</a>	Active	Production	LCCC (FK)   20	55   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 9088202M2A TLC2202MFKB
<a href="#">5962-9088202MPA</a>	Active	Production	CDIP (JG)   8	50   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9088202MPA TLC2202M
<a href="#">5962-9088203QPA</a>	Active	Production	CDIP (JG)   8	50   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9088203QPA TLC2201AM
<a href="#">5962-9088204Q2A</a>	Active	Production	LCCC (FK)   20	55   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 9088204Q2A TLC2202 AMFKB
<a href="#">5962-9088204QPA</a>	Active	Production	CDIP (JG)   8	50   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9088204QPA TLC2202AM
<a href="#">TLC2201ACD</a>	Active	Production	SOIC (D)   8	75   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2201AC
<a href="#">TLC2201ACD.A</a>	Active	Production	SOIC (D)   8	75   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2201AC
<a href="#">TLC2201ACDR</a>	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2201AC
<a href="#">TLC2201ACDR.A</a>	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2201AC
<a href="#">TLC2201AID</a>	Active	Production	SOIC (D)   8	75   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-	2201AI
<a href="#">TLC2201AID.A</a>	Active	Production	SOIC (D)   8	75   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2201AI
<a href="#">TLC2201AIDR</a>	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-	2201AI
<a href="#">TLC2201AIDR.A</a>	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2201AI
<a href="#">TLC2201AMD</a>	Active	Production	SOIC (D)   8	75   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	2201AM
<a href="#">TLC2201AMD.A</a>	Active	Production	SOIC (D)   8	75   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	2201AM
<a href="#">TLC2201AMDG4</a>	Active	Production	SOIC (D)   8	75   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-	2201AM
<a href="#">TLC2201AMDG4.A</a>	Active	Production	SOIC (D)   8	75   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	2201AM
<a href="#">TLC2201AMJG</a>	Active	Production	CDIP (JG)   8	50   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	TLC2201 AMJG

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLC2201AMJG.A	Active	Production	CDIP (JG)   8	50   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	TLC2201 AMJG
<a href="#">TLC2201AMJGB</a>	Active	Production	CDIP (JG)   8	50   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9088203QPA TLC2201AM
TLC2201AMJGB.A	Active	Production	CDIP (JG)   8	50   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9088203QPA TLC2201AM
<a href="#">TLC2201CD</a>	Active	Production	SOIC (D)   8	75   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2201C
TLC2201CD.A	Active	Production	SOIC (D)   8	75   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2201C
<a href="#">TLC2201CDR</a>	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2201C
TLC2201CDR.A	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2201C
<a href="#">TLC2201CP</a>	Active	Production	PDIP (P)   8	50   TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLC2201CP
TLC2201CP.A	Active	Production	PDIP (P)   8	50   TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLC2201CP
<a href="#">TLC2201ID</a>	Active	Production	SOIC (D)   8	75   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-	2201I
TLC2201ID.A	Active	Production	SOIC (D)   8	75   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2201I
<a href="#">TLC2201IDR</a>	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-	2201I
TLC2201IDR.A	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2201I
<a href="#">TLC2201IP</a>	Active	Production	PDIP (P)   8	50   TUBE	Yes	NIPDAU	N/A for Pkg Type	-	TLC2201IP
TLC2201IP.A	Active	Production	PDIP (P)   8	50   TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLC2201IP
<a href="#">TLC2201MFKB</a>	Active	Production	LCCC (FK)   20	55   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 9088201M2A TLC2201MFKB
TLC2201MFKB.A	Active	Production	LCCC (FK)   20	55   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 9088201M2A TLC2201MFKB
<a href="#">TLC2201MJGB</a>	Active	Production	CDIP (JG)   8	50   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9088201MPA TLC2201M
TLC2201MJGB.A	Active	Production	CDIP (JG)   8	50   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9088201MPA TLC2201M
<a href="#">TLC2202ACD</a>	Active	Production	SOIC (D)   14	50   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2202AC
TLC2202ACD.A	Active	Production	SOIC (D)   14	50   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2202AC
<a href="#">TLC2202ACDR</a>	Active	Production	SOIC (D)   14	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-	2202AC
TLC2202ACDR.A	Active	Production	SOIC (D)   14	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	2202AC
<a href="#">TLC2202AID</a>	Active	Production	SOIC (D)   14	50   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	2202AI

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLC2202AID.A	Active	Production	SOIC (D)   14	50   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	2202AI
<a href="#">TLC2202AMFKB</a>	Active	Production	LCCC (FK)   20	55   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 9088204Q2A TLC2202 AMFKB
TLC2202AMFKB.A	Active	Production	LCCC (FK)   20	55   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 9088204Q2A TLC2202 AMFKB
<a href="#">TLC2202AMJG</a>	Active	Production	CDIP (JG)   8	50   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	TLC2202 AMJG
TLC2202AMJG.A	Active	Production	CDIP (JG)   8	50   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	TLC2202 AMJG
<a href="#">TLC2202AMJGB</a>	Active	Production	CDIP (JG)   8	50   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9088204QPA TLC2202AM
TLC2202AMJGB.A	Active	Production	CDIP (JG)   8	50   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9088204QPA TLC2202AM
<a href="#">TLC2202CD</a>	Active	Production	SOIC (D)   14	50   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2202C
TLC2202CD.A	Active	Production	SOIC (D)   14	50   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2202C
<a href="#">TLC2202CDR</a>	Active	Production	SOIC (D)   14	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2202C
TLC2202CDR.A	Active	Production	SOIC (D)   14	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2202C
<a href="#">TLC2202CP</a>	Active	Production	PDIP (P)   8	50   TUBE	Yes	NIPDAU	N/A for Pkg Type	-	TLC2202CP
TLC2202CP.A	Active	Production	PDIP (P)   8	50   TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLC2202CP
<a href="#">TLC2202CPS</a>	Active	Production	SO (PS)   8	80   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-	P2202
TLC2202CPS.A	Active	Production	SO (PS)   8	80   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	P2202
<a href="#">TLC2202CPSR</a>	Active	Production	SO (PS)   8	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-	P2202
TLC2202CPSR.A	Active	Production	SO (PS)   8	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	P2202
<a href="#">TLC2202ID</a>	Active	Production	SOIC (D)   14	50   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-	TLC2202I
TLC2202ID.A	Active	Production	SOIC (D)   14	50   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLC2202I
<a href="#">TLC2202IP</a>	Active	Production	PDIP (P)   8	50   TUBE	Yes	NIPDAU	N/A for Pkg Type	-	TLC2202IP
TLC2202IP.A	Active	Production	PDIP (P)   8	50   TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLC2202IP
<a href="#">TLC2202MFKB</a>	Active	Production	LCCC (FK)   20	55   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 9088202M2A TLC2202MFKB

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLC2202MFKB.A	Active	Production	LCCC (FK)   20	55   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 9088202M2A TLC2202MFKB
<a href="#">TLC2202MJG</a>	Active	Production	CDIP (JG)   8	50   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	TLC2202MJG
TLC2202MJG.A	Active	Production	CDIP (JG)   8	50   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	TLC2202MJG
<a href="#">TLC2202MJGB</a>	Active	Production	CDIP (JG)   8	50   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9088202MPA TLC2202M
TLC2202MJGB.A	Active	Production	CDIP (JG)   8	50   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9088202MPA TLC2202M

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "-" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

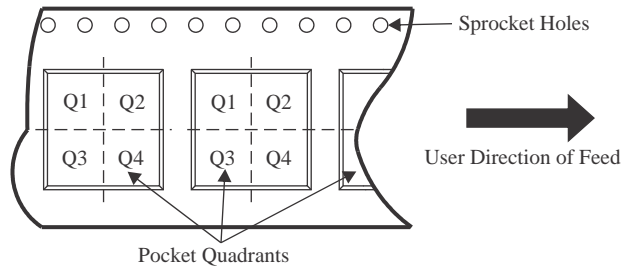
**OTHER QUALIFIED VERSIONS OF TLC2201, TLC2201A, TLC2201AM, TLC2201M, TLC2202, TLC2202A, TLC2202AM, TLC2202M :**

- Catalog : [TLC2201A](#), [TLC2201](#), [TLC2202A](#), [TLC2202](#)
- Military : [TLC2201M](#), [TLC2201AM](#), [TLC2202M](#), [TLC2202AM](#)
- Space : [TLC2201-SP](#), [TLC2201-SP](#)

## NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
- Military - QML certified for Military and Defense Applications
- Space - Radiation tolerant, ceramic packaging and qualified for use in Space-based application

**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


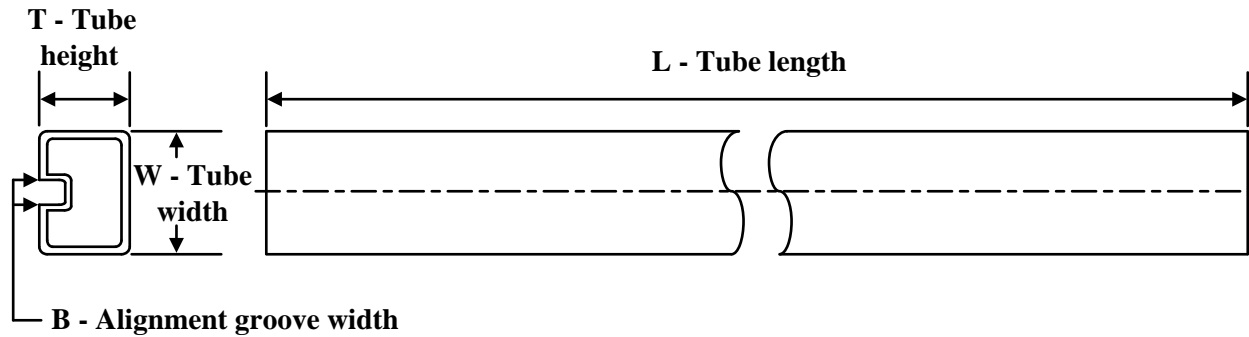
\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLC2201ACDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLC2201AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLC2201CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLC2201IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLC2202ACDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TLC2202CDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TLC2202CPSR	SO	PS	8	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLC2201ACDR	SOIC	D	8	2500	353.0	353.0	32.0
TLC2201AIDR	SOIC	D	8	2500	353.0	353.0	32.0
TLC2201CDR	SOIC	D	8	2500	353.0	353.0	32.0
TLC2201IDR	SOIC	D	8	2500	353.0	353.0	32.0
TLC2202ACDR	SOIC	D	14	2500	350.0	350.0	43.0
TLC2202CDR	SOIC	D	14	2500	350.0	350.0	43.0
TLC2202CPSR	SO	PS	8	2000	353.0	353.0	32.0

**TUBE**


\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
5962-9088201M2A	FK	LCCC	20	55	506.98	12.06	2030	NA
5962-9088202M2A	FK	LCCC	20	55	506.98	12.06	2030	NA
5962-9088204Q2A	FK	LCCC	20	55	506.98	12.06	2030	NA
TLC2201ACD	D	SOIC	8	75	505.46	6.76	3810	4
TLC2201ACD	D	SOIC	8	75	507	8	3940	4.32
TLC2201ACD.A	D	SOIC	8	75	505.46	6.76	3810	4
TLC2201ACD.A	D	SOIC	8	75	507	8	3940	4.32
TLC2201AID	D	SOIC	8	75	507	8	3940	4.32
TLC2201AID	D	SOIC	8	75	505.46	6.76	3810	4
TLC2201AID.A	D	SOIC	8	75	507	8	3940	4.32
TLC2201AID.A	D	SOIC	8	75	505.46	6.76	3810	4
TLC2201AMD	D	SOIC	8	75	505.46	6.76	3810	4
TLC2201AMD.A	D	SOIC	8	75	505.46	6.76	3810	4
TLC2201AMDG4	D	SOIC	8	75	505.46	6.76	3810	4
TLC2201AMDG4.A	D	SOIC	8	75	505.46	6.76	3810	4
TLC2201CD	D	SOIC	8	75	505.46	6.76	3810	4
TLC2201CD	D	SOIC	8	75	507	8	3940	4.32
TLC2201CD.A	D	SOIC	8	75	507	8	3940	4.32
TLC2201CD.A	D	SOIC	8	75	505.46	6.76	3810	4
TLC2201CP	P	PDIP	8	50	506	13.97	11230	4.32
TLC2201CP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLC2201ID	D	SOIC	8	75	507	8	3940	4.32
TLC2201ID	D	SOIC	8	75	505.46	6.76	3810	4
TLC2201ID.A	D	SOIC	8	75	507	8	3940	4.32
TLC2201ID.A	D	SOIC	8	75	505.46	6.76	3810	4
TLC2201IP	P	PDIP	8	50	506	13.97	11230	4.32
TLC2201IP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLC2201MFKB	FK	LCCC	20	55	506.98	12.06	2030	NA
TLC2201MFKB.A	FK	LCCC	20	55	506.98	12.06	2030	NA

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
TLC2202ACD	D	SOIC	14	50	505.46	6.76	3810	4
TLC2202ACD.A	D	SOIC	14	50	505.46	6.76	3810	4
TLC2202AID	D	SOIC	14	50	505.46	6.76	3810	4
TLC2202AID.A	D	SOIC	14	50	505.46	6.76	3810	4
TLC2202AMFKB	FK	LCCC	20	55	506.98	12.06	2030	NA
TLC2202AMFKB.A	FK	LCCC	20	55	506.98	12.06	2030	NA
TLC2202CD	D	SOIC	14	50	505.46	6.76	3810	4
TLC2202CD.A	D	SOIC	14	50	505.46	6.76	3810	4
TLC2202CP	P	PDIP	8	50	506	13.97	11230	4.32
TLC2202CP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLC2202CPS	PS	SOP	8	80	530	10.5	4000	4.1
TLC2202CPS.A	PS	SOP	8	80	530	10.5	4000	4.1
TLC2202ID	D	SOIC	14	50	505.46	6.76	3810	4
TLC2202ID.A	D	SOIC	14	50	505.46	6.76	3810	4
TLC2202IP	P	PDIP	8	50	506	13.97	11230	4.32
TLC2202IP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLC2202MFKB	FK	LCCC	20	55	506.98	12.06	2030	NA
TLC2202MFKB.A	FK	LCCC	20	55	506.98	12.06	2030	NA



# D0014A

# PACKAGE OUTLINE

## SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4220718/A 09/2016

### NOTES:

1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
5. Reference JEDEC registration MS-012, variation AB.

# EXAMPLE BOARD LAYOUT

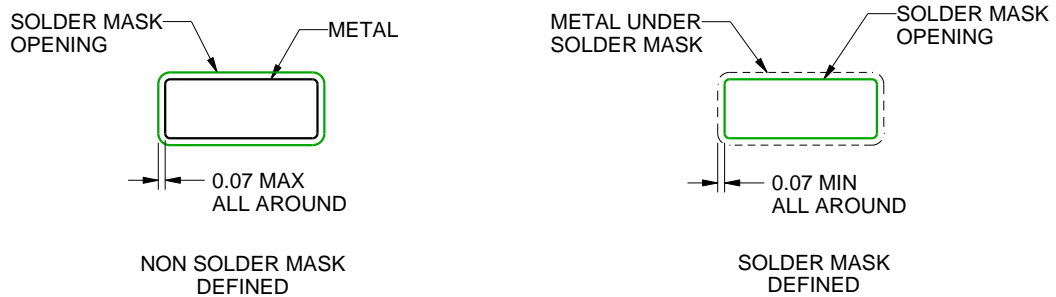
D0014A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE  
SCALE:8X



SOLDER MASK DETAILS

4220718/A 09/2016

NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

D0014A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE:8X

4220718/A 09/2016

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

## GENERIC PACKAGE VIEW

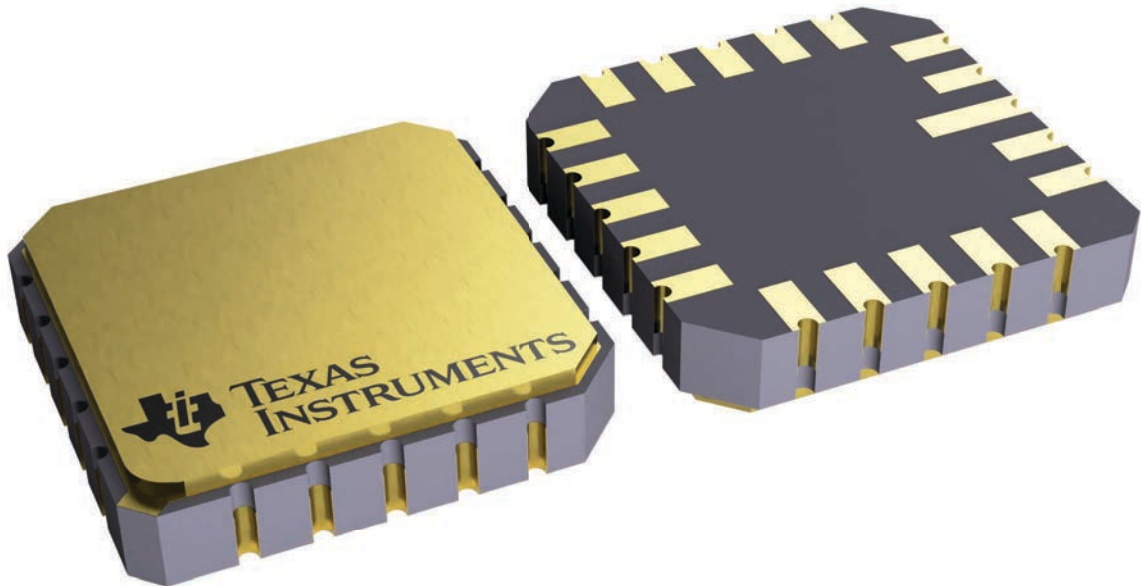
**FK 20**

**LCCC - 2.03 mm max height**

8.89 x 8.89, 1.27 mm pitch

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary.  
Refer to the product data sheet for package details.



4229370VA\



D0008A

# PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

### NOTES:

- Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- This drawing is subject to change without notice.
- This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- This dimension does not include interlead flash.
- Reference JEDEC registration MS-012, variation AA.

# EXAMPLE BOARD LAYOUT

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE  
 EXPOSED METAL SHOWN  
 SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

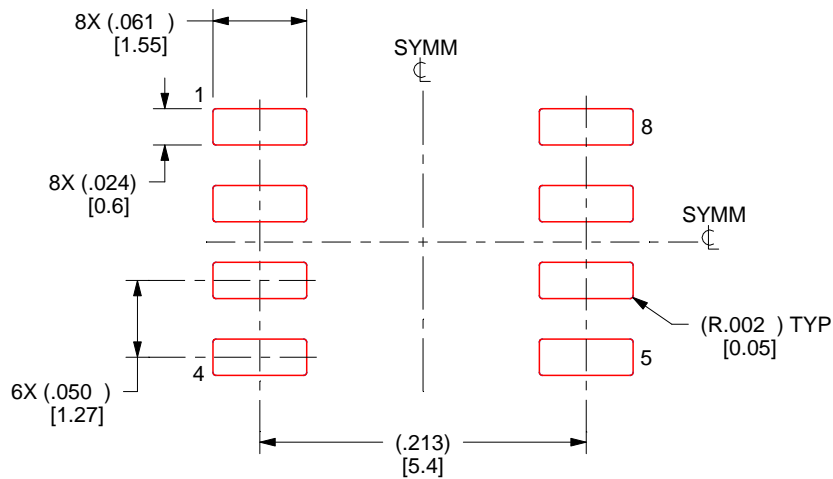
- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE  
BASED ON .005 INCH [0.125 MM] THICK STENCIL  
SCALE:8X

4214825/C 02/2019

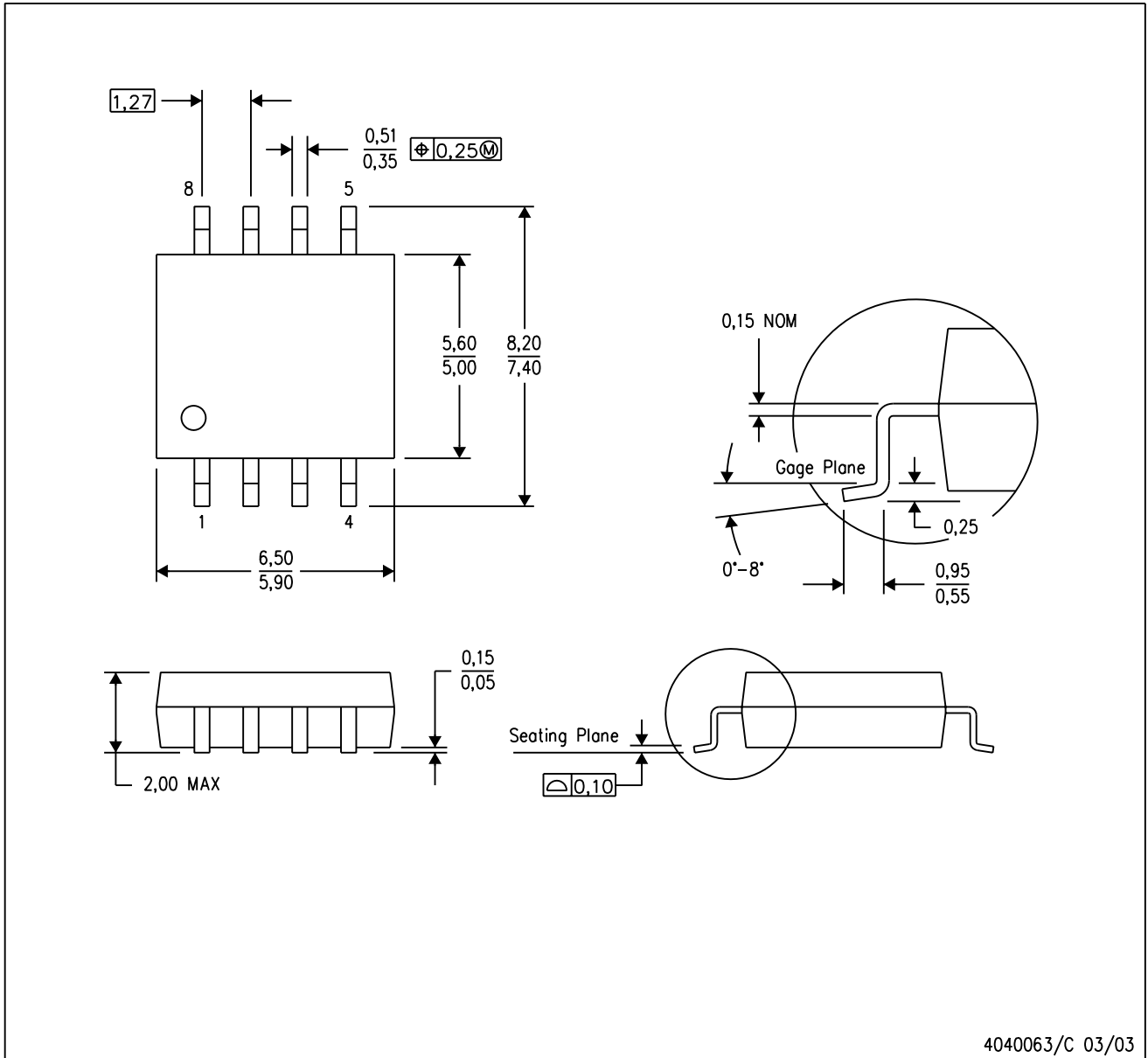
NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

## MECHANICAL DATA

PS (R-PDSO-G8)

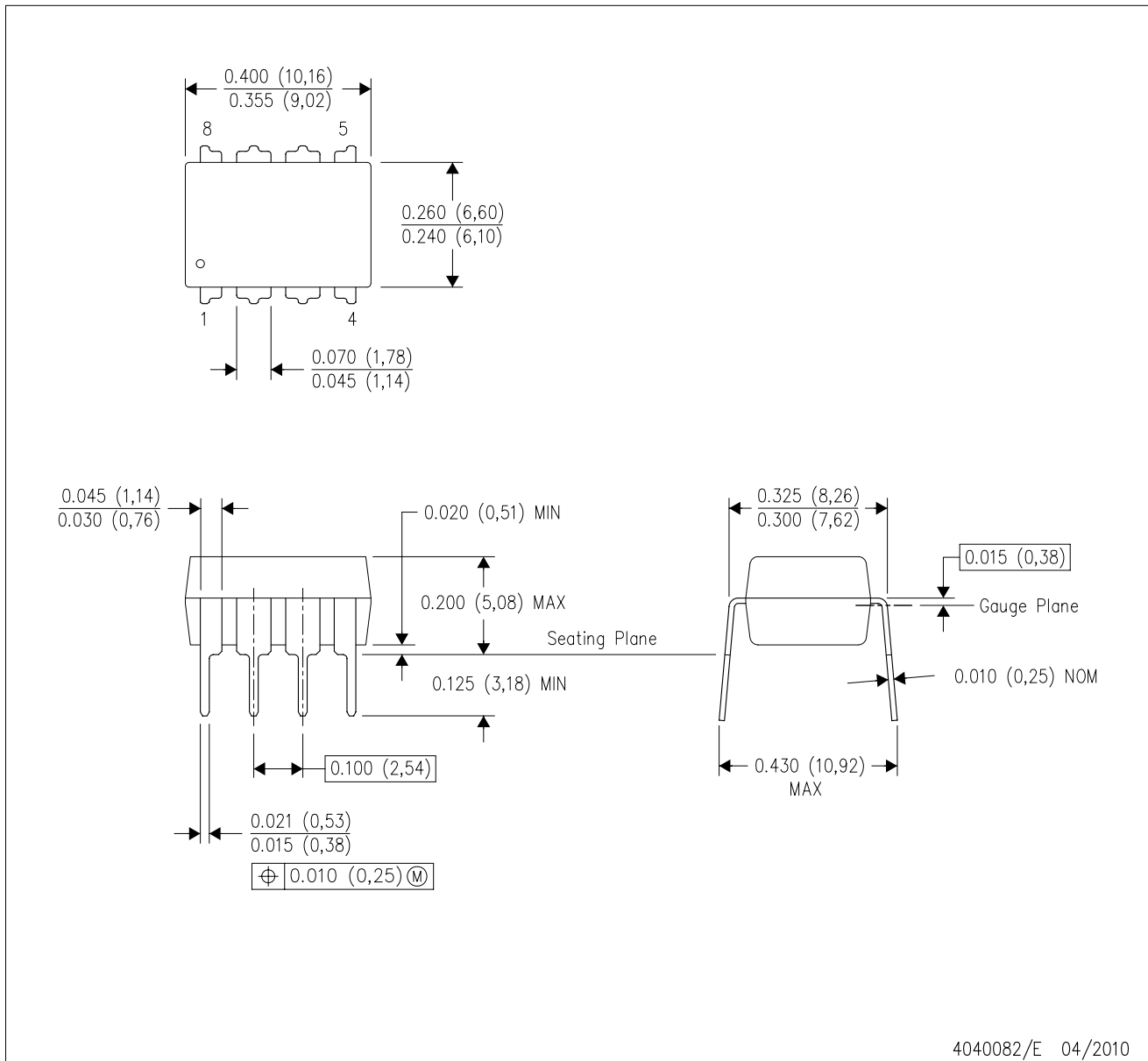
PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



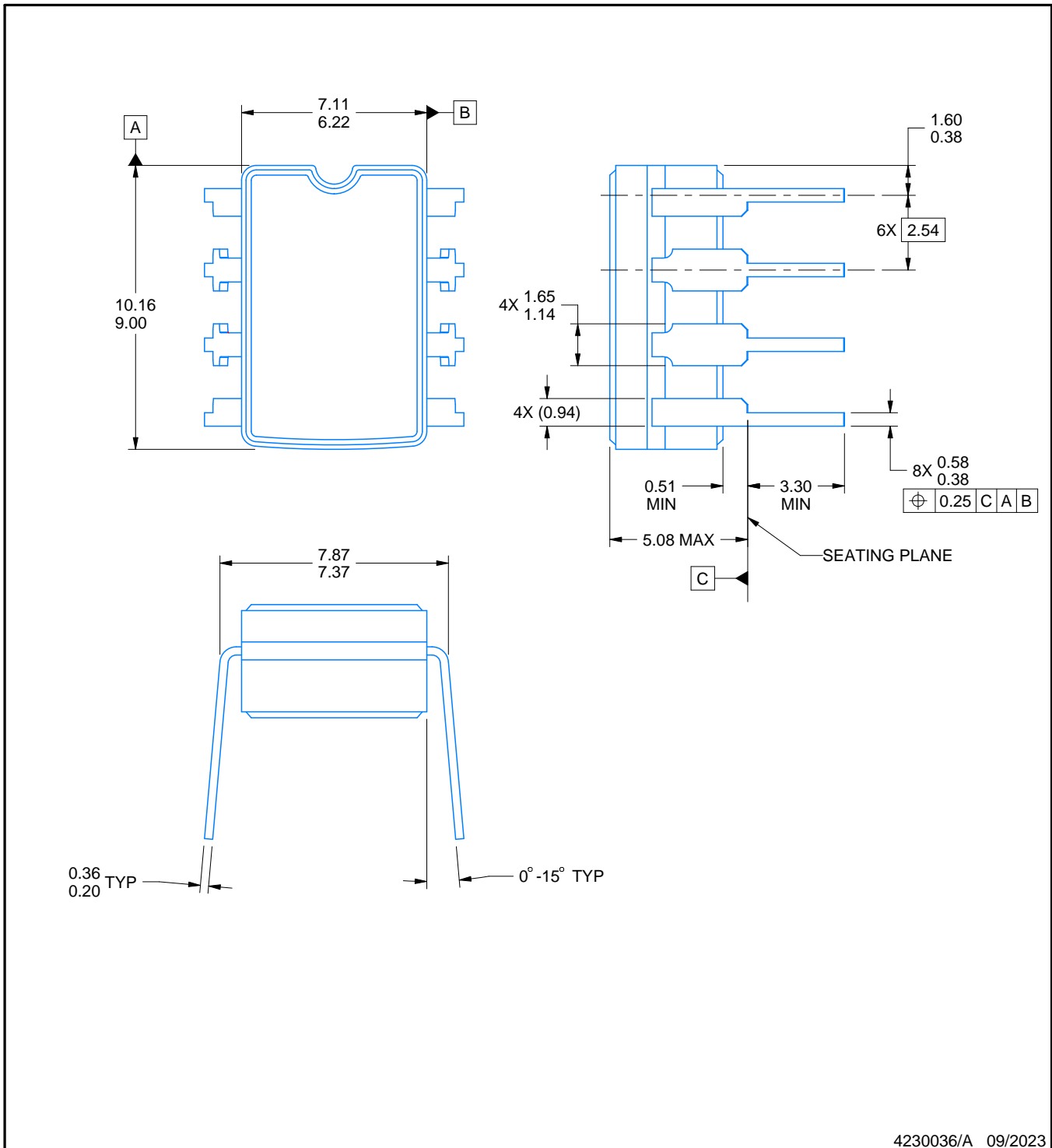
- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - C. Falls within JEDEC MS-001 variation BA.

# PACKAGE OUTLINE

## JG0008A

### CDIP - 5.08 mm max height

CERAMIC DUAL IN-LINE PACKAGE



#### NOTES:

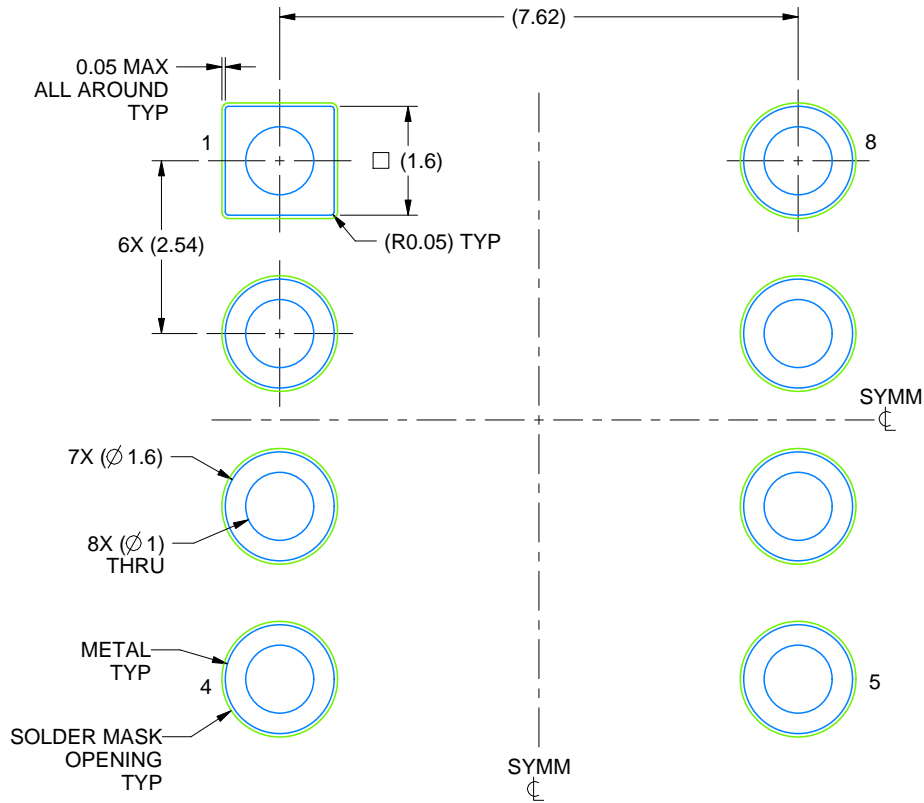
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This package can be hermetically sealed with a ceramic lid using glass frit.
4. Index point is provided on cap for terminal identification.
5. Falls within MIL STD 1835 GDIP1-T8

# EXAMPLE BOARD LAYOUT

JG0008A

CDIP - 5.08 mm max height

CERAMIC DUAL IN-LINE PACKAGE



LAND PATTERN EXAMPLE  
NON SOLDER MASK DEFINED  
SCALE: 9X

4230036/A 09/2023

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